

TC1161/TC1162

32-Bit Single-Chip Microcontroller

TriCore™

32bit

Microcontrollers



Never stop thinking.

Edition 2005-11

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TC1161/TC1162

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TC1161/TC1162 Data Sheet

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32-Bit Single-Chip Microcontroller TriCore™

TC1161/TC1162

Advance Information**Summary of Features**

- One General Purpose Timer Array Module (GPTA) with a powerful set of digital signal filtering and timer functionality to realize autonomous and complex Input/Output management
- One 16-channel Analog-to-Digital Converter unit (ADC) with selectable 8-bit, 10-bit, or 12-bit, supporting 32 input channels
- One 2-channel Fast Analog-to-Digital Converter unit (FADC) with concatenated comb filters for hardware data reduction: supporting 10-bit resolution, with minimum conversion time of 318.2 ns
- 32 analog input lines for ADC and FADC
- 81 digital general purpose I/O lines
- Digital I/O ports with 3.3 V capability
- On-chip debug support for OCDS Level 1 and 2 (CPU, DMA)
- Power Management System
- Clock Generation Unit with PLL
- Core supply voltage of 1.5 V
- I/O voltage of 3.3 V
- Full Industrial and Multi-Market temperature range: -40° to +85°C
- PG-LQFP-176-2 package

Advance Information**Summary of Features****Ordering Information**

The ordering code for Infineon microcontrollers provides an exact reference to the required product. This ordering code identifies:

- The derivative itself, i.e. its function set, the temperature range, and the supply voltage
- The package and the type of delivery

For the available ordering codes for the TC1161/TC1162, please refer to the “Product Catalog Microcontrollers” that summarizes all available microcontroller variants.

This document describes the derivatives of the device. **Table 1-1** enumerates these derivatives and summarizes the differences.

Table 1-1 TC1161/TC1162 Derivative Synopsis

Derivative	Ambient Temperature Range
SAF-TC1161-128F66HL	$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$
SAF-TC1162-128F66HL	$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$

2 General Device Information

Chapter 2 provides the general information for the TC1161/TC1162.

2.1 Block Diagram

Figure 2-1 shows the TC1161/TC1162 block diagram.

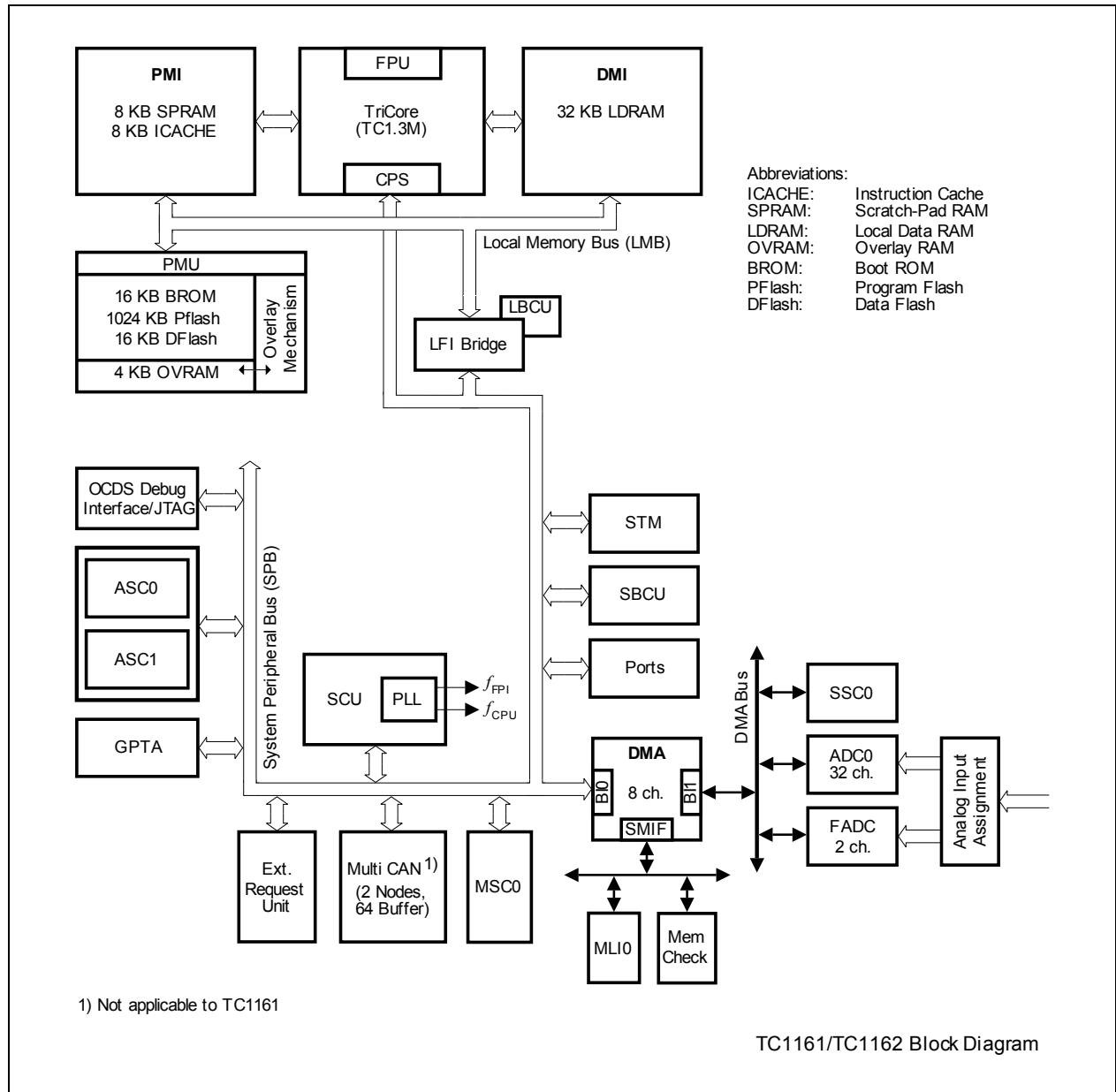


Figure 2-1 TC1161/TC1162 Block Diagram

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2.2 Logic Symbol

Figure 2-2 shows the TC1161/TC1162 logic symbol.

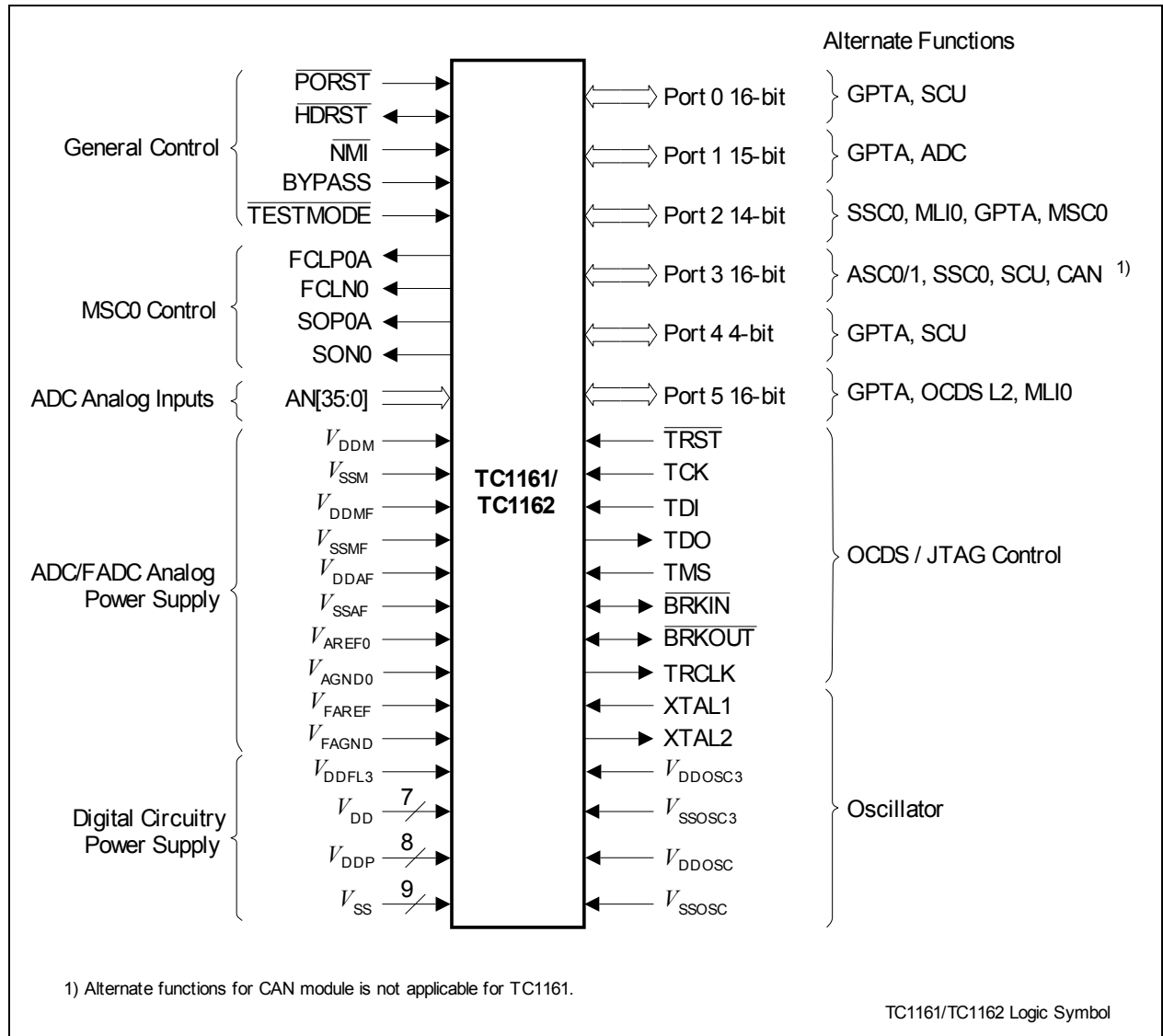


Figure 2-2 TC1161/TC1162 Logic Symbol

2.3 Pin Configuration

Figure 2-3 shows the TC1161/TC1162 pin configuration.

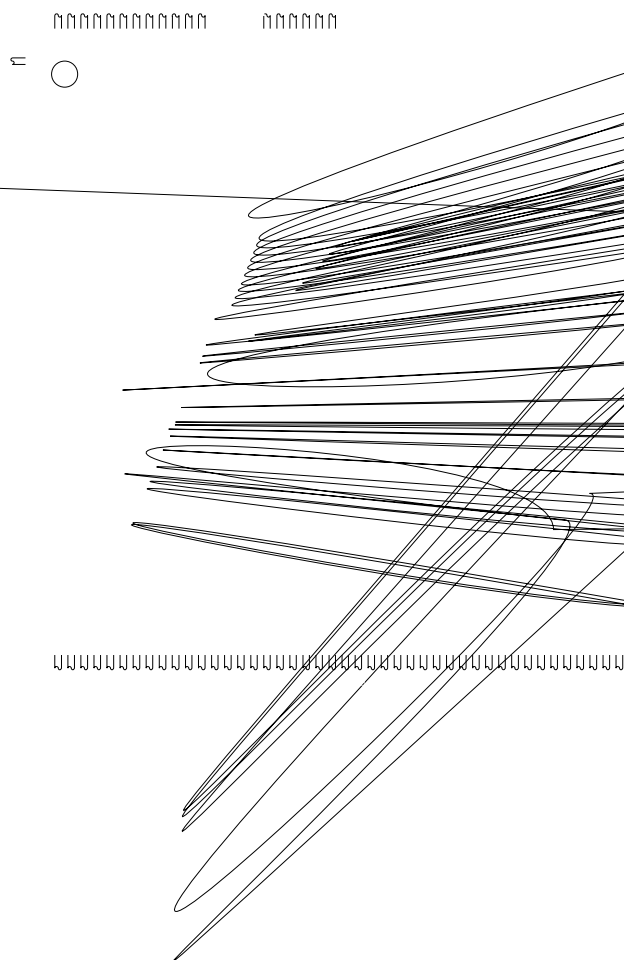


Figure 2-3 TC1161/TC1162 Pinning for PG-LQFP-176-2 Package

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General Device Information

2.4 Pad Driver and Input Classes Overview

The TC1161/TC1162 provides different types and classes of input and output lines. For understanding of the abbreviations in [Table 2-2](#) starting at the next page, [Table 2-1](#) gives an overview on the pad type and class types.

Table 2-1 Pad Driver and Input Classes Overview

Class	Power Supply	Type	Sub Class	Speed Grade	Termination
A	3.3V	LVTTL I/O, LVTTL outputs	A1 (e.g. GPIO)	6 MHz	No
			A2 (e.g. serial I/Os)	40 MHz	Series termination recommended
			A3 (e.g. BRKIN, BRKOUT)	66 MHz/	Yes, series termination
			A4 (e.g. Trace Clock)	66 MHz	Yes, series termination
C	3.3V	LVDS	–	50 MHz	Parallel termination
D		Analog input	–	–	–

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General Device Information
2.5 Pin Definitions and Functions

Table 2-2 shows the TC1161/TC1162 pin definitions and functions.

Table 2-2 Pin Definitions and Functions

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
Parallel Ports					
P0		I/O	A1	V_{DDP}	Port 0 Port 0 is a 16-bit bi-directional general-purpose I/O port which can be alternatively used for GPTA I/O lines or external trigger inputs. P0.0 145 IN0 / OUT0 / OUT56 line of GPTA P0.1 146 IN1 / OUT1 / OUT57 line of GPTA P0.2 147 IN2 / OUT2 / OUT58 line of GPTA P0.3 148 IN3 / OUT3 / OUT59 line of GPTA P0.4 166 IN4 / OUT4 / OUT60 line of GPTA P0.5 167 IN5 / OUT5 / OUT61 line of GPTA P0.6 173 IN6 / OUT6 / OUT62 line of GPTA REQ2 External trigger input 2 P0.7 174 IN7 / OUT7 / OUT63 line of GPTA REQ3 External trigger input 3 P0.8 149 IN8 / OUT8 / OUT64 line of GPTA P0.9 150 IN9 / OUT9 / OUT65 line of GPTA P0.10 151 IN10 / OUT10 / OUT66 line of GPTA P0.11 152 IN11 / OUT11 / OUT67 line of GPTA P0.12 168 IN12 / OUT12 / OUT68 line of GPTA P0.13 169 IN13 / OUT13 / OUT69 line of GPTA P0.14 175 IN14 / OUT14 / OUT70 line of GPTA REQ4 External trigger input 4 P0.15 176 IN15 / OUT15 / OUT71 line of GPTA REQ5 External trigger input 5 In addition, the state of the port pins are latched into the software configuration input register SCU_SCLIR at the rising edge of HDRST. Therefore, Port 0 pins can be used for operating mode selections by software.

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General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
P1		I/O		V_{DDP}	Port 1 Port 1 is a 15-bit bi-directional general purpose I/O port which can be alternatively used for GPTA I/O lines and ADC0 interface.
P1.0	91		A1		IN16 / OUT16 / OUT72 line of GPTA
P1.1	92		A1		IN17 / OUT17 / OUT73 line of GPTA
P1.2	93		A1		IN18 / OUT18 / OUT74 line of GPTA
P1.3	98		A1		IN19 / OUT19 / OUT75 line of GPTA
P1.4	107		A1		IN20 / OUT20 / OUT76 line of GPTA
P1.5	108		A1		IN21 / OUT21 / OUT77 line of GPTA
P1.6	109		A1		IN22 / OUT22 / OUT78 line of GPTA
P1.7	110		A1		IN23 / OUT23 / OUT79 line of GPTA
P1.8	94		A2		IN24 / OUT24 / IN48 / OUT48 line of GPTA
P1.9	95		A2		IN25 / OUT25 / IN49 / OUT49 line of GPTA
P1.10	96		A2		IN26 / OUT26 / IN50 / OUT50 line of GPTA
P1.11	97		A2		IN27 / OUT27 / IN51 / OUT51 line of GPTA
P1.12	73		A1		AD0EMUX0 ADC0 external multiplexer control output 0
P1.13	72		A1		AD0EMUX1 ADC0 external multiplexer control output 1
P1.14	71		A1		AD0EMUX2 ADC0 external multiplexer control output 2
					In addition, P1.4 also serves as emergency shut-off input for certain I/O lines (e.g. GPTA related outputs).

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General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
P2		I/O		V_{DDP}	Port 2 Port 2 is a 14-bit bi-directional general-purpose I/O port which can be alternatively used for GPTA I/O, and interface for MLI0, MSC0 or SSC0.
P2.0	74		A2		TCLK0A MLI0 transmit channel clock output A
P2.1	75		A2		IN32 / OUT32 line of GPTA TREADY0A MLI0 transmit channel ready input A
P2.2	76		A2		IN33 / OUT33 line of GPTA SLSO03 SSC0 slave select output 3 TVALID0A MLI0 transmit channel valid output A
P2.3	77		A2		IN34 / OUT34 line of GPTA TDATA0A MLI0 transmit channel data output A
P2.4	78		A1		IN35 / OUT35 line of GPTA RCLK0A MLI0 receive channel clock input A
P2.5	79		A2		IN36 / OUT36 line of GPTA RREADY0A MLI0 receive channel ready output A
P2.6	80		A1		IN37 / OUT37 line of GPTA RVALID0A MLI0 receive channel valid input A
P2.7	81		A1		IN38 / OUT38 line of GPTA RDATA0A MLI0 receive channel data input A IN39 / OUT39 line of GPTA

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General Device Information
Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions	
P2.8	164		A2		SLSO04	SSC0 Slave Select output 4
					EN00	MSC0 enable output 0
P2.9	160		A2		SLSO05	SSC0 Slave Select output 5
					EN01	MSC0 enable output 1
P2.10	161		A2			
P2.11	162		A2		FCLP0B	MSC0 clock output B
P2.12	163		A2		SOP0B	MSC0 serial data output B
P2.13	165		A1		SDI0	MSC0 serial data input

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General Device Information

P3 I/O V_{DDP}

P3.0 136 A2
P3.1 135 A2

P3.2 129 A2
P3.3 130 A2

P3.4 132 A2

P3.5 126 A2
P3.6 127 A2
P3.7 131 A2

P3.8 128 A2

P3.9 138 A2
P3.10 137 A1
P3.11 144 A1
P3.12 143 A2

P3.13 142 A2

P3.14 134 A2

P3.15 133 A2

Port 3

Port 3 is a 16-bit bi-directional general-purpose I/O port which can be alternatively used for ASC0/1, SSC0 and CAN¹⁾ lines.

RXD0A ASC0 receiver inp./outp. A
TXD0A ASC0 transmitter output A

This pin is sampled at the rising edge of PORST. If this pin and the BYPASS input pin are both active, then oscillator bypass mode is entered.

SCLK0 SSC0 clock input/output
MRST0 SSC0 master receive input/
 slave transmit output
MTSR0 SSC0 master transmit
 output/slave receive input

SLSO00
SLSO01
SLSI0
SLSO02
SLSO06
TXD1A
RXD1A
REQ0
REQ1
RXDCAN0¹⁾
RXD0B
TXDCAN0¹⁾
TXD0B
RXDCAN1¹⁾
RXD1B
TXDCAN1¹⁾
TXD1B

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General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
P4 P4.[3:0]		I/O		V_{DDP}	Port 4 / Hardware Configuration Inputs HWCFG[3:0] Boot mode and boot location inputs; inputs are latched with the rising edge of <u>HDRST</u> . During normal operation, Port 4 pins may be used as alternate functions for GPTA or system clock output.
P4.0	86		A1		IN28 / OUT28 / IN52 / OUT52 line of GPTA
P4.1	87		A1		IN29 / OUT29 / IN53 / OUT53 line of GPTA
P4.2	88		A2		IN30 / OUT30 / IN54 / OUT54 line of GPTA
P4.3	90		A2		IN31 / OUT31 / IN55 / OUT55 line of GPTA
					SYSCLK System Clock Output

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General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
P5		I/O	A2	V_{DDP}	Port 5 Port 5 is a 16-bit bi-directional general-purpose I/O port. In emulation, it is used as a trace port for OCDS Level 2 debug lines. In normal operation, it is used for GPTA I/O or the MLI0 interface.
P5.0	1				OCDSDBG0 OCDS L2 Debug Line 0 (Pipeline Status Sig. PS0)
P5.1	2				IN40 / OUT40 line of GPTA OCDSDBG1 OCDS L2 Debug Line 1 (Pipeline Status Sig. PS1)
P5.2	3				IN41 / OUT41 line of GPTA OCDSDBG2 OCDS L2 Debug Line 2 (Pipeline Status Sig. PS2)
P5.3	4				IN42 / OUT42 line of GPTA OCDSDBG3 OCDS L2 Debug Line 3 (Pipeline Status Sig. PS3)
P5.4	5				IN43 / OUT43 line of GPTA OCDSDBG4 OCDS L2 Debug Line 4 (Pipeline Status Sig. PS4)
P5.5	6				IN44 / OUT44 line of GPTA OCDSDBG5 OCDS L2 Debug Line 5 (Break Qualification Line BRK0)
P5.6	7				IN45 / OUT45 line of GPTA OCDSDBG6 OCDS L2 Debug Line 6 (Break Qualification Line BRK1)
P5.7	8				IN46 / OUT46 line of GPTA OCDSDBG7 OCDS L2 Debug Line 7 (Break Qualification Line BRK2)
					IN47 / OUT47 line of GPTA

Advance Information
General Device Information
Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
P5.8	13				OCDSDBG8 OCDS L2 Debug Line 8 (Indirect PC Addr. PC0) RDATA0B MLI0 receive channel data input B
P5.9	14				OCDSDBG9 OCDS L2 Debug Line 9 (Indirect PC Addr. PC1) RVALID0B MLI0 receive channel valid input B
P5.10	15				OCDSDBG10 OCDS L2 Debug Line 10 (Indirect PC Addr. PC2) RREADY0B MLI0 receive channel ready output B
P5.11	16				OCDSDBG11 OCDS L2 Debug Line 11 (Indirect PC Addr. PC3) RCLK0B MLI0 receive channel clock input B
P5.12	17				OCDSDBG12 OCDS L2 Debug Line 12 (Indirect PC Addr. PC04) TDATA0B MLI0 transmit channel data output B
P5.13	18				OCDSDBG13 OCDS L2 Debug Line 13 (Indirect PC Addr. PC05) TVALID0B MLI0 transmit channel valid output B
P5.14	19				OCDSDBG14 OCDS L2 Debug Line 14 (Indirect PC Address PC6) TREADY0B MLI0 transmit channel ready input B
P5.15	20				OCDSDBG15 OCDS L2 Debug Line 15 (Indirect PC Address PC7) TCLK0B MLI0 transmit channel clock output B

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General Device Information
Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
MSC0 Outputs					
FCLP0A	157	O	C	V_{DDP}	LVDS MSC Clock and Data Outputs³⁾ MSC0 Differential Driver Clock Output Positive A
FCLN0	156	O			MSC0 Differential Driver Clock Output Negative
SOP0A	159	O			MSC0 Differential Driver Serial Data Output Positive A
SON0	158	O			MSC0 Differential Driver Serial Data Output Negative

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General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
Analog Inputs					
AN[35:0]		I	D	–	Analog Input Port The Analog Input Port provides altogether 36 analog input lines to ADC0 and FADC. AN[31:0]: ADC0 analog inputs [31:0] AN[35:32]: FADC analog differential inputs
AN0	67				Analog input 0
AN1	66				Analog input 1
AN2	65				Analog input 2
AN3	64				Analog input 3
AN4	63				Analog input 4
AN5	62				Analog input 5
AN6	61				Analog input 6
AN7	36				Analog input 7
AN8	60				Analog input 8
AN9	59				Analog input 9
AN10	58				Analog input 10
AN11	57				Analog input 11
AN12	56				Analog input 12
AN13	55				Analog input 13
AN14	50				Analog input 14
AN15	49				Analog input 15
AN16	48				Analog input 16
AN17	47				Analog input 17
AN18	46				Analog input 18
AN19	45				Analog input 19
AN20	44				Analog input 20
AN21	43				Analog input 21
AN22	42				Analog input 22
AN23	41				Analog input 23
AN24	40				Analog input 24
AN25	39				Analog input 25
AN26	38				Analog input 26
AN27	37				Analog input 27
AN28	35				Analog input 28
AN29	34				Analog input 29
AN30	33				Analog input 30

Advance Information

General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
AN31	32	I	D	–	Analog input 31
AN32	31				Analog input 32
AN33	30				Analog input 33
AN34	29				Analog input 34
AN35	28				Analog input 35
System I/O					
TRST	114	I	A2 ²⁾	V_{DDP}	JTAG Module Reset/Enable Input
TCK	115	I	A2 ²⁾	V_{DDP}	JTAG Module Clock Input
TDI	111	I	A1 ²⁾	V_{DDP}	JTAG Module Serial Data Input
TDO	113	O	A2	V_{DDP}	JTAG Module Serial Data Output
TMS	112	I	A2 ²⁾	V_{DDP}	JTAG Module State Machine Control Input
BRKIN	117	I/O	A3	V_{DDP}	OCDS Break Input (Alternate Output)³⁾⁴⁾
BRK OUT	116	I/O	A3	V_{DDP}	OCDS Break Output (Alternate Input)³⁾⁴⁾
TRCLK	9	O	A4	V_{DDP}	Trace Clock for OCDS_L2 Lines³⁾
NMI	120	I	A2 ⁵⁾	V_{DDP}	Non-Maskable Interrupt Input
HDRST	122	I/O	A2	V_{DDP}	Hardware Reset Input / Reset Indication Output
PORST 6)	121	I	A2 ⁵⁾	V_{DDP}	Power-on Reset Input
BYPASS	119	I	A1 ²⁾	V_{DDP}	PLL Clock Bypass Select Input This input has to be held stable during power-on resets. With BYPASS = 1, the spike filters in the HDRST , PORST and NMI inputs are switched off.
TEST MODE	118	I	A2 ⁵⁾	V_{DDP}	Test Mode Select Input For normal operation of the TC1161/TC1162, this pin should be connected to high level.
XTAL1 XTAL2	102 103	I O	n.a.	V_{DDOSC}	Oscillator/PLL/Clock Generator Input/Output Pins
N.C.	21, 89	–	–	–	Not Connected These pins are reserved for future extension and must not be connected externally.

Advance Information

General Device Information

Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
Power Supplies					
V_{DDM}	54	–	–	–	ADC Analog Part Power Supply (3.3 V)
V_{SSM}	53	–	–	–	ADC Analog Part Ground for V_{DDM}
V_{DDMF}	24	–	–	–	FADC Analog Part Power Supply (3.3 V)
V_{SSMF}	25	–	–	–	FADC Analog Part Ground for V_{DDMF}
V_{DDAF}	23	–	–	–	FADC Analog Part Logic Power Supply (1.5 V)
V_{SSAF}	22	–	–	–	FADC Analog Part Logic Ground for V_{DDAF}
V_{AREF0}	52	–	–	–	ADC Reference Voltage
V_{AGND0}	51	–	–	–	ADC Reference Ground
V_{FAREF}	26	–	–	–	FADC Reference Voltage
V_{FAGND}	27	–	–	–	FADC Reference Ground
V_{DDOSC}	105	–	–	–	Main Oscillator and PLL Power Supply (1.5 V)
V_{DDOSC3}	106	–	–	–	Main Oscillator Power Supply (3.3 V)
V_{SSOSC}	104	–	–	–	Main Oscillator and PLL Ground
V_{DDFL3}	141	–	–	–	Power Supply for Flash (3.3 V)
V_{DD}	10, 68, 84, 99, 123, 153, 170	–	–	–	Core Power Supply (1.5 V)

Advance Information
General Device Information
Table 2-2 Pin Definitions and Functions (cont'd)

Symbol	Pins	I/O	Pad Driver Class	Power Supply	Functions
V_{DDP}	11, 69, 83, 100, 124, 154, 171, 139	—	—	—	Port Power Supply (3.3 V)
V_{SS}	12, 70, 85, 101, 125, 155, 172, 140, 82	—	—	—	Ground

- 1) Not applicable to TC1161
- 2) These pads are I/O pads with input only function. Its input characteristics are identical with the input characteristics as defined for class A pads.
- 3) In case of a power-fail condition (one or more power supply voltages drop below the specified voltage range), an undefined output driving level may occur at these pins.
- 4) Programmed by software as either break input or break output.
- 5) These pads are input only pads with input characteristics.
- 6) The dual input reset system of TC1161/TC1162 assumes that the $\overline{\text{PORST}}$ reset pin is used for power on reset only.

Advance Information
General Device Information
Table 2-3 List of Pull-up/Pull-down Reset Behavior of the Pins

Pins	$\overline{\text{PORST}} = 0$	$\overline{\text{PORST}} = 1$
TDI, TMS, TDO	Pull-up	
HDRST	Drive-low	Pull-up
BYPASS	Pull-up	High-impedance
TRST, TCK	High-impedance	Pull-down
TRCLK	High-impedance	
BRKIN, BRKOUT, TESTMODE	Pull-up	
NMI, $\overline{\text{PORST}}$	Pull-down	

3 Functional Description

Chapter 3 provides an overview of the TC1161/TC1162 functional description.

3.1 System Architecture and On-Chip Bus Systems

The TC1161/TC1162 has two independent on-chip buses (see also TC1161/TC1162 block diagram on [Page 2-6](#)):

- Local Memory Bus (LMB)
- System Peripheral Bus (SPB)

The LMB Bus connects the CPU local resources for data and instruction fetch. The Local Memory Bus interconnects the memory units and functional units, such as CPU and PMU. The main target of the LMB bus is to support devices with fast response times, optimized for speed. This allows the DMI and PMI fast access to local memory and reduces load on the FPI bus. The Tricore system itself is located on LMB bus.

The Local Memory Bus is a synchronous, pipelined, split bus with variable block size transfer support. It supports 8-, 16-, 32- and 64-bit single transactions and variable length 64-bit block transfers.

The SPB Bus is accessible to the CPU via the LMB Bus bridge. The System Peripheral Bus (SPB Bus) in TC1161/TC1162 is an on-chip FPI Bus. The FPI Bus interconnects the functional units of the TC1161/TC1162, such as the DMA and on-chip peripheral components. The FPI Bus is designed to be quick to be acquired by on-chip functional units, and quick to transfer data. The low setup overhead of the FPI Bus access protocol guarantees fast FPI Bus acquisition, which is required for time-critical applications. The FPI Bus is designed to sustain high transfer rates. For example, a peak transfer rate of up to 264 Mbyte/s can be achieved with a 66 MHz bus clock and 32-bit data bus. Multiple data transfers per bus arbitration cycle allow the FPI Bus to operate at close to its peak bandwidth.

Both the LMB Bus and the SPB Bus runs at full CPU speed. The maximum CPU speed is 66 MHz.

Additionally, two simplified bus interfaces are connected to and controlled by the DMA Controller.

- DMA Bus
- SMIF Interface.

Advance Information**Functional Description****3.2 On-Chip Memories**

As shown in the TC1161/TC1162 block diagram on [Page 2-6](#), some of the TC1161/TC1162 units provide on-chip memories that are used as program or data memory.

- Program memory in PMU
 - 16 Kbyte Boot ROM (BROM)
 - 1024 Kbyte Program Flash (PFlash)
- Program memory in PMI
 - 8 Kbyte Scratch-Pad RAM (SPRAM)
 - 8 Kbyte Instruction Cache (ICACHE)
- Data memory in PMU
 - 16 Kbyte Data Flash (DFlash)
 - 4 Kbyte Overlay RAM (OVRAM)
- Data memory in DMI
 - 32 Kbyte Local Data RAM (LDRAM)
- On-chip SRAM with parity error protection

Features of Program Flash

- 1024 Kbyte on-chip program Flash memory
- Usable for instruction code or constant data storage
- 256-byte program interface
 - 256 bytes are programmed into PFLASH page in one step/command
- 256-bit read interface
 - Transfer from PFLASH to CPU/PMI by four 64-bit single cycle burst transfers
- Dynamic correction of single-bit errors during read access
- Detection of double-bit errors
- Fixed sector architecture
 - Eight 16 Kbyte, one 128 Kbyte, one 256 Kbyte and one 512 Kbyte sectors
 - Each sector separately erasable
 - Each sector separately write-protectable
- Configurable read protection for complete PFLASH with sophisticated read access supervision, combined with write protection for complete PFLASH (protection against “Trojan horse” software)
- Configurable write protection for each sector
 - Each sector separately write-protectable
 - With capability to be re-programmed
 - With capability to be locked forever (OTP)
- Password mechanism for temporary disabling of write and read protection
- On-chip generation of programming voltage
- JEDEC-standard based command sequences for PFLASH control
 - Write state machine controls programming and erase operations
 - Status and error reporting by status flags and interrupt

Advance Information**Functional Description**

- Margin check for detection of problematic PFLASH bits

Features of Data Flash

- 16 Kbyte on-chip data Flash memory, organized in two 8 Kbyte banks
- Usable for data storage with EEPROM functionality
- 128 Byte of program interface
 - 128 bytes are programmed into one DFLASH page by one step/command
- 64-bit read interface (no burst transfers)
- Dynamic correction of single-bit errors during read access
- Detection of double-bit errors
- Fixed sector architecture
 - Two 8 Kbyte banks/sectors
 - Each sector separately erasable
- Configurable read protection (combined with write protection) for complete DFLASH together with PFLASH read protection
- Password mechanism for temporary disabling of write and read protection
- Erasing/programming of one bank possible while reading data from the other bank
- Programming of one bank while erasing the other bank possible
- On-chip generation of programming voltage
- JEDEC-standard based command sequences for DFLASH control
 - Write state machine controls programming and erase operations
 - Status and error reporting by status flags and interrupt
- Margin check for detection of problematic DFLASH bits

3.3 Memory Maps

This chapter gives an overview of the TC1161/TC1162 memory map and describes the address locations and access possibilities for the units, memories, and reserved areas as “seen” from different on-chip buses’ (SPB and LMB) point of view.

3.3.1 Architectural Address Map

Table 3-1 shows the overall architectural address map as defined for the TriCore and as implemented in TC1161/TC1162.

Table 3-1 TC1161/TC1162 Architectural Address Map

Segment	Contents	Size	Description
0-7	Global	8 x 256 Mbyte	Reserved (MMU space); cached
8	Global Memory	256 Mbyte	Reserved (246 Mbyte); PMU, Boot ROM; cached
9	Global Memory	256 Mbyte	FPI space; cached
10	Global Memory	256 Mbyte	Reserved (246 Mbyte), PMU, Boot ROM; non-cached
11	Global Memory	256 Mbyte	FPI space; non-cached
12	Local LMB Memory	256 Mbyte	Reserved; bottom 4 Mbyte visible from FPI bus in segment 14; cached
13	DMI	64 Mbyte	Local Data Memory RAM; non-cached
	PMI	64 Mbyte	Local Code Memory RAM; non-cached
	EXT_PER	96 Mbyte	Reserved; non-cached
	EXT_EMU	16 Mbyte	Reserved; non-cached
	BOOTROM	16 Mbyte	Boot ROM space, Boot ROM mirror; non-cached

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Table 3-1 TC1161/TC1162 Architectural Address Map (cont'd)

Seg- ment	Contents	Size	Description
14	EXTPER	128 Mbyte	Reserved; non-speculative; non-cached; no execution
	CPU[0 ..15] image region	16 x 8 Mbyte	Non-speculative; non-cached; no execution
15	LMB_PER CSFRs INT_PER	256 Mbyte	CSFRs of CPUs[0 ..15]; LMB & FPI Peripheral Space; non-speculative; non-cached; no execution

3.3.2 How to Read the Address Maps

The bus-specific address maps describe how the different bus master devices react on accesses to on-chip memories and modules, and which address ranges are valid or invalid for the corresponding buses.

The FPI Bus address map shows the system addresses from the point of view of the SPB master agents. SPB master agents are OCDS and DMA.

The LMB address map shows the system addresses from the point of view of the LMB master agents. LMB master agents are PMI and DMI.

Table 3-2 defines the acronyms and other terms that are used in the address maps (**Table 3-3** to **Table 3-5**).

Table 3-2 Definition of Acronyms and Terms

Term	Description
...BE	Means "Bus error" generation.
...BET	Means "Bus error & trap" generation.
SPBBE	A bus access is terminated with a bus error on the SPB.
SPBBET	A bus access is terminated with a bus error on the SPB and a DSE trap (read access) or DAE trap (write access).
LMBBE	A bus access is terminated with a bus error on the LMB.
LMBBET	A bus access is terminated with a bus error on the LMB and a DSE trap (read access) or DAE trap (write access).
access	A bus access is allowed and is executed.
ignore	A bus access is ignored and is not executed. No bus error is generated.
trap	A DSE trap (read access) or DAE trap (write access) is generated.
32	Only 32-bit word bus accesses are permitted to that register/address range.
nE	A bus access generates no bus error, although the bus access points to an undefined address or address range. This is valid e.g. for CPU accesses (MTCR/MFCR) to undefined addresses in the CSFR range.

3.3.3 Contents of the Segments

This section summarizes the contents of the segments.

Segments 0-7

These segments are reserved segments in the TC1161/TC1162.

Segment 8

From the SPB point of view (DMA and Cerberus), this memory segment allows accesses to all PMU memories (PFLASH, DFLASH, BROM, and TROM).

From the CPU point of view (PMI and DMI), this memory segment allows cached accesses to all PMU memories (PFLASH, DFLASH, BROM, and TROM).

Segment 9

This memory segment is reserved in the TC1161/TC1162.

Segment 10

From the SPB point of view (DMA and Cerberus), this memory segment allows accesses to all PMU memories (PFLASH, DFLASH, BROM, and TROM).

From the CPU point of view (PMI and DMI), this memory segment allows non-cached accesses to all PMU memories (PFLASH, DFLASH, BROM, and TROM).

Segment 11

This memory segment is reserved in the TC1161/TC1162.

Segment 12

From the SPB point of view (PCP, DMA, and Cerberus), this memory segment is reserved in the TC1161/TC1162.

From the CPU point of view (PMI and DMI), this memory segment allows cached accesses to the PMU memory, OVRAM.

Segment 13

From the SPB point of view (DMA and Cerberus), this memory segment is reserved in the TC1161/TC1162.

From the CPU point of view (PMI and DMI), this memory segment allows non-cached accesses to the PMI scratch-pad RAM, read access to the boot ROM and test ROM (BROM and TROM) and the DMI memories (LDRAM).

Advance Information**Functional Description****Segment 14**

From the SPB point of view (DMA and Cerberus), this memory segment allows accesses to the PMU Overlay memory (OVRAM), the DMI Local Data RAM (LDRAM), and the PMI scratch-pad RAM (SPRAM).

From the CPU point of view (PMI and DMI), this memory segment is reserved in the TC1161/TC1162.

Segment 15

From the SPB point of view (DMA and Cerberus), this memory segment allows accesses to all SFRs and CSFRs, and the MLI transfer windows.

From the CPU point of view (PMI and DMI), this memory segment allows accesses to all SFRs and CSFRs, and the MLI transfer windows.

3.3.4 Address Map of the FPI Bus System

Table 3-3 and **Table 3-4** shows the address maps of the FPI Bus System.

3.3.4.1 Segments 0 to 14

Table 3-3 shows the address maps of segments 0 to 14 as it is seen from the SPB bus masters, DMA and OCDS.

Table 3-3 SPB Address Map of Segment 0 to 14

Segment	Address Range	Size	Description	Access Type	
				Read	Write
0-7	0000 0000 _H - 0000 0007 _H	8 byte	Reserved (virtual address space)	MPN trap	MPN trap
	0000 0008 _H - 7FFF FFFF _H	8 × 256 Mbyte		SPBBE	SPBBE

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Table 3-3 SPB Address Map of Segment 0 to 14 (cont'd)

Segment	Address Range	Size	Description	Access Type	
				Read	Write
8	8000 0000 _H - 800F FFFF _H	1 Mbyte	Program Flash (PFLASH)	access	access ¹⁾
	8010 0000 _H - 8017 7FFF _H	≈ 0.5 Mbyte	Reserved	access ²⁾	access ¹⁾²⁾
	8017 8000 _H - 807F FFFF _H	6.5 Mbyte	Reserved	LMBBE & SPBBE	LMBBE
	8080 0000 _H - 8FDF FFFF _H	246 Mbyte	Reserved	LMBBE & SPBBE	LMBBE
	8FE0 0000 _H - 8FE0 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 0	access	access ¹⁾
	8FE0 2000 _H - 8FE0 3FFF _H	8 Kbyte	Reserved	access ²⁾	access ¹⁾²⁾
	8FE0 4000 _H - 8FE0 FFFF _H	48 Kbyte	Reserved	LMBBE & SPBBE	LMBBE
	8FE1 0000 _H - 8FE1 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 1	access	access ¹⁾
	8FE1 2000 _H - 8FE1 3FFF _H	8 Kbyte	Reserved	access ²⁾	access ¹⁾²⁾
	8FE1 4000 _H - 8FF1 FFFF _H	1 Mbyte	Reserved	LMBBE & SPBBE	LMBBE
	8FF2 0000 _H - 8FF5 FFFF _H	256 Kbyte	Reserved		
	8FF6 0000 _H - 8FFF BFFF _H	624 Kbyte	Reserved		
	8FFF C000 _H - 8FFF FFFF _H	16 Kbyte	Boot ROM (BROM)	access	
9	9000 0000 _H - 9FFF FFFF _H	256 Mbyte	Reserved	SPBBE	SPBBE

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Table 3-3 SPB Address Map of Segment 0 to 14 (cont'd)

Segment	Address Range	Size	Description	Access Type	
				Read	Write
10	A000 0000 _H - A00F FFFF _H	1 Mbyte	Program Flash (PFLASH)	access	access ¹⁾
	A010 0000 _H - A017 FFFF _H	≈ 0.5 Mbyte	Reserved	access ²⁾	access ¹⁾²⁾
	A017 8000 _H - A07F FFFF _H	6.5 Mbyte	Reserved	LMBBE & SPBBE	LMBBE
	A080 0000 _H - AFDF FFFF _H	246 Mbyte	Reserved	LMBBE & SPBBE	LMBBE
	AFE0 0000 _H - AFE0 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 0	access	access ¹⁾
	AFE0 2000 _H - AFE0 3FFF _H	8 Kbyte	Reserved	access ²⁾	access ¹⁾²⁾
	AFE0 4000 _H - AFE0 FFFF _H	48 Kbyte	Reserved	LMBBE & SPBBE	LMBBE
	AFE1 0000 _H - AFE1 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 1	access	access ¹⁾
	AFE1 2000 _H - AFE1 3FFF _H	8 Kbyte	Reserved	access ²⁾	access ¹⁾²⁾
	AFE1 4000 _H - AFF1 FFFF _H	1 Mbyte	Reserved	LMBBE & SPBBE	ignore
	AFF2 0000 _H - AFF5 FFFF _H	256 Kbyte	Reserved		
	AFF6 0000 _H - AFFF BFFF _H	624 Kbyte	Reserved		
	AFFF C000 _H - AFFF FFFF _H	16 Kbyte	Boot ROM (BROM)	access	
11	B000 0000 _H - BFFF FFFF _H	256 Mbyte	Reserved	SPBBE	SPBBE
12	C000 0000 _H - C000 0FFF _H	4 Kbyte	Overlay memory (OVRAM)	SPBBE	SPBBE
	C000 1000 _H - CFFF FFFF _H	≈ 256 Mbyte	Reserved	SPBBE	SPBBE

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Table 3-3 SPB Address Map of Segment 0 to 14 (cont'd)

Seg- ment	Address Range	Size	Description	Access Type	
				Read	Write
13	D000 0000 _H - D000 7FFF _H	32 Kbyte	DMI Local Data RAM (LDRAM)	SPBBE	SPBBE
	D000 8000 _H - D3FF FFFF _H	≈ 64 Mbyte	Reserved	SPBBE	SPBBE
	D400 0000 _H - D400 1FFF _H	8 Kbyte	PMI Scratch-Pad RAM (SPRAM)	SPBBE	SPBBE
	D400 2000 _H - D7FF FFFF _H	≈ 64 Mbyte	Reserved	SPBBE	SPBBE
	D800 0000 _H - DEFF FFFF _H	112 Mbyte	Reserved	SPBBE	SPBBE
	DF00 0000 _H - DFFF FFEF _H	≈ 16 Mbyte	Reserved (for Boot Rom)	SPBBE	SPBBE
	DFFF FFF0 _H - DFFF FFFF _H	16 byte	microROM	SPBBE	SPBBE

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Table 3-3 SPB Address Map of Segment 0 to 14 (cont'd)

Segment	Address Range	Size	Description	Access Type	
				Read	Write
14	E000 0000 _H - E7FF FFFF _H	128 MB	Reserved	LMBBE	LMBBE
	E800 0000 _H - E800 0FFF _H	4 Kbyte	Overlay memory (OVRAM)	access	access
	E800 1000 _H - E800 1FFF _H	4 Kbyte	Reserved	access ²⁾	access ²⁾
	E800 2000 _H - E83F FFFF _H	≈ 4 Mbyte	Reserved	LMBBE	LMBBE
	E840 0000 _H - E840 7FFF _H	32 Kbyte	DMI Local Data RAM (LDRAM)	access	access
	E840 8000 _H - E840 DFFF _H	24 Kbyte	Reserved	access ²⁾	access ²⁾
	E840 E000 _H - E84F FFFF _H	≈ 1 Mbyte	Reserved	LMBBE	LMBBE
	E850 0000 _H - E850 1FFF _H	8 Kbyte	PMI Scratch-Pad RAM (SPRAM)	access	access
	E850 2000 _H - E850 3FFF _H	8 Kbyte	Reserved	access ²⁾	access ²⁾
	E850 4000 _H - E85F FFFF _H	≈ 1 Mbyte	Reserved	LMBBE	LMBBE
	E860 C000 _H - EFFF FFFF _H	≈ 122 Mbyte	Reserved	LMBBE	LMBBE
	F000 0000 _H - FFFF FFFF _H	256 Mbyte	see Table 3-4		

1) Only applicable when writing Flash command sequences.

2) Read and write accesses to this address range will not generate any traps.

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3.3.4.2 Segment 15

Table 3-4 shows the address map of segment 15 as seen from the SPB bus masters DMA and OCDS. Please note that access in **Table 3-4** means only that an access to an address within the defined address range is not automatically incorrect or ignored. If an access is really addressing a correct address, it can be found in the detailed tables in the TC116x User's Manual, Register Overview's chapter.

Table 3-4 SPB Address Map of Segment 15

Unit	Address Range	Size	Access Type	
			Read	Write
System Control Unit (SCU) and Watchdog Timer (WDT)	F000 0000 _H - F000 00FF _H	256 byte	access	access
System Peripheral Bus Control Unit (SBCU)	F000 0100 _H - F000 01FF _H	256 byte	access	access
System Timer (STM)	F000 0200 _H - F000 02FF _H	256 byte	access	access
Reserved	F000 0300 _H - F000 03FF _H	–	SPBBE	SPBBE
On-Chip Debug Support (Cerberus)	F000 0400 _H - F000 04FF _H	256 byte	access	access
Reserved	F000 0500 _H - F000 07FF _H	–	SPBBE	SPBBE
MicroSecond Bus Controller 0 (MSC0)	F000 0800 _H - F000 08FF _H	256 byte	access	access
Reserved	F000 0900 _H - F000 09FF _H	–	SPBBE	SPBBE
Async./Sync. Serial Interface 0 (ASC0)	F000 0A00 _H - F000 0AFF _H	256 byte	access	access
Async./Sync. Serial Interface 1 (ASC1)	F000 0B00 _H - F000 0BFF _H	256 byte	access	access
Port 0	F000 0C00 _H - F000 0CFF _H	256 byte	access	access
Port 1	F000 0D00 _H - F000 0DFF _H	256 byte	access	access
Port 2	F000 0E00 _H - F000 0EFF _H	256 byte	access	access

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Table 3-4 SPB Address Map of Segment 15 (cont'd)

Unit	Address Range	Size	Access Type	
			Read	Write
Port 3	F000 0F00 _H - F000 0FFF _H	256 byte	access	access
Port 4	F000 1000 _H - F000 10FF _H	256 byte	access	access
Port 5	F000 1100 _H - F000 11FF _H	256 byte	access	access
Reserved	F000 1200 _H - F000 12FF _H	–	SPBBE	SPBBE
Reserved	F000 1300 _H - F000 13FF _H	–	SPBBE	SPBBE
Reserved	F000 1400 _H - F000 14FF _H	–	SPBBE	SPBBE
Reserved	F000 1500 _H - F000 15FF _H	–	SPBBE	SPBBE
Reserved	F000 1600 _H - F000 16FF _H	–	SPBBE	SPBBE
Reserved	F000 1700 _H - F000 17FF _H	–	SPBBE	SPBBE
General Purpose Timer Array 0 (GPTA0)	F000 1800 _H - F000 1FFF _H	8 × 256 byte	access	access
Reserved	F000 2000 _H - F000 27FF _H	–	SPBBE	SPBBE
Reserved	F000 2800 _H - F000 2FFF _H	–	SPBBE	SPBBE
Reserved	F000 3000 _H - F000 3BFF _H	–	SPBBE	SPBBE
Direct Memory Access Controller (DMA)	F000 3C00 _H - F000 3EFF _H	3 × 256 byte	access	access
Reserved	F000 3F00 _H - F000 3FFF _H	–	SPBBE	SPBBE
MultiCAN Controller (CAN)	F000 4000 _H - F000 5FFF _H	8 Kbyte	access ¹⁾	access ¹⁾

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Table 3-4 SPB Address Map of Segment 15 (cont'd)

Unit	Address Range	Size	Access Type	
			Read	Write
Reserved	F000 6000 _H - F003 FFFF _H	–	SPBBE	SPBBE
Reserved	F004 0000 _H - F004 3EFF _H	–	SPBBE	SPBBE
Reserved	F004 3F00 _H - F004 3FFF _H	256 byte	access ²⁾	access ²⁾
Reserved	F004 4000 _H - F004 FFFF _H	–	SPBBE	SPBBE
Reserved	F005 0000 _H - F005 1FFF _H	8 Kbyte	nE, 32 ³⁾	nE, 32 ³⁾
Reserved	F005 2000 _H - F005 FFFF _H	–	SPBBE	SPBBE
Reserved	F006 0000 _H - F006 2FFF _H	12 Kbyte	nE, 32 ³⁾	nE, 32 ³⁾
Reserved	F006 3000 _H - F007 FFFF _H	–	SPBBE	SPBBE
Reserved	F008 0000 _H - F00F FFFF _H	–	SPBBE	SPBBE
Reserved	F010 0000 _H - F010 00FF _H	–	SPBBE	SPBBE
Synchronous Serial Interface 0 (SSC0)	F010 0100 _H - F010 01FF _H	256 byte	access	access
Reserved	F010 0200 _H - F010 02FF _H	256 byte	access ²⁾	access ²⁾
Fast Analog-to-Digital Converter (FADC)	F010 0300 _H - F010 03FF _H	256 byte	access	access
Analog-to-Digital Converter 0 (ADC0)	F010 0400 _H - F010 05FF _H	2 × 256 byte	access	access
Reserved	F010 0600 _H - F010 07FF _H	–	SPBBE	SPBBE
Reserved	F010 0800 _H - F010 9FFF _H	–	SPBBE	SPBBE

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Table 3-4 SPB Address Map of Segment 15 (cont'd)

Unit		Address Range	Size	Access Type	
				Read	Write
Reserved		F010 A000 _H - F010 BFFF _H	–	SPBBE	SPBBE
Micro Link Interface 0 (MLI0)		F010 C000 _H - F010 C0FF _H	256 byte	access	access
Reserved		F010 C100 _H - F010 C1FF _H	256 byte	access ²⁾	access ²⁾
Memory Checker (MCHK)		F010 C200 _H - F010 C2FF _H	256 byte	access	access
Reserved		F010 C300 _H - F01D FFFF _H	–	SPBBE	SPBBE
MLI0 Small Transfer Windows		F01E 0000 _H - F01E 7FFF _H	4 × 8 Kbyte	access	access
Reserved		F01E 8000 _H - F01E FFFF _H	4 × 8 Kbyte	access ²⁾	access ²⁾
Reserved		F01F 0000 _H - F01F FFFF _H	–	SPBBE	SPBBE
MLI0 Large Transfer Windows		F020 0000 _H - F023FFFF _H	4 × 64 Kbyte	access	access
Reserved		F024 0000 _H - F027 FFFF _H	4 × 64 Kbyte	access ²⁾	access ²⁾
Reserved		F028 0000 _H - F7E0 FEFF _H	–	SPBBE	SPBBE
CPU	CPU Slave Interface Registers (CPS)	F7E0 FF00 _H - F7E0 FFFF _H	256 byte	access	access
	CPU Core SFRs & GPRs	F7E1 0000 _H - F7E1 FFFF _H	64 Kbyte	access	access
Reserved		F7E2 0000 _H - F7FF FFFF _H	–	SPBBE	SPBBE
Reserved		F800 0000 _H - F800 03FF _H	–	SPBBE	SPBBE
Reserved		F800 0400 _H - F800 04FF _H	–	LMBBE & SPBBE	LMBBE

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Table 3-4 SPB Address Map of Segment 15 (cont'd)

Unit		Address Range	Size	Access Type	
				Read	Write
Program Memory Unit (PMU)		F800 0500 _H - F800 05FF _H	256 byte	access	access
Reserved		F800 0600 _H - F800 0FFF _H	–	LMBBE & SPBBE	LMBBE
Flash Register		F800 1000 _H - F800 23FF _H	5 Kbyte	access	access
Reserved		F800 2400 _H - F801 00FF _H	–	LMBBE & SPBBE	LMBBE
Reserved		F801 0100 _H - F801 01FF _H	–	LMBBE & SPBBE	LMBBE
Reserved		F801 0200 _H - F87F F9FF _H	–	LMBBE & SPBBE	LMBBE
Reserved		F87F FA00 _H - F87F FAFF _H	–	LMBBE & SPBBE	LMBBE
Reserved		F87F FB00 _H - F87F FBFF _H	–	LMBBE & SPBBE	LMBBE
CPU	DMI Registers	F87F FC00 _H - F87F FCFF _H	256 byte	access	access
	PMI Registers	F87F FD00 _H - F87F FDFF _H	256 byte	access	access
Local Memory Bus Control Unit (LBCU)		F87F FE00 _H - F87F FEFF _H	256 byte	access	access
LFI Bridge		F87F FF00 _H - F87F FFFF _H	256 byte	access	access
Reserved		F880 0000 _H - FFFF FFFF _H	–	LMBBE & SPBBE	LMBBE

- 1) For TC1161, read and write accesses to this address range will not generate any traps.
- 2) Read and write accesses to this address range will not generate any traps.
- 3) For “32” access type, read and write accesses to this address range will not generate any traps.

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3.3.5 Address Map of the Local Memory Bus (LMB)

Table 3-5 shows the address map as seen from the LMB bus masters (PMI and DMI).

Table 3-5 LMB Address Map

Segment	Address Range	Size	Description	Action	
				Read	Write
0-7 ¹⁾	0000 0000 _H - 0000 0007 _H	8 byte	Reserved (virtual address space)	MPN trap	MPN trap
	0000 0008 _H - 7FFF FFFF _H	8 × 256 Mbyte		SPBBET	SPBBE
8 ¹⁾	8000 0000 _H - 800F FFFF _H	1 Mbyte	Program Flash (PFLASH)	access	access ²⁾
	8010 0000 _H - 8017 7FFF _H	≈ 0.5 Mbyte	Reserved	access ³⁾	access ²⁾³⁾
	8017 8000 _H - 807F FFFF _H	6.5 Mbyte	Reserved	LMBBET	LMBBET
	8080 0000 _H - 8FDF FFFF _H	246 Mbyte	Reserved	LMBBET	LMBBET
	8FE0 0000 _H - 8FE0 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 0	access	access ²⁾
	8FE0 2000 _H - 8FE0 3FFF _H	8 Kbyte	Reserved	access ³⁾	access ²⁾³⁾
	8FE0 4000 _H - 8FE0 FFFF _H	48 Kbyte	Reserved	LMBBET	LMBBET
	8FE1 0000 _H - 8FE1 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 1	access	access ²⁾
	8FE1 2000 _H - 8FE1 3FFF _H	8 Kbyte	Reserved	access ³⁾	access ²⁾³⁾
	8FE1 4000 _H - 8FF1 FFFF _H	1 Mbyte	Reserved	LMBBET	LMBBET
	8FF2 0000 _H - 8FF5 FFFF _H	256 Kbyte	Reserved		
	8FF6 0000 _H - 8FFF BFFF _H	624 Kbyte	Reserved		
	8FFF C000 _H - 8FFF FFFF _H	16 Kbyte	Boot ROM (BROM)	access	

Advance Information

Functional Description

Table 3-5 LMB Address Map (cont'd)

Segment	Address Range	Size	Description	Action	
				Read	Write
9 ¹⁾	9000 0000 _H - 9FFF FFFF _H	256 Mbyte	Reserved	SPBBET	SPBBE
10 ⁴⁾	A000 0000 _H - A00F FFFF _H	1 Mbyte	Program Flash (PFLASH)	access	access ²⁾
	A010 0000 _H - A017 FFFF _H	≈ 0.5 Mbyte	Reserved	access ³⁾	access ²⁾³⁾
	A017 8000 _H - A07F FFFF _H	6.5 Mbyte	Reserved	LMBBET	LMBBET
	A080 0000 _H - AFDF FFFF _H	246 Mbyte	Reserved	LMBBET	LMBBET
	AFE0 0000 _H - AFE0 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 0	access	access ²⁾
	AFE0 2000 _H - AFE0 3FFF _H	8 Kbyte	Reserved	access ³⁾	access ²⁾³⁾
	AFE0 4000 _H - AFE0 FFFF _H	48 Kbyte	Reserved	LMBBET	LMBBET
	AFE1 0000 _H - AFE1 1FFF _H	8 Kbyte	Data Flash (DFLASH) Bank 1	access	access ²⁾
	AFE1 2000 _H - AFE1 3FFF _H	8 Kbyte	Reserved	access ³⁾	access ²⁾³⁾
	AFE1 4000 _H - AFF1 FFFF _H	1 Mbyte	Reserved	LMBBET	LMBBET
	AFF2 0000 _H - AFF5 FFFF _H	256 Kbyte	Reserved		
	AFF6 0000 _H - AFFF BFFF _H	624 Kbyte	Reserved		
	AFFF C000 _H - AFFF FFFF _H	16 Kbyte	Boot ROM (BROM)	access	
11 ⁴⁾	B000 0000 _H - BFFF FFFF _H	256 Mbyte	Reserved	SPBBET	SPBBE

Advance Information

Functional Description

Table 3-5 LMB Address Map (cont'd)

Seg- ment	Address Range	Size	Description	Action	
				Read	Write
12 ¹⁾	C000 0000 _H - C000 0FFF _H	4 Kbyte	Overlay memory (OVRAM)	access	access
	C000 1000 _H - C000 1FFF _H	4 Kbyte	Reserved	access ³⁾	access ³⁾
	C000 2000 _H - CFFF FFFF _H	256 Mbyte	Reserved	LMBBET	LMBBET
13 ⁴⁾	D000 0000 _H - D000 7FFF _H	32 Kbyte	DMI Local Data RAM (LDRAM)	access SPBBE	access SPBBE
	D000 8000 _H - D000 DFFF _H	24 Kbyte	Reserved	access SPBBE ⁵⁾	access SPBBE ⁵⁾
	D000 E000 _H - D3FF FFFF _H	64 Mbyte	Reserved	LMBBET	LMBBET
	D400 0000 _H - D400 1FFF _H	8 Kbyte	PMI Scratch-Pad RAM (SPRAM)	access	access
	D400 2000 _H - D400 3FFF _H	8 Kbyte	Reserved	access ³⁾	access ³⁾
	D400 4000 _H - D7FF FFFF _H	≈ 64 Mbyte	Reserved	LMBBET	LMBBET
	D800 0000 _H - DEFF FFFF _H	112 Mbyte	Reserved		
	DF00 0000 _H - DFFF FFEF _H	16 Mbyte	Reserved (for Boot Rom)		
14 ⁴⁾	E000 0000 _H - E7FF FFFF _H	128 Mbyte	Reserved	LMBBET	LMBBET
	E800 0000 _H - EFFF FFFF _H	128 Mbyte	Reserved	LMBBET	LMBBET

Advance Information

Functional Description

Table 3-5 LMB Address Map (cont'd)

Segment	Address Range	Size	Description	Action	
				Read	Write
15	F000 0000 _H - F7FF FFFF _H	128 Mbyte	Address map is identical to FPI Bus segment 15 address map (see Table 3-5) Reserved areas give an bus error.	SPBBET	SPBBE
	F800 0000 _H - F800 03FF _H	1 Kbyte	Reserved	LMBBET	LMBBET
	F800 0400 _H - F800 04FF _H	256 byte	Reserved	LMBBET	LMBBET
	F800 0500 _H - F800 05FF _H	256 byte	Program Memory Unit (PMU)	access	access
	F800 0600 _H - F800 0FFF _H	≈ 2 Kbyte	Reserved	LMBBET	LMBBET
	F800 1000 _H - F800 23FF _H	5 Kbyte	Flash Registers	access	access
	F800 2400 _H - F87F FBFF _H	≈ 8 Mbyte	Reserved	LMBBET	LMBBET
	F87F FC00 _H - F87F FCFF _H	256 byte	Data Memory Interface Unit	access	access
	F87F FD00 _H - F87F FDFF _H	256 byte	Program Memory Interface Unit	access	access
	F87F FE00 _H - F87F FEFF _H	256 byte	LBCU register space	access	access
	F87F FF00 _H - F87F FFFF _H	256 byte	LFI Bus Bridge	access	access
	F880 0000 _H - FFFF FFFF _H	≈ 119 Mbyte	Reserved	LMBBET	LMBBET

- 1) Cached area
- 2) Only applicable when writing Flash command sequences
- 3) Read and write accesses to this address range will not generate any traps.
- 4) Non-cached area
- 5) If accessible, read and write accesses to this address range will not generate any traps.

3.4 Memory Protection System

The TC1161/TC1162 memory protection system specifies the addressable range and read/write permissions of memory segments available to the current executing task. The memory protection system controls the position and range of addressable segments in memory. It also controls the types of read and write operations allowed within addressable memory segments. Any illegal memory access is detected by the memory protection hardware, which then invokes the appropriate Trap Service Routine (TSR) to handle the error. Thus, the memory protection system protects critical system functions against both software and hardware errors. The memory protection hardware can also generate signals to the Debug Unit to facilitate tracing illegal memory accesses.

There are two Memory Protection Register Sets in the TC1161/TC1162, numbered 0 and 1, which specify memory protection ranges and permissions for code and data. The PSW.PRS bit field determines which of these is the set currently in use by the CPU. As the TC1161/TC1162 uses a Harvard-style memory architecture, each Memory Protection Register Set is broken down into a Data Protection Register Set and a Code Protection Register Set. Each Data Protection Register Set can specify up to four address ranges to receive a particular protection modes. Each Code Protection Register Set can specify up to two address ranges to receive a particular protection modes.

Each Data Protection Register Sets and Code Protection Register Sets determines the range and protection modes for a separate memory area. Each set contains a pair of registers which determine the address range (the Data Segment Protection Registers and Code Segment Protection Registers) and one register (Data Protection Mode Register) which determines the memory access modes that applies to the specified range.

3.5 DMA Controller and Memory Checker

The DMA Controller of the TC1161/TC1162 transfers data from data source locations to data destination locations without intervention of the CPU or other on-chip devices. One data move operation is controlled by one DMA channel. Eight DMA channels are provided in one DMA Sub-Block. The Bus Switch provides the connection of the DMA Sub-Block to the two FPI Bus interfaces and an MLI bus interface. In the TC1161/TC1162, the FPI Bus interfaces are connected to the System Peripheral Bus and the DMA Bus. The third specific bus interface provides a connection to Micro Link Interface module (one MLI module in the TC1161/TC1162) and other DMA-related devices (Memory Checker module in the TC1161/TC1162). Clock control, address decoding, DMA request wiring, and DMA interrupt service request control are implementation-specific and managed outside the DMA controller kernel. **Figure 3-1** shows the implementation details and interconnections of the DMA module.

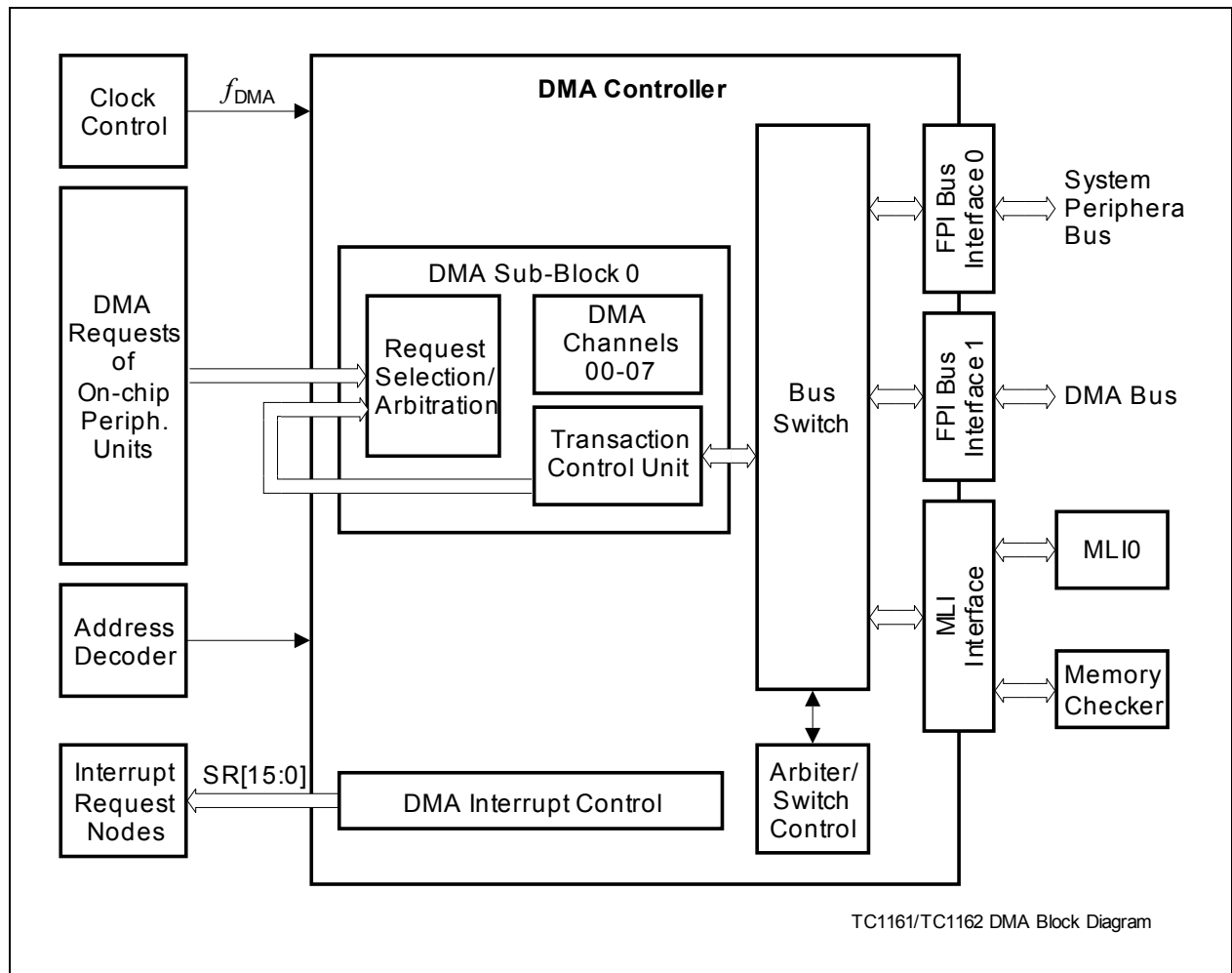


Figure 3-1 DMA Controller Block Diagram

Advance Information

Functional Description

Features

- 8 independent DMA channels
 - 8 DMA channels in the DMA Sub-Block
 - Up to 8 selectable request inputs per DMA channel
 - 2-level programmable priority of DMA channels within the DMA Sub-Block
 - Software and hardware DMA request
 - Hardware requests by selected on-chip peripherals and external inputs
- Programmable priority of the DMA Sub-Blocks on the bus interfaces
- Buffer capability for move actions on the buses (at least 1 move per bus is buffered).
- Individually programmable operation modes for each DMA channel
 - Single Mode: stops and disables DMA channel after a predefined number of DMA transfers
 - Continuous Mode: DMA channel remains enabled after a predefined number of DMA transfers; DMA transaction can be repeated.
 - Programmable address modification
- Full 32-bit addressing capability of each DMA channel
 - 4 Gbyte address range
 - Support of circular buffer addressing mode
- Programmable data width of DMA transfer/transaction: 8-bit, 16-bit, or 32-bit
- Micro Link bus interface support
- Register set for each DMA channel
 - Source and destination address register
 - Channel control and status register
 - Transfer count register
- Flexible interrupt generation (the service request node logic for the MLI channels is also implemented in the DMA module)
- All buses connected to the DMA module must work at the same frequency.
- Read/write requests of the System Bus side to the peripherals on DMA Bus are bridged to the DMA Bus (only the DMA is the master on the DMA bus), allowing easy access to these peripherals by CPU

Memory Checker

The Memory Checker Module (MCHK) makes it possible to check the data consistency of memories. Any SPB bus master may access the memory checker. It is preferable the DMA does it as described hereafter. It uses DMA 8-bit, 16-bit, or 32-bit moves to read from the selected address area and to write the value read in a memory checker input register. With each write operation to the memory checker input register, a polynomial checksum calculation is triggered and the result of the calculation is stored in the memory checker result register.

The memory checker uses the standard Ethernet polynomial, which is given by:

$$G^{32} = x^{32} + x^{26} + x^{23} + x^{22} + x^{16} + x^{12} + x^{11} + x^{10} + x^8 + x^7 + x^5 + x^4 + x^2 + x + 1$$

Advance Information**Functional Description**

Note: Although the polynomial above is used for generation, the generation algorithm differs from the one that is used by the Ethernet protocol.

3.6 Interrupt System

The TC1161/TC1162 interrupt system provides a flexible and time-efficient means of processing interrupts. An interrupt request is serviced by the CPU, which is called the "Service Provider". Interrupt requests are called "Service Requests" rather than "Interrupt Requests" in this document.

Each peripheral in the TC1161/TC1162 can generate service requests. Additionally, the Bus Control Units, the Debug Unit, and even the CPU itself can generate service requests to the Service Provider.

As shown in [Figure 3-2](#), each TC1161/TC1162 unit that can generate service requests is connected to one or multiple Service Request Nodes (SRN). Each SRN contains a Service Request Control Register `mod_SRCx`, where "mod" is the identifier of the service requesting unit and "x" an optional index. The CPU Interrupt Arbitration Bus connects the SRNs with the Interrupt Control Unit (ICU), which arbitrates service requests for the CPU and administers the CPU Interrupt Arbitration Bus.

The Debug Unit can generate service requests to the CPU. The CPU makes service requests directly to itself (via the ICU). The CPU Service Request Nodes are activated through software.

Depending on the selected system clock frequency f_{SYS} , the number of f_{SYS} clock cycles per arbitration cycle must be selected as follows:

- $f_{\text{SYS}} < 60 \text{ MHz}$: `ICR.CONECYC = 1`
- $f_{\text{SYS}} > 60 \text{ MHz}$: `ICR.CONECYC = 0`

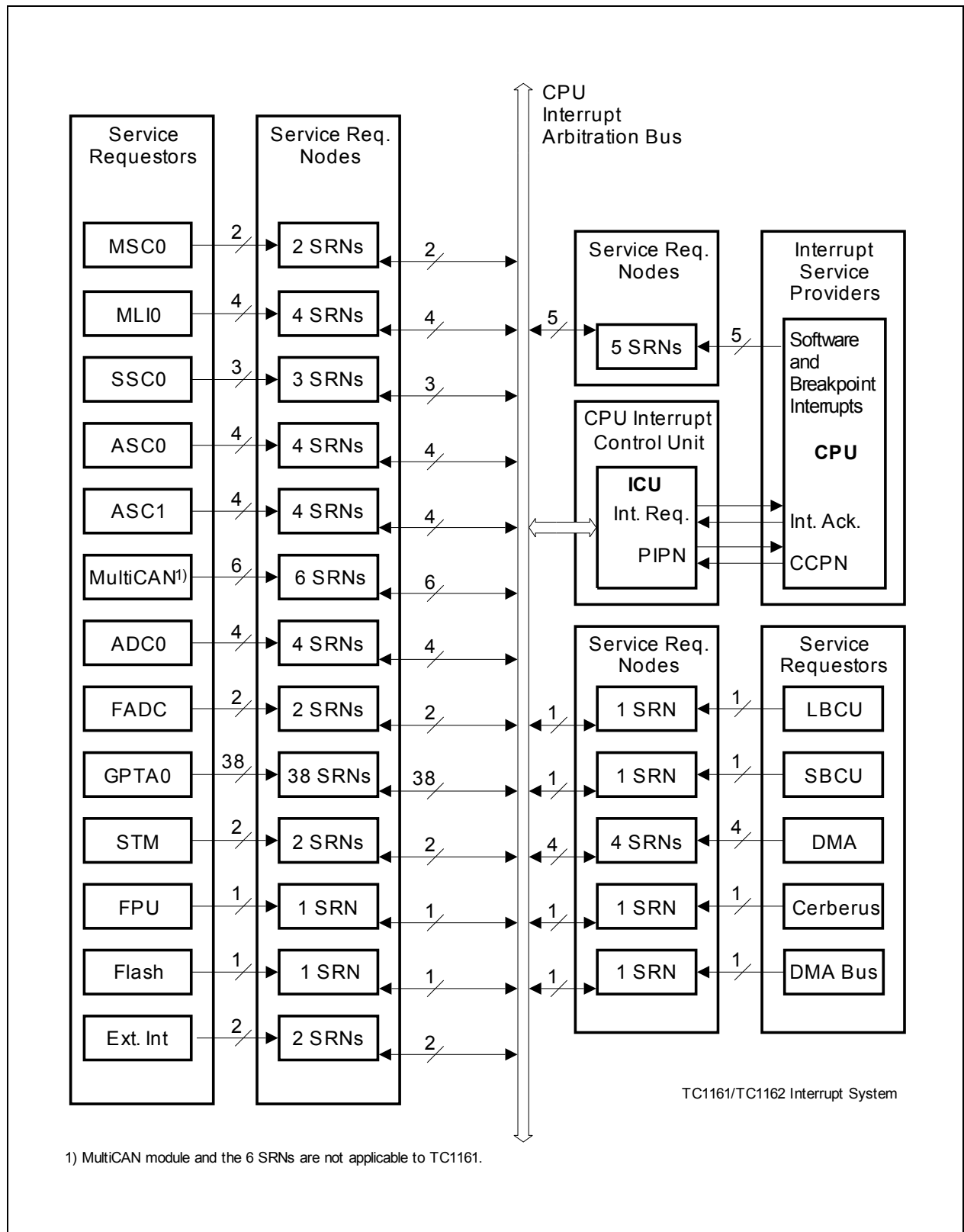


Figure 3-2 Block Diagram of the TC1161/TC1162 Interrupt System

3.7 Asynchronous/Synchronous Serial Interfaces (ASC0, ASC1)

Figure 3-3 shows a global view of the functional blocks and interfaces of the two Asynchronous/Synchronous Serial Interfaces, ASC0 and ASC1.

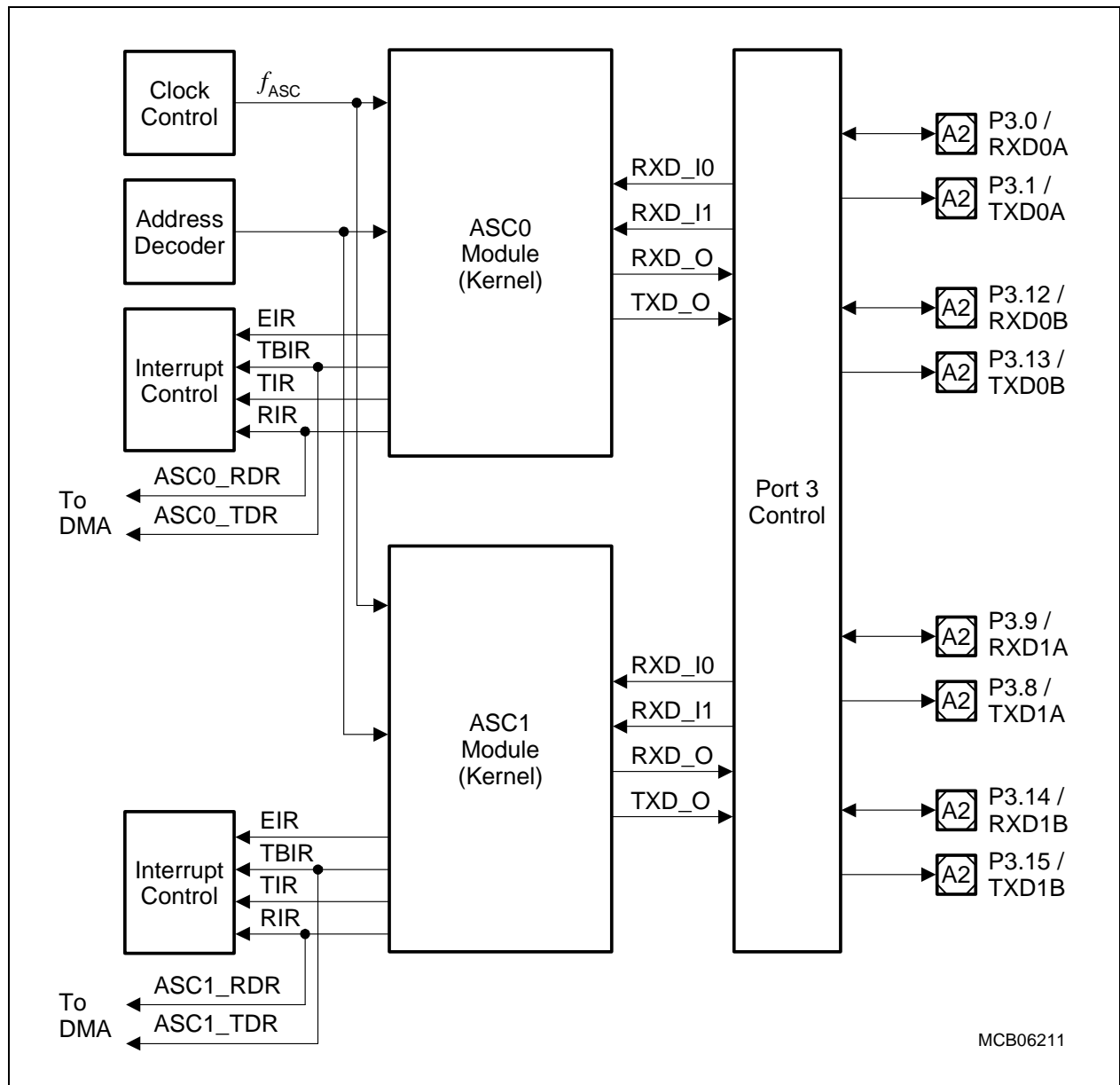


Figure 3-3 Block Diagram of the ASC Interfaces

The ASC provides serial communication between the TC1161/TC1162 and other microcontrollers, microprocessors, or external peripherals.

The ASC supports full-duplex asynchronous communication and half-duplex synchronous communication. In Synchronous Mode, data is transmitted or received synchronous to a shift clock that is generated by the ASC internally. In Asynchronous Mode, 8-bit or 9-bit data transfer, parity generation, and the number of stop bits can be

Advance Information**Functional Description**

selected. Parity, framing, and overrun error detection are provided to increase the reliability of data transfers. Transmission and reception of data is double-buffered. For multiprocessor communication, a mechanism is included to distinguish address bytes from data bytes. Testing is supported by a loop-back option. A 13-bit baud rate generator provides the ASC with a separate serial clock signal, which can be accurately adjusted by a prescaler implemented as fractional divider.

Features

- Full-duplex asynchronous operating modes
 - 8-bit or 9-bit data frames, LSB first
 - Parity-bit generation/checking
 - One or two stop bits
 - Baud rate from 4.1Mbit/s to 0.98 bit/s (@ 66 MHz module clock)
 - Multiprocessor mode for automatic address/data byte detection
 - Loop-back capability
- Half-duplex 8-bit synchronous operating mode
 - Baud rate from 8.25 Mbit/s to 671.4 bit/s (@ 66 MHz module clock)
- Double-buffered transmitter/receiver
- Interrupt generation
 - On a transmit buffer empty condition
 - On a transmit last bit of a frame condition
 - On a receive buffer full condition
 - On an error condition (frame, parity, overrun error)

3.8 High-Speed Synchronous Serial Interfaces (SSC0)

Figure 3-4 shows a global view of the functional blocks and interfaces of the high-speed Synchronous Serial Interfaces, SSC0.

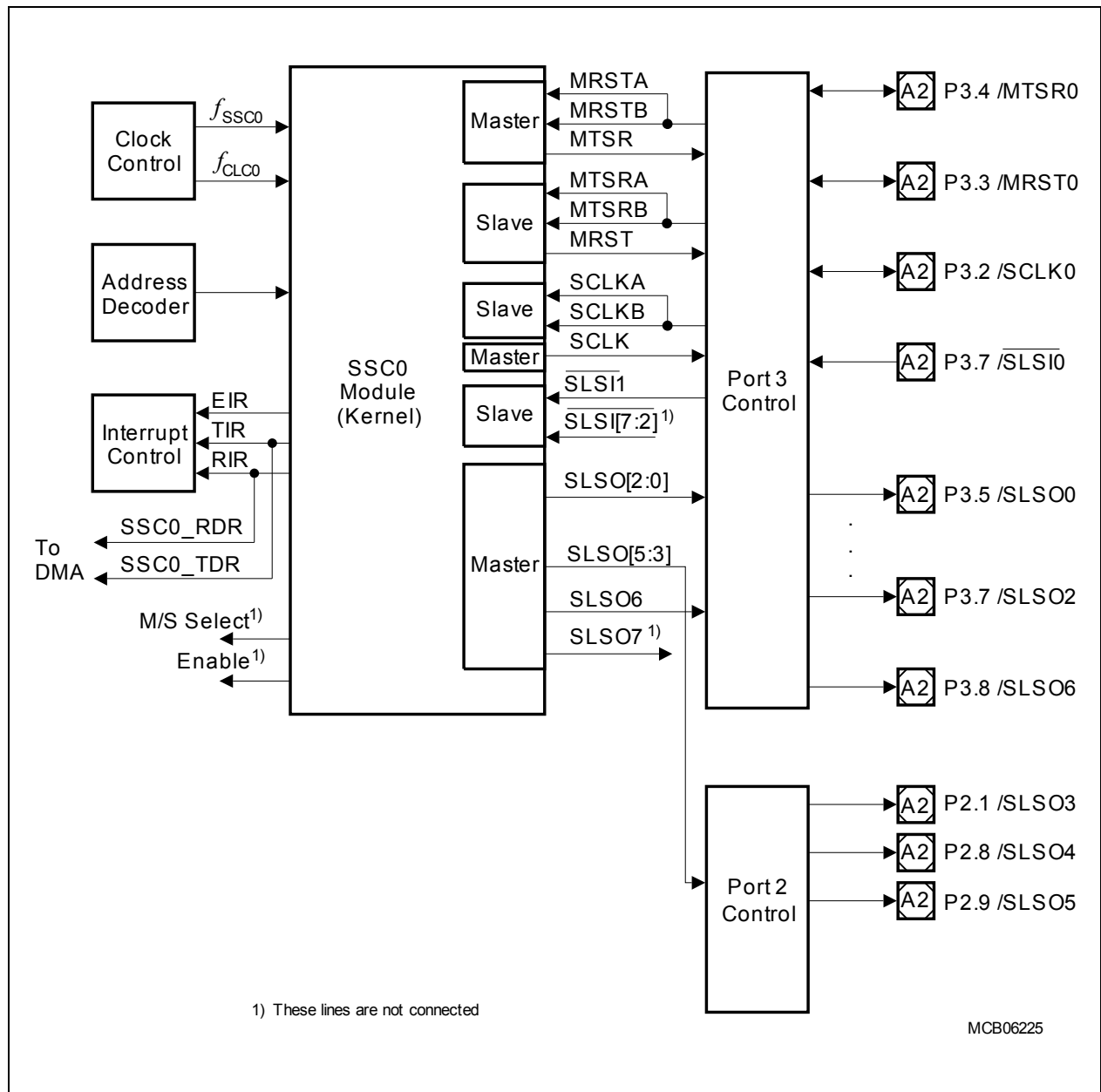


Figure 3-4 Block Diagram of the SSC Interfaces

The SSC supports full-duplex and half-duplex serial synchronous communication up to 33 MBaud (@ 66 MHz module clock). The serial clock signal can be generated by the SSC itself (Master Mode) or can be received from an external master (Slave Mode). Data width, shift direction, clock polarity and phase are programmable. This allows communication with SPI-compatible devices. Transmission and reception of data is

Advance Information**Functional Description**

double-buffered. A shift clock generator provides the SSC with a separate serial clock signal. Seven slave select inputs are available for Slave Mode operation. Eight programmable slave select outputs (chip selects) are supported in Master Mode.

Features

- Master and Slave Mode operation
 - Full-duplex or half-duplex operation
 - Automatic pad control possible
- Flexible data format
 - Programmable number of data bits: 2 to 16 bits
 - Programmable shift direction: LSB or MSB shift first
 - Programmable clock polarity: Idle low or idle high state for the shift clock
 - Programmable clock/data phase: Data shift with leading or trailing edge of the shift clock
- Baud rate generation from 503.5 bit/s to 33 Mbit/s (@ 66 MHz module clock)
- Interrupt generation
 - On a transmitter empty condition
 - On a receiver full condition
 - On an error condition (receive, phase, baud rate, transmit error)
- Flexible SSC pin configuration
- Seven slave select inputs $\overline{\text{SLSI}}[7:1]$ in Slave Mode
- Eight programmable slave select outputs $\text{SLSO}[7:0]$ in Master Mode
 - Automatic SLSO generation with programmable timing
 - Programmable active level and enable control

3.9 Micro Second Bus Interfaces (MSC0)

The MSC interface provides a serial communication link typically used to connect power switches or other peripheral devices. The serial communication link includes a fast synchronous downstream channel and a slow asynchronous upstream channel.

Figure 3-5 shows a global view of the MSC interface signals.

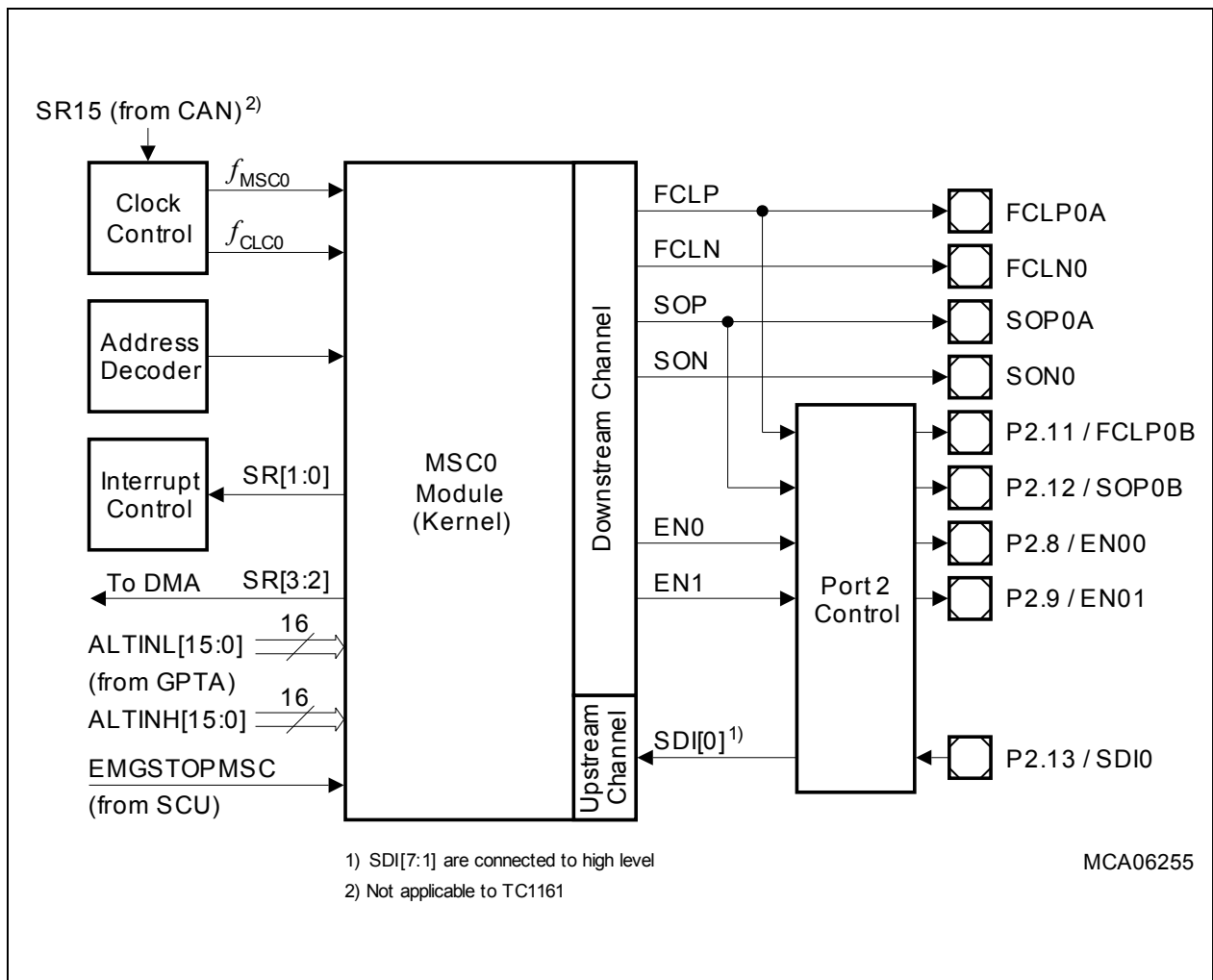


Figure 3-5 Block Diagram of the MSC Interfaces

The downstream and upstream channels of the MSC module communicate with the external world via nine I/O lines. Eight output lines are required for the serial communication of the downstream channel (clock, data, and enable signals). One out of eight input lines SDI[7:0] is used as serial data input signal for the upstream channel. The source of the serial data to be transmitted by the downstream channel can be MSC register contents or data that is provided at the ALTINL/ALTINH input lines. These input lines are typically connected to other on-chip peripheral units (for example with a timer unit like the GPTA). An emergency stop input signal makes it possible to set bits of the serial data stream to dedicated values in emergency cases.

Advance Information**Functional Description**

Clock control, address decoding, and interrupt service request control are managed outside the MSC module kernel. Service request outputs are able to trigger an interrupt or a DMA request.

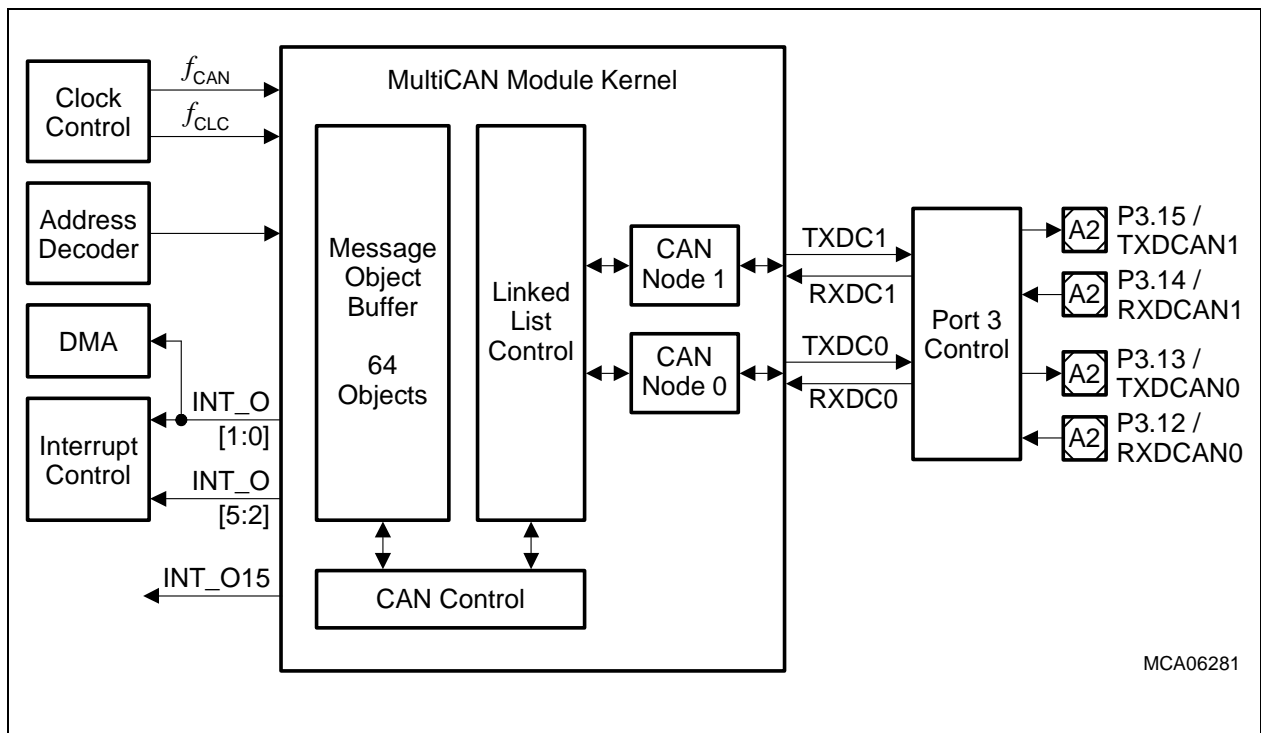
Features

- Fast synchronous serial interface to connect power switches in particular, or other peripheral devices via serial buses
- High-speed synchronous serial transmission on downstream channel
 - Serial output clock frequency: $f_{FCL} = f_{MSC}/2$
 - Fractional clock divider for precise frequency control of serial clock f_{MSC}
 - Command, data, and passive frame types
 - Start of serial frame: Software-controlled, timer-controlled, or free-running
 - Programmable upstream data frame length (16 or 12 bits)
 - Transmission with or without SEL bit
 - Flexible chip select generation indicates status during serial frame transmission
 - Emergency stop without CPU intervention
- Low-speed asynchronous serial reception on upstream channel
 - Baud rate: f_{MSC} divided by 4, 8, 16, 32, 64, 128, or 256
 - Standard asynchronous serial frames
 - Parity error checker
 - 8-to-1 input multiplexer for SDI lines
 - Built-in spike filter on SDI lines

3.10 MultiCAN Controller (CAN)

Note: **Section 3.10** is not applicable to TC1161.

Figure 3-6 shows a global view of the MultiCAN module with its functional blocks and interfaces.



MCA06281

Figure 3-6 Block Diagram of MultiCAN Module

The MultiCAN module contains two independently-operating CAN nodes with Full-CAN functionality that are able to exchange Data and Remote Frames via a gateway function. Transmission and reception of CAN frames is handled in accordance with CAN specification V2.0 B (active). Each CAN node can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers.

Both CAN nodes share a common set of message objects. Each message object can be individually allocated to one of the CAN nodes. Besides serving as a storage container for incoming and outgoing frames, message objects can be combined to build gateways between the CAN nodes or to setup a FIFO buffer.

The message objects are organized in double-chained linked lists, where each CAN node has its own list of message objects. A CAN node stores frames only into message objects that are allocated to the message object list of the CAN node, and it transmits only messages belonging to this message object list. A powerful, command-driven list controller performs all message object list operations.

Advance Information**Functional Description**

The bit timings for the CAN nodes are derived from the module timer clock (f_{CAN}), and

3.11 Micro Link Serial Bus Interface (MLI0)

The Micro Link Interface is a fast synchronous serial interface that allows data exchange between microcontrollers of the 32-bit AUDO microcontroller family without intervention of a CPU or other bus masters. **Figure 3-7** shows how two microcontrollers are typically connected together via their MLI interface. The MLI operates in both microcontrollers as a bus master on the system bus.

Figure 3-7 Typical Micro Link Interface Connection

Features

- Synchronous serial communication between MLI transmitters and MLI receivers located on the same or on different microcontroller devices
- Automatic data transfer/request transactions between local/remote controller
- Fully transparent read/write access supported (= remote programming)

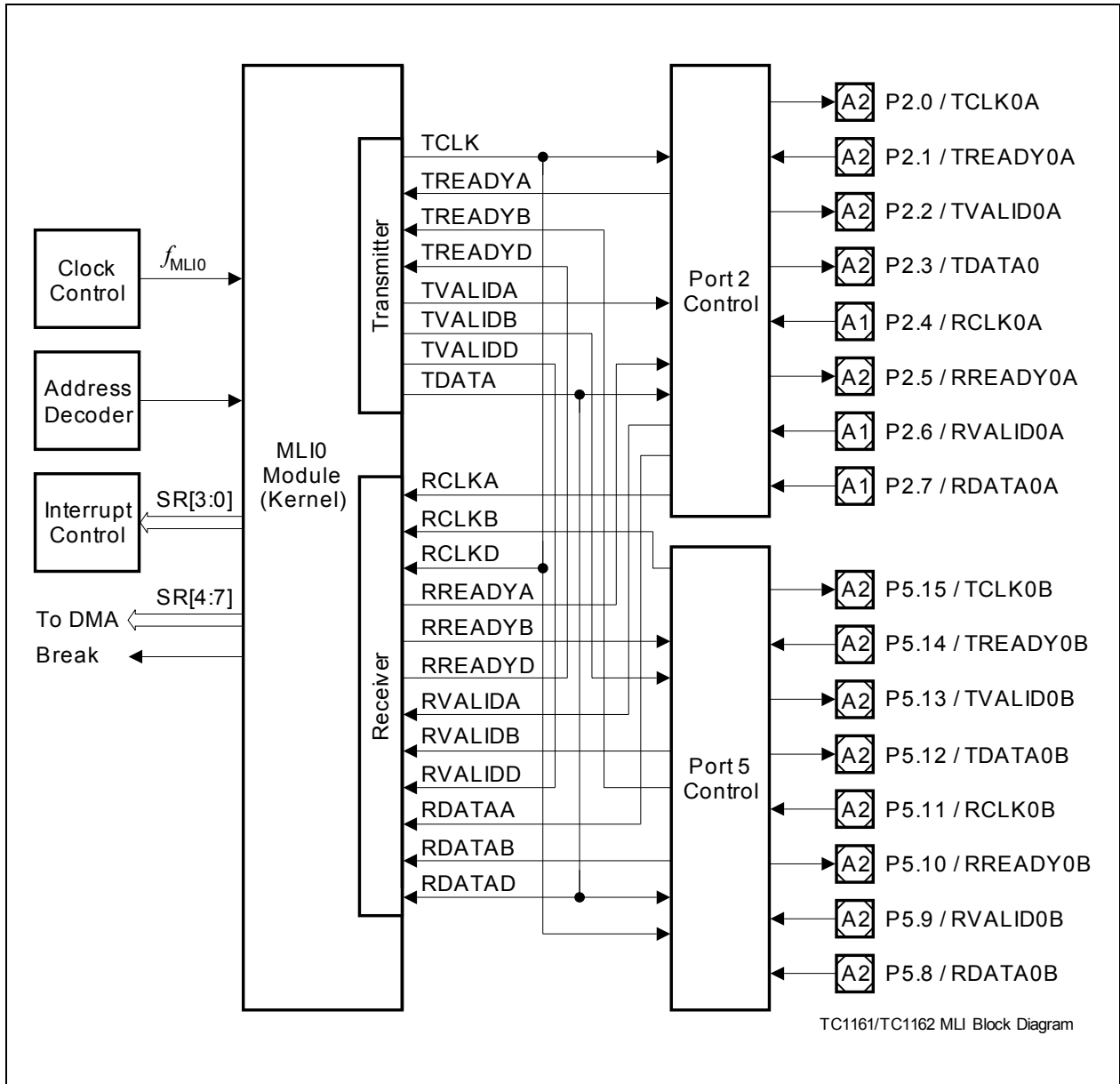


Figure 3-8 Block Diagram of the MLI Module

3.12 General Purpose Timer Array

The GPTA provides a set of timer, compare, and capture functionalities that can be flexibly combined to form signal measurement and signal generation units. They are optimized for tasks typical of electrical motor control applications, but can also be used to generate simple and complex signal waveforms needed in other industrial applications.

The TC1161/TC1162 contains one General Purpose Timer Array (GPTA0). **Figure 3-9** shows a global view of the GPTA module.

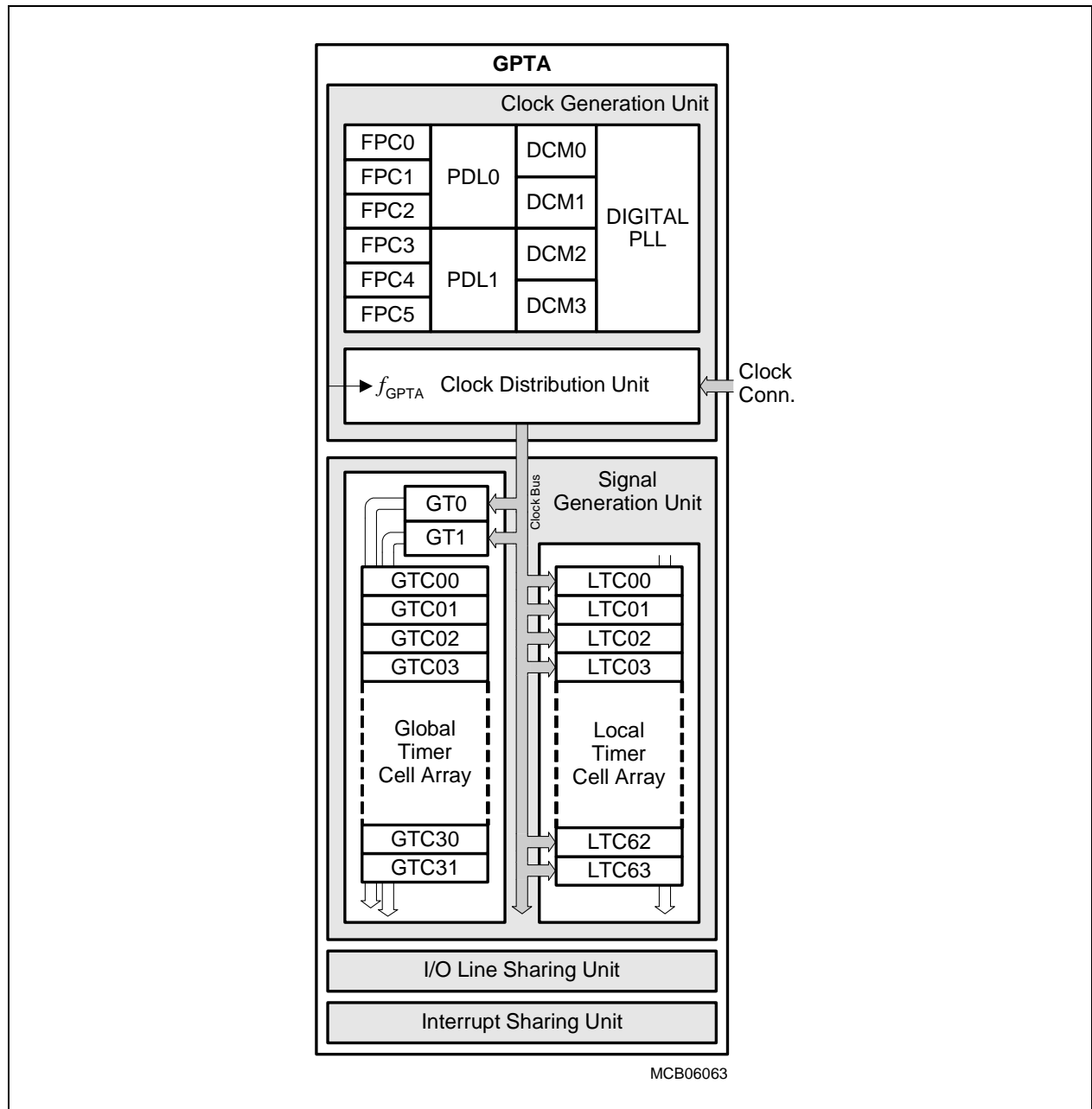


Figure 3-9 Block Diagram of the GPTA Module

3.12.1 Functionality of GPTA0

The General Purpose Timer Array GPTA0 provides a set of hardware modules required for high-speed digital signal processing:

- Filter and Prescaler Cells (FPC) support input noise filtering and prescaler operation.
- Phase Discrimination Logic units (PDL) decode the direction information output by a rotation tracking system.
- Duty Cycle Measurement Cells (DCM) provide pulse-width measurement capabilities.
- A Digital Phase Locked Loop unit (PLL) generates a programmable number of GPTA module clock ticks during an input signal's period.
- Global Timer units (GT) driven by various clock sources are implemented to operate as a time base for the associated Global Timer Cells.
- Global Timer Cells (GTC) can be programmed to capture the contents of a Global Timer on an external or internal event. A GTC may also be used to control an external port pin depending on the result of an internal compare operation. GTCs can be logically concatenated to provide a common external port pin with a complex signal waveform.
- Local Timer Cells (LTC) operating in Timer, Capture, or Compare Mode may also be logically tied together to drive a common external port pin with a complex signal waveform. LTCs — enabled in Timer Mode or Capture Mode — can be clocked or triggered by various external or internal events.

Input lines can be shared by an LTC and a GTC to trigger their programmed operation simultaneously.

The following list summarizes the specific features of the GPTA unit.

Clock Generation Unit

- Filter and Prescaler Cell (FPC)
 - Six independent units
 - Three basic operating modes:
Prescaler, Delayed Debounce Filter, Immediate Debounce Filter
 - Selectable input sources:
Port lines, GPTA module clock, FPC output of preceding FPC cell
 - Selectable input clocks:
GPTA module clock, prescaled GPTA module clock, DCM clock, compensated or uncompensated PLL clock
 - $f_{\text{GPTA}}/2$ maximum input signal frequency in Filter Modes
- Phase Discriminator Logic (PDL)
 - Two independent units
 - Two operating modes (2- and 3-sensor signals)
 - $f_{\text{GPTA}}/4$ maximum input signal frequency in 2-sensor Mode, $f_{\text{GPTA}}/6$ maximum input signal frequency in 3-sensor Mode

Advance Information

Functional Description

- Duty Cycle Measurement (DCM)
 - Four independent units
 - 0 - 100% margin and time-out handling
 - f_{GPTA} maximum resolution
 - $f_{GPTA}/2$ maximum input signal frequency
- Digital Phase Locked Loop (PLL)
 - One unit
 - Arbitrary multiplication factor between 1 and 65535
 - f_{GPTA} maximum resolution
 - $f_{GPTA}/2$ maximum input signal frequency
- Clock Distribution Unit (CDU)
 - One unit
 - Provides nine clock output signals:
 f_{GPTA} , divided f_{GPTA} clocks, FPC1/FPC4 outputs, DCM clock, LTC prescaler clock

Signal Generation Unit

- Global Timers (GT)
 - Two independent units
 - Two operating modes (Free-Running Timer and Reload Timer)
 - 24-bit data width
 - f_{GPTA} maximum resolution
 - $f_{GPTA}/2$ maximum input signal frequency
- Global Timer Cell (GTC)
 - 32 units related to the Global Timers
 - Two operating modes (Capture, Compare and Capture after Compare)
 - 24-bit data width
 - f_{GPTA} maximum resolution
 - $f_{GPTA}/2$ maximum input signal frequency
- Local Timer Cell (LTC)
 - 64 independent units
 - Three basic operating modes (Timer, Capture and Compare) for 63 units
 - Special compare modes for one unit
 - 16-bit data width
 - f_{GPTA} maximum resolution
 - $f_{GPTA}/2$ maximum input signal frequency

Interrupt Control Unit

- 111 interrupt sources, generating up to 38 service requests

Advance Information**Functional Description****I/O Sharing Unit**

- Interconnecting inputs and outputs from internal clocks, FPC, GTC, LTC, ports, and MSC interface

3.13 Analog-to-Digital Converter (ADC0)

Section 3.13 shows the global view of the ADC module with its functional blocks and interfaces and the features which are provided by the module.

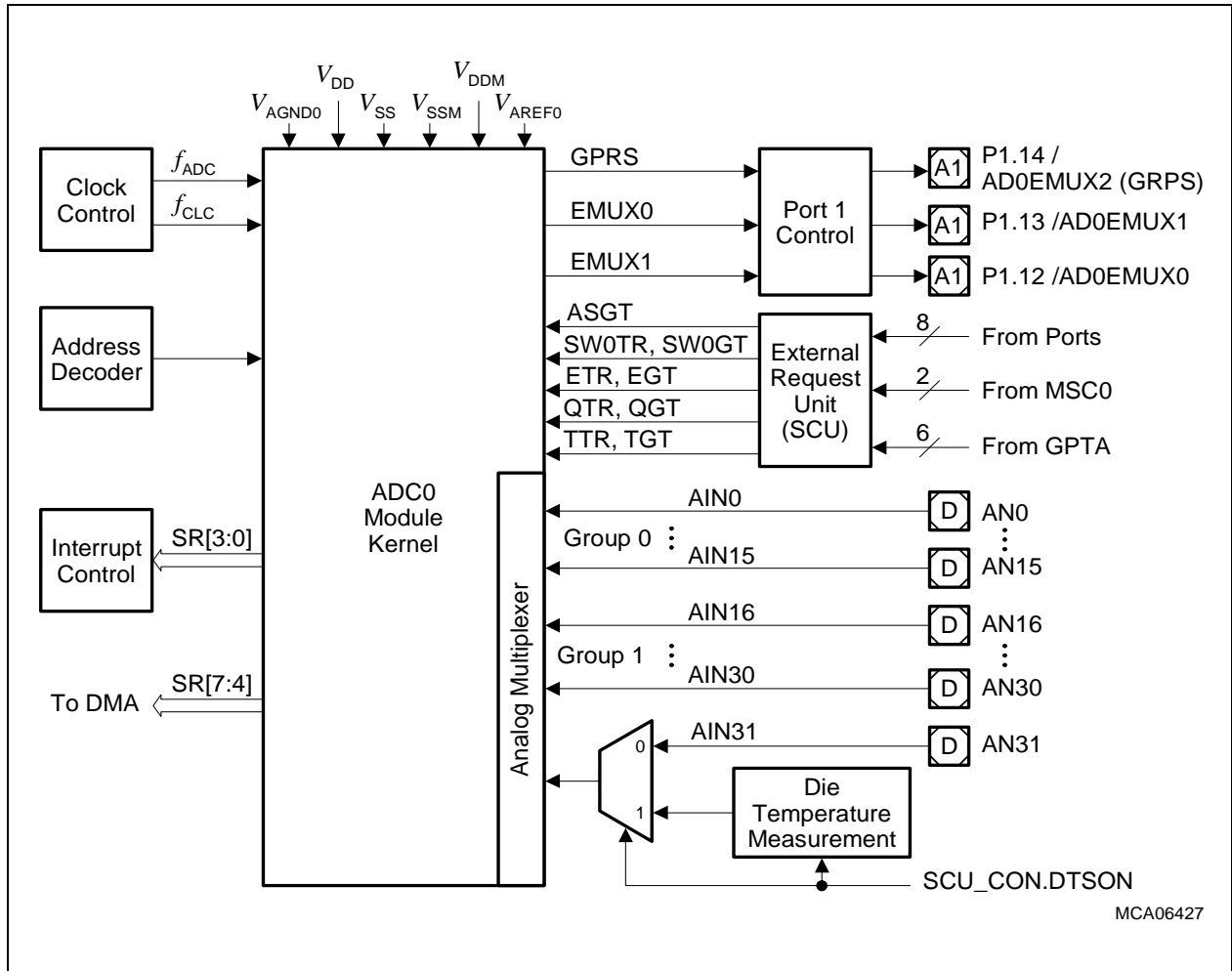


Figure 3-10 Block Diagram of the ADC Module

The ADC module has 16 analog input channels. An analog multiplexer selects the input line for the analog input channels from among 32 analog inputs. Additionally, an external analog multiplexer can be used for analog input extension. External Clock control, address decoding, and service request (interrupt) control are managed outside the ADC module kernel. External trigger conditions are controlled by an External Request Unit. This unit generates the control signals for auto-scan control (ASGT), software trigger control (SW0TR, SW0GT), the event trigger control (ETR, EGT), queue control (QTR, QGT), and timer trigger control (TTR, TGT).

An automatic self-calibration adjusts the ADC module to changing temperatures or process variations. **Figure 3-10** shows the global view of the ADC module with its functional blocks and interfaces.

Advance Information**Functional Description****Features**

- 8-bit, 10-bit, 12-bit A/D conversion
- Conversion time below 2.5 μ s @ 10-bit resolution
- Extended channel status information on request source
- Successive approximation conversion method
- Total Unadjusted Error (TUE) of ± 2 LSB @ 10-bit resolution
- Integrated sample & hold functionality
- Direct control of up to 16(32) analog input channels per ADC
- Dedicated control and status registers for each analog channel
- Powerful conversion request sources
- Selectable reference voltages for each channel
- Programmable sample and conversion timing schemes
- Limit checking
- Flexible ADC module service request control unit
- Automatic control of external analog multiplexers
- Equidistant samples initiated by timer
- External trigger and gating inputs for conversion requests
- Power reduction and clock control feature
- On-chip die temperature sensor output voltage measurement

3.14 Fast Analog-to-Digital Converter Unit (FADC)

The on-chip FADC module of the TC1161/TC1162 basically is a 2-channel A/D converter with 10-bit resolution that operates by the method of the successive approximation.

As shown in [Figure 3-11](#), the main FADC functional blocks are:

- The Input Stage — contains the differential inputs and the programmable amplifier
- The A/D Converter — is responsible for the analog-to-digital conversion
- The Data Reduction Unit — contains programmable antialiasing and data reduction filters
- The Channel Trigger Control block — determines the trigger and gating conditions for the two FADC channels
- The Channel Timers — can independently trigger the conversion of each FADC channel
- The A/D Control block is responsible for the overall FADC functionality

The FADC module is supplied by the following power supply and reference voltage lines:

- V_{DDMF}/V_{DDMF} : FADC Analog Part Power Supply (3.3 V)
- V_{DDAF}/V_{DDAF} : FADC Analog Part Logic Power Supply (1.5 V)
- V_{FAREF}/V_{FAGND} : FADC Reference Voltage (3.3 V)/FADC Reference Ground

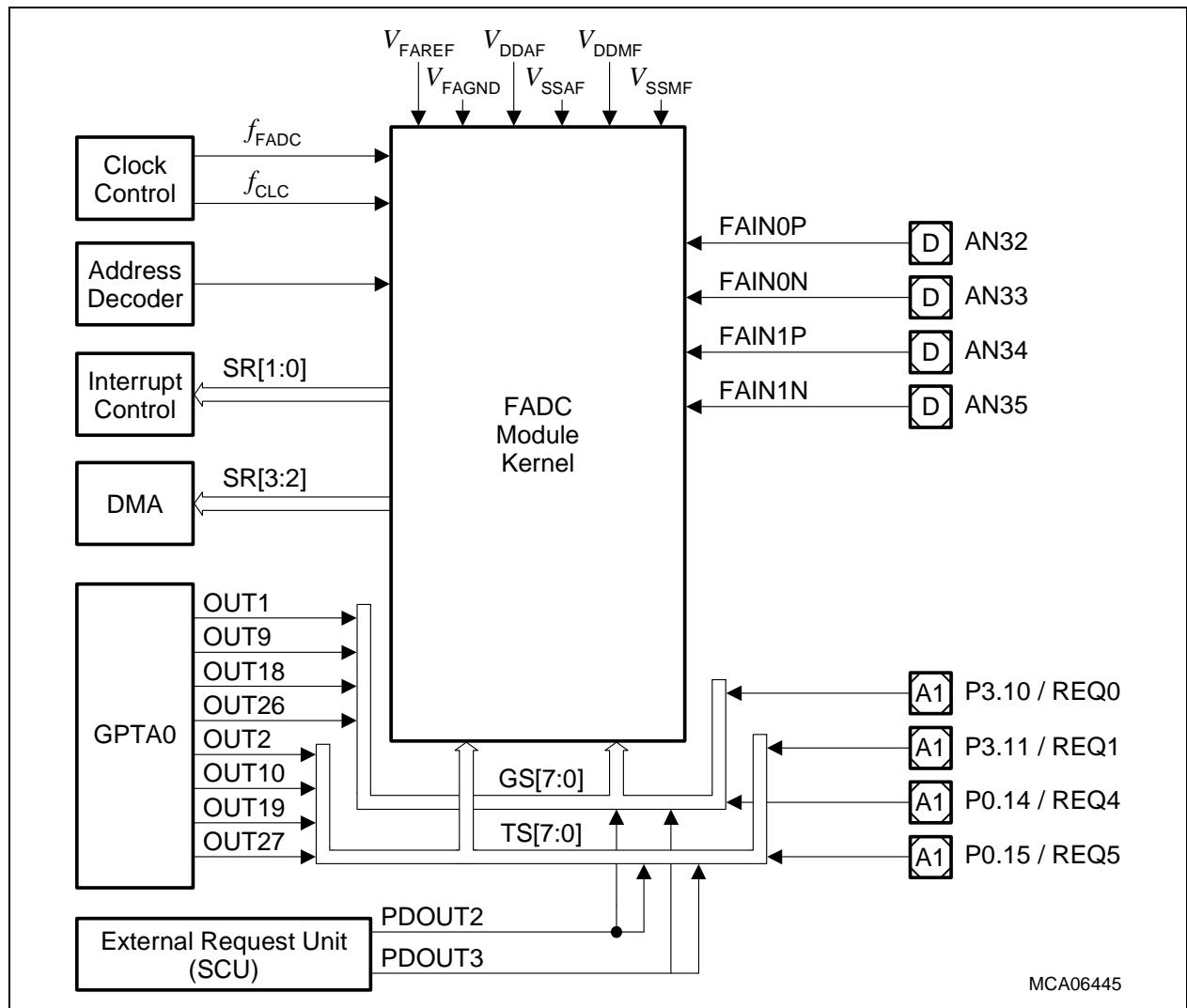


Figure 3-11 Block Diagram of the FADC Module

Features

- Extreme fast conversion, 21 cycles of f_{FADC} clock (318.2 ns @ $f_{FADC} = 66$ MHz)
- 10-bit A/D conversion
 - Higher resolution by averaging of consecutive conversions is supported
- Successive approximation conversion method
- Two differential input channels
- Offset and gain calibration support for each channel
- Differential input amplifier with programmable gain of 1, 2, 4 and 8 for each channel
- Free-running (Channel Timers) or triggered conversion modes
- Trigger and gating control for external signals
- Built-in Channel Timers for internal triggering
- Channel timer request periods independently selectable for each channel
- Selectable, programmable anti-aliasing and data reduction filter block

3.15 System Timer

The TC1161/TC1162's STM is designed for global system timing applications requiring both high precision and long period.

Features

- Free-running 56-bit counter
- All 56 bits can be read synchronously
- Different 32-bit portions of the 56-bit counter can be read synchronously
- Flexible interrupt generation based on compare match with partial STM content
- Driven by maximum 66 MHz ($= f_{\text{SYS}}$, default after reset $= f_{\text{SYS}}/2$)
- Counting starts automatically after a reset operation
- STM is reset by:
 - Watchdog reset
 - Software reset (RST_REQ.RRSTM must be set)
 - Power-on reset
- STM (and clock divider STM_CLC.RMC) is not reset at a hardware reset ($\overline{\text{HDRST}} = 0$)
- STM can be halted in debug/suspend mode (via STM_CLC register)

The STM is an upward counter, running either at the system clock frequency f_{SYS} or at a fraction of it. The STM clock frequency is $f_{\text{STM}} = f_{\text{SYS}}/\text{RMC}$ with $\text{RMC} = 0-7$ (default after reset is $f_{\text{STM}} = f_{\text{SYS}}/2$, selected by $\text{RMC} = 010_{\text{B}}$). RMC is a bit field in register STM_CLC. In case of a power-on reset, a watchdog reset, or a software reset, the STM is reset. After one of these reset conditions, the STM is enabled and immediately starts counting up. It is not possible to affect the content of the timer during normal operation of the TC1161/TC1162. The timer registers can only be read but not written to.

The STM can be optionally disabled for power-saving purposes, or suspended for debugging purposes via its clock control register. In suspend mode of the TC1161/TC1162 (initiated by writing an appropriate value to STM_CLC register), the STM clock is stopped but all registers are still readable.

Due to the 56-bit width of the STM, it is not possible to read its entire content with one instruction. It needs to be read with two load instructions. Since the timer would continue to count between the two load operations, there is a chance that the two values read are not consistent (due to possible overflow from the low part of the timer to the high part between the two read operations). To enable a synchronous and consistent reading operation of the STM content, a capture register (STM_CAP) is implemented. It latches the content of the high part of the STM each time when one of the registers STM_TIM0 to STM_TIM5 is read. Thus, STM_CAP holds the upper value of the timer at exactly the same time when the lower part is read. The second read operation would then read the content of the STM_CAP to get the complete timer value.

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The STM can also be read in sections from seven registers, STM_TIM0 through STM_TIM6, that select increasingly higher-order 32-bit ranges of the STM. These can be viewed as individual 32-bit timers, each with a different resolution and timing range.

The content of the 56-bit System Timer can be compared with the content of two compare values stored in the STM_CMP0 and STM_CMP1 registers. Interrupts can be generated on a compare match of the STM with the STM_CMP0 or STM_CMP1 registers.

The maximum clock period is $2^{56} \times f_{\text{STM}}$. At $f_{\text{STM}} = 66 \text{ MHz}$, for example, the STM counts 34.60 years before overflowing. Thus, it is capable of timing the entire expected product life-time of a system without overflowing continuously.

Figure 3-12 shows an overview on the System Timer with the options for reading parts of the STM contents.

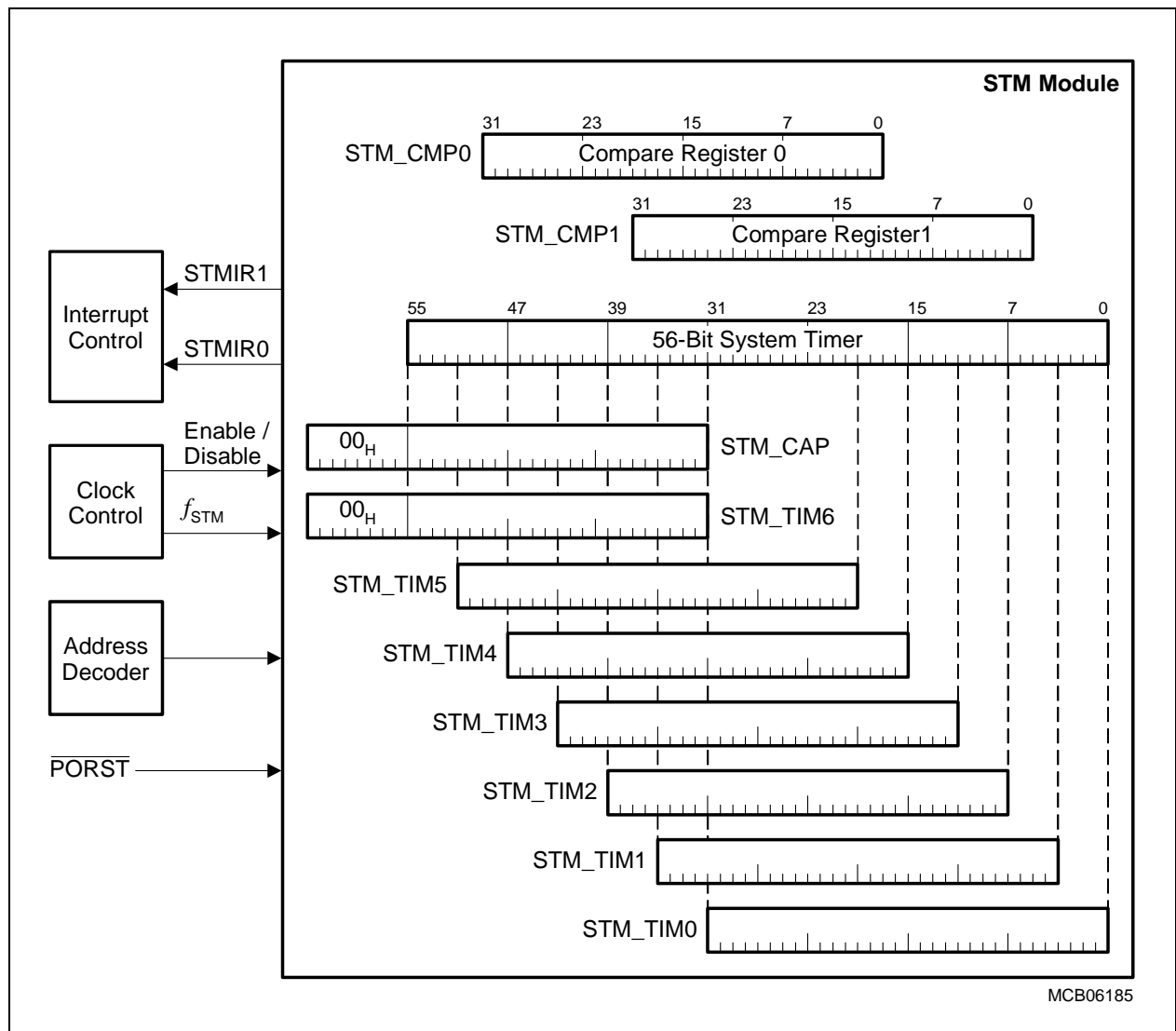


Figure 3-12 General Block Diagram of the STM Module Registers

Advance Information**Functional Description****3.16 Watchdog Timer**

The WDT provides a highly reliable and secure way to detect and recover from software or hardware failure. The WDT helps to abort an accidental malfunction of the TC1161/TC1162 in a user-specified time period. When enabled, the WDT will cause the TC1161/TC1162 system to be reset if the WDT is not serviced within a user-programmable time period. The CPU must service the WDT within this time interval to prevent the WDT from causing a TC1161/TC1162 system reset. Hence, routine service of the WDT confirms that the system is functioning as expected.

In addition to this standard "Watchdog" function, the WDT incorporates the End-of-Initialization (Endinit) feature and monitors its modifications. A system-wide line is connected to the WDT_CON0.ENDINIT bit, serving as an additional write-protection for critical registers (besides Supervisor Mode protection). Registers protected via this line can only be modified when Supervisor Mode is active and bit ENDINIT = 0.

A further enhancement in the TC1161/TC1162's WDT is its reset prewarning operation. Instead of resetting the device upon the detection of an error immediately (the way that standard Watchdogs do), the WDT first issues a Non-Maskable Interrupt (NMI) to the CPU before resetting the device at a specified time period later. This step gives the CPU a chance to save the system state to the memory for later investigation of the cause of the malfunction; an important aid in debugging.

Features

- 16-bit Watchdog counter
- Selectable input frequency: $f_{\text{SYS}}/256$ or $f_{\text{SYS}}/16384$
- 16-bit user-definable reload value for normal Watchdog operation, fixed reload value for Time-Out and Prewarning Modes
- Incorporation of the ENDINIT bit and monitoring of its modifications
- Sophisticated Password Access mechanism with fixed and user-definable password fields
- Proper access always requires two write accesses. The time between the two accesses is monitored by the WDT and is limited.
- Access Error Detection: Invalid password (during first access) or invalid guard bits (during second access) trigger the Watchdog reset generation
- Overflow Error Detection: An overflow of the counter triggers the Watchdog reset generation.
- Watchdog function can be disabled; access protection and ENDINIT monitor function remain enabled.
- Double Reset Detection: If a Watchdog induced reset occurs twice without a proper access to its control register in between, a severe system malfunction is assumed and the TC1161/TC1162 is held in reset until a power-on or hardware reset occurs. This prevents the device from being periodically reset if, for instance, connection to

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the external memory has been lost such that system initialization could not even be performed.

- Important debugging support is provided through the reset prewarning operation by first issuing an NMI to the CPU before finally resetting the device after a certain period of time.

3.17 System Control Unit

The System Control Unit (SCU) of the TC1161/TC1162 handles several system control tasks. The system control tasks of the SCU are:

- Clock system selection and control
- Reset and boot operation control
- Power management control
- Configuration input sampling
- External Request Unit
- System clock output control
- On-chip SRAM parity control
- Pad driver temperature compensation control
- Emergency stop input control for GPTA outputs
- GPTA input IN1 control
- Pad test mode control for dedicated pins
- ODCS level 2 trace control
- NMI control
- Miscellaneous SCU control

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3.18 Boot Options

The TC1161/TC1162 booting schemes provide a number of different boot options for the start of code execution. [Table 3-6](#) shows the boot options available in the TC1161/TC1162.

Table 3-6 TC1161/TC1162 Boot Selections

BRKIN	HWCFG [3:0]	TESTMODE	Type of Boot	BootROM Exit Jump Address
Normal Boot Options				
1	0000 _B	1	Enter bootstrap loader mode 1: Serial ASC0 boot via ASC0 pins	D400 0000 _H
	0001 _B ¹⁾		Enter bootstrap loader mode 2: Serial CAN boot via P3.12 and P3.13 pins	
	0010 _B		Start from internal PFLASH	A000 0000 _H
	0011 _B		Alternate boot mode (ABM): Start from internal PFLASH after CRC check is correctly executed; enter a serial bootstrap loader mode ²⁾ if CRC check fails	Defined in ABM header or D400 0000 _H
	1111 _B		Enter bootstrap loader mode 3: Serial ASC0 boot via P3.12 and P3.13 pins	D400 0000 _H
	others		Reserved; execute stop loop	—
Debug Boot Options				
0	0000 _B	1	Tri-state chip	—
	others	irrel.	Reserved; execute stop loop	—

1) This option is not applicable to TC1161.

2) The type of the alternate bootstrap loader mode is selected by the value of the SCU_SCLIR.SWOPT[2:0] bit field, which contains the levels of the P0.[2:0] latched in with the rising edge of the HDRST.

3.19 Power Management System

The TC1161/TC1162 power management system allows software to configure the various processing units so that they automatically adjust to draw the minimum necessary power for the application. There are three power management modes:

- Run Mode
- Idle Mode
- Sleep Mode

The operation of each system component in each of these states can be configured by software. The power-management modes provide flexible reduction of power consumption through a combination of techniques, including stopping the CPU clock, stopping the clocks of other system components individually, and individually clock-speed reduction of some peripheral components.

Besides these explicit software-controlled power-saving modes, special attention has been paid to automatic power-saving in those operating units which are not required at a certain point of time, or idle in the TC1161/TC1162. In that case, they are shut off automatically until their operation is required again.

Table 3-7 describes the features of the power management modes.

Table 3-7 Power Management Mode Summary

Mode	Description
Run	The system is fully operational. All clocks and peripherals are enabled, as determined by software.
Idle	The CPU clock is disabled, waiting for a condition to return it to Run Mode. Idle Mode can be entered by software when the processor has no active tasks to perform. All peripherals remain powered and clocked. Processor memory is accessible to peripherals. A reset, Watchdog Timer event, a falling edge on the NMI pin, or any enabled interrupt event will return the system to Run Mode.
Sleep	The system clock signal is distributed only to those peripherals programmed to operate in Sleep Mode. The other peripheral module will be shut down by the suspend signal. Interrupts from operating peripherals, the Watchdog Timer, a falling edge on the NMI pin, or a reset event will return the system to Run Mode. Entering this state requires an orderly shut-down controlled by the Power Management State Machine.

In typical operation, Idle Mode and Sleep Mode may be entered and exited frequently during the run time of an application. For example, system software will typically cause the CPU to enter Idle Mode each time it has to wait for an interrupt before continuing its tasks. In Sleep Mode and Idle Mode, wake-up is performed automatically when any

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enabled interrupt signal is detected, or when the count value (WDT_SR.WDTTIM) changes from 7FFF_H to 8000_H.

3.20 On-Chip Debug Support

Figure 3-13 shows a block diagram of the TC1161/TC1162 OCDS system.

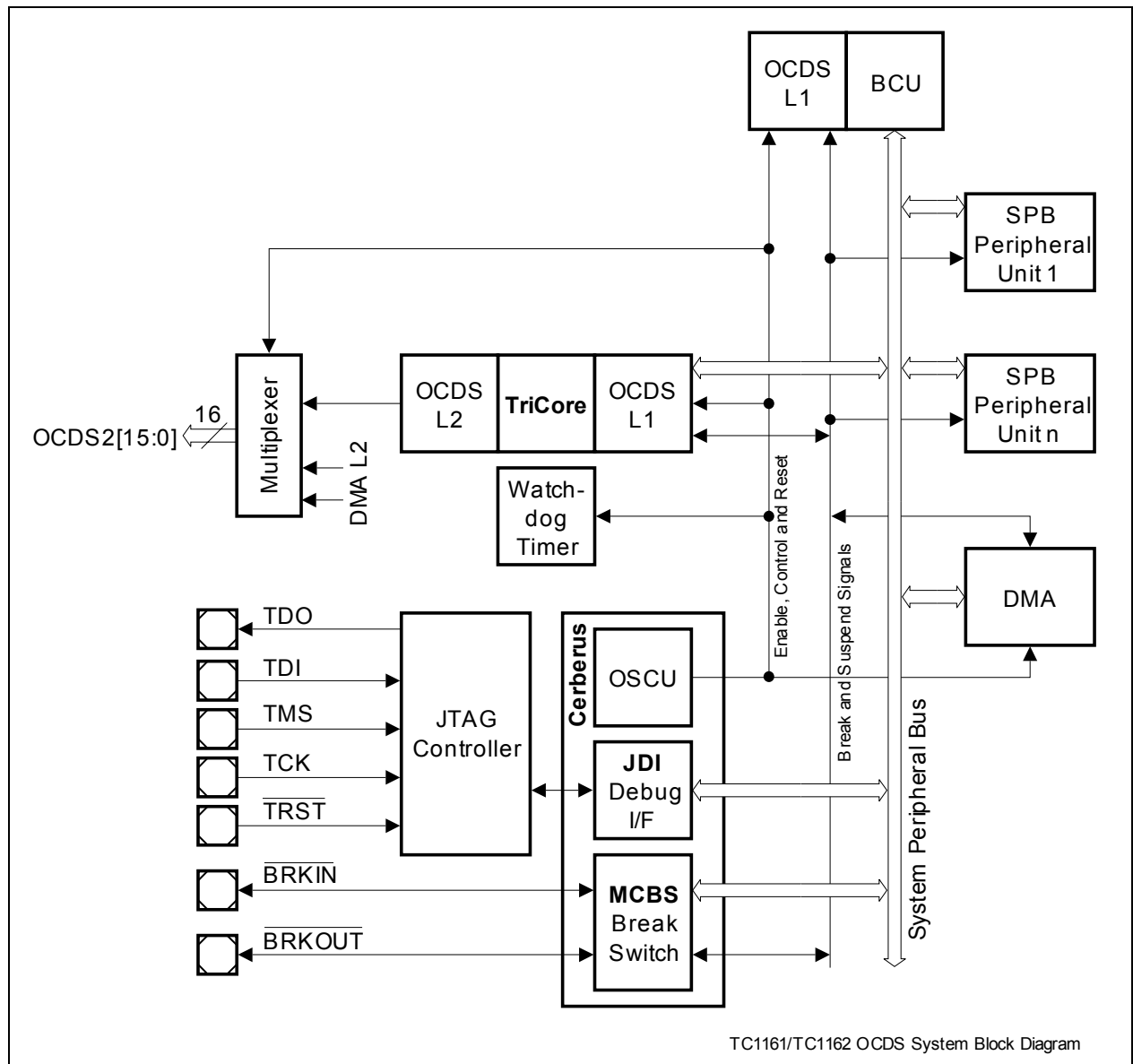


Figure 3-13 OCDS System Block Diagram

The TC1161/TC1162 basically supports three levels of debug operation:

- OCDS Level 1 debug support
- OCDS Level 2 debug support

Advance Information**Functional Description****OCDS Level 1 Debug Support**

The OCDS Level 1 debug support is mainly assigned for real-time software debugging purposes which have a demand for low-cost standard debugger hardware.

The OCDS Level 1 is based on a JTAG interface that is used by the external debug hardware to communicate with the system. The on-chip Cerberus module controls the interactions between the JTAG interface and the on-chip modules. The external debug hardware may become master of the internal buses, and read or write the on-chip register/memory resources. The Cerberus also makes it possible to define breakpoint and trigger conditions as well as to control user program execution (run/stop, break, single-step).

OCDS Level 2 Debug Support

The OCDS Level 2 debug support makes it possible to implement program tracing capabilities for enhanced debuggers by extending the OCDS Level 1 debug functionality with an additional 16-bit wide trace output port with trace clock. With the trace extension, the following four trace capabilities are provided (only one of the three trace capabilities can be selected at a time):

- Trace of the CPU program flow
- Trace of the DMA Controller transaction requests
- Trace of the DMA Controller Move Engine status information

3.21 Clock Generation and PLL

The TC1161/TC1162 clock system performs the following functions:

- Acquires and buffers incoming clock signals to create a master clock frequency
- Distributes in-phase synchronized clock signals throughout the TC1161/TC1162's entire clock tree
- Divides a system master clock frequency into lower frequencies required by the different modules for operation.
- Dynamically reduces power consumption during operation of functional units
- Statically reduces power consumption through programmable power-saving modes
- Reduces electromagnetic interference (EMI) by switching off unused modules

The clock system must be operational before the TC1161/TC1162 can function, so it contains special logic to handle power-up and reset operations. Its services are fundamental to the operation of the entire system, so it contains special fail-safe logic.

Features

- PLL operation for multiplying clock source by different factors
- Direct drive capability for direct clocking
- Comfortable state machine for secure switching between basic PLL, direct or prescaler operation
- Sleep and Power-Down Mode support

The TC1161/TC1162 Clock Generation Unit (CGU) as shown in [Figure 3-14](#) allows a very flexible clock generation. It basically consists of an main oscillator circuit and a Phase- Locked Loop (PLL). The PLL can convert a low-frequency external clock signal from the oscillator circuit to a high-speed internal clock for maximum performance.

The system clock f_{SYS} is generated from an oscillator clock f_{OSC} in either one of the four hardware/software selectable ways:

- **Direct Drive Mode (PLL Bypass):**
In Direct Drive Mode, the TC1161/TC1162 clock system is directly driven by an external clock signal. input, i.e. $f_{\text{CPU}} = f_{\text{OSC}}$ and $f_{\text{SYS}} = f_{\text{OSC}}$. This allows operation of the TC1161/TC1162 with a reasonably small fundamental mode crystal.
- **VCO Bypass Mode (Prescaler Mode):**
In VCO Bypass Mode, f_{CPU} and f_{SYS} are derived from f_{OSC} by the two divider stages, P-Divider and K-Divider. The system clock f_{SYS} is equal to f_{CPU} .
- **PLL Mode:**
In PLL Mode, the PLL is running. The VCO clock f_{VCO} is derived from f_{OSC} , divided by the P factor, multiplied by the PLL (N-Divider). The clock signals f_{CPU} and f_{SYS} are derived from f_{VCO} by the K-Divider. The system clock f_{SYS} is equal to f_{CPU} .
- **PLL Base Mode:**
In PLL Base Mode, the PLL is running at its VCO base frequency and f_{CPU} and f_{SYS}

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are derived from f_{VCO} only by the K-Divider. In this mode, the system clock f_{SYS} is equal to f_{CPU} .

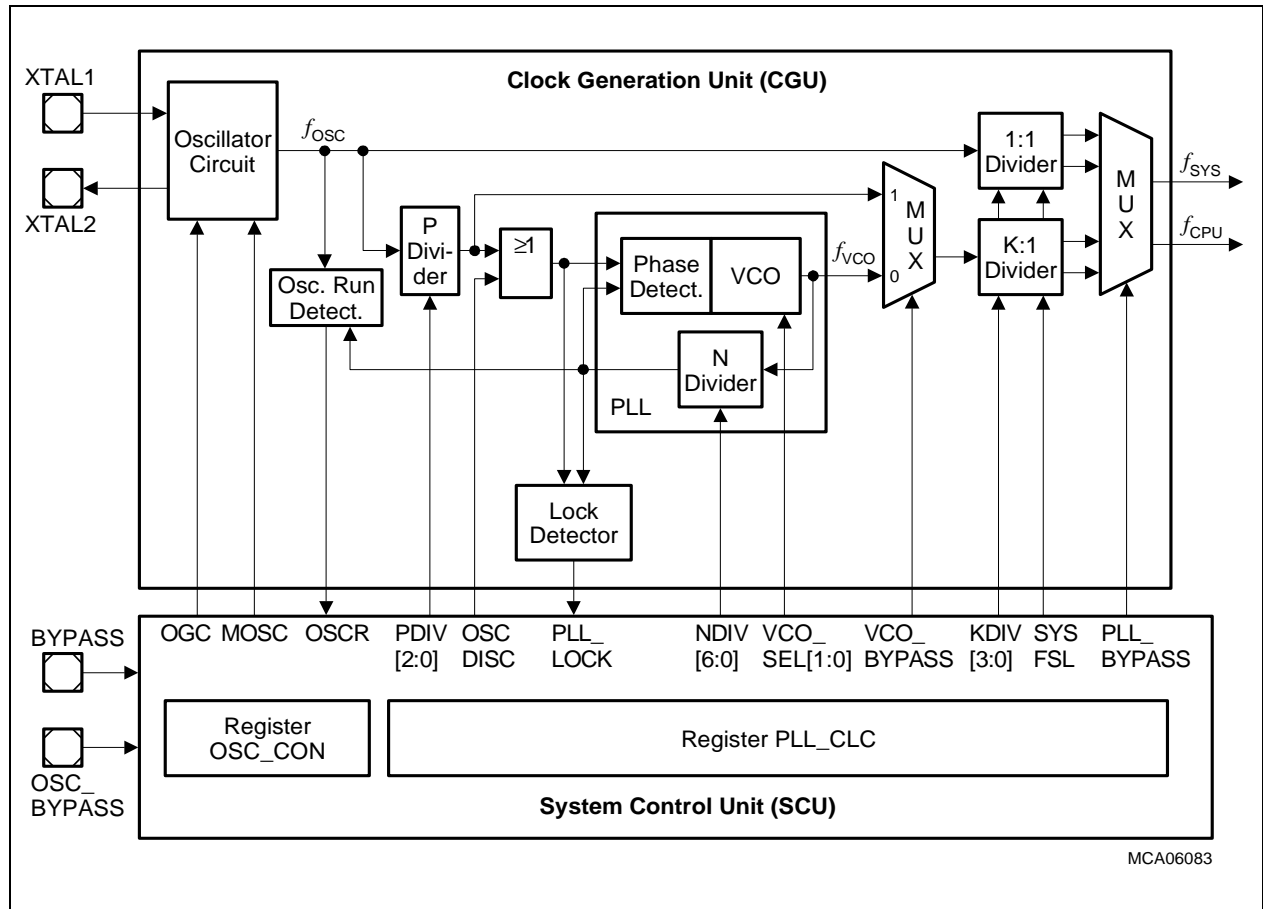


Figure 3-14 Clock Generation Unit

Recommended Oscillator Circuits

The oscillator circuit, a Pierce oscillator, is designed to work with both, an external crystal oscillator or an external stable clock source. It basically consists of an inverting amplifier and a feedback element with XTAL1 as input, and XTAL2 as output.

When using a crystal, a proper external oscillator circuitry must be connected to both pins, XTAL1 and XTAL2. The crystal frequency can be within the range of 4 MHz to 25 MHz. Additionally, it is necessary to have two load capacitances C_{X1} and C_{X2} , and depending on the crystal type, a series resistor R_{X2} , to limit the current. A test resistor R_Q may be temporarily inserted to measure the oscillation allowance (negative resistance) of the oscillator circuitry. R_Q values are typically specified by the crystal vendor. The C_{X1} and C_{X2} values shown in [Figure 3-15](#) can be used as starting points for the negative resistance evaluation and for non-productive systems. The exact values and related operating range are dependent on the crystal frequency and have to be determined and optimized together with the crystal vendor using the negative resistance method.

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Oscillation measurement with the final target system is strongly recommended to verify the input amplitude at XTAL1 and to determine the actual oscillation allowance (margin negative resistance) for the oscillator-crystal system.

When using an external clock signal, the signal must be connected to XTAL1. XTAL2 is left open (unconnected). The external clock frequency can be in the range of 0 - 40 MHz if the PLL is bypassed, and 4 - 40 MHz if the PLL is used.

The oscillator can also be used in combination with a ceramic resonator. The final circuitry must also be verified by the resonator vendor.

Figure 3-15 shows the recommended external oscillator circuitries for both operating modes, external crystal mode and external input clock mode. A block capacitor is recommended to be placed between V_{DDOSC}/V_{DDOSC3} and V_{SSOSC} .

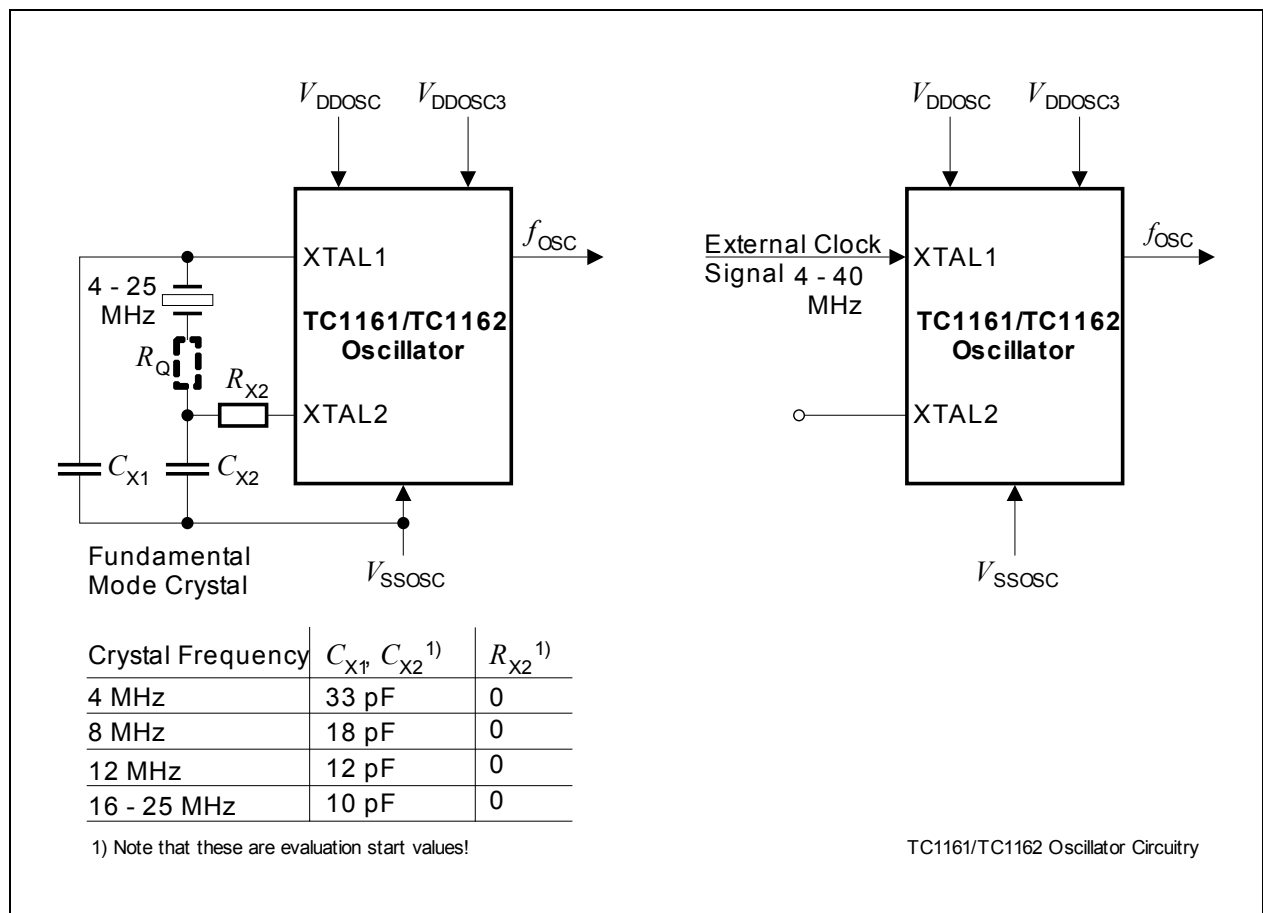


Figure 3-15 Oscillator Circuitries

Note: For crystal operation, it is strongly recommended to measure the negative resistance in the final target system (layout) to determine the optimum parameters for the oscillator operation. Please refer to the minimum and maximum values of the negative resistance specified by the crystal supplier.

3.22 Power Supply

The TC1161/TC1162 has several power supply lines for different voltage classes:

- 1.5 V: Core logic, oscillator and A/D converter supply
- 3.3 V: I/O ports, Flash memories, oscillator, and A/D converter supply with reference voltages

Figure 3-16 shows the power supply concept of the TC1161/TC1162 with the power supply pins and its connections to the functional units.

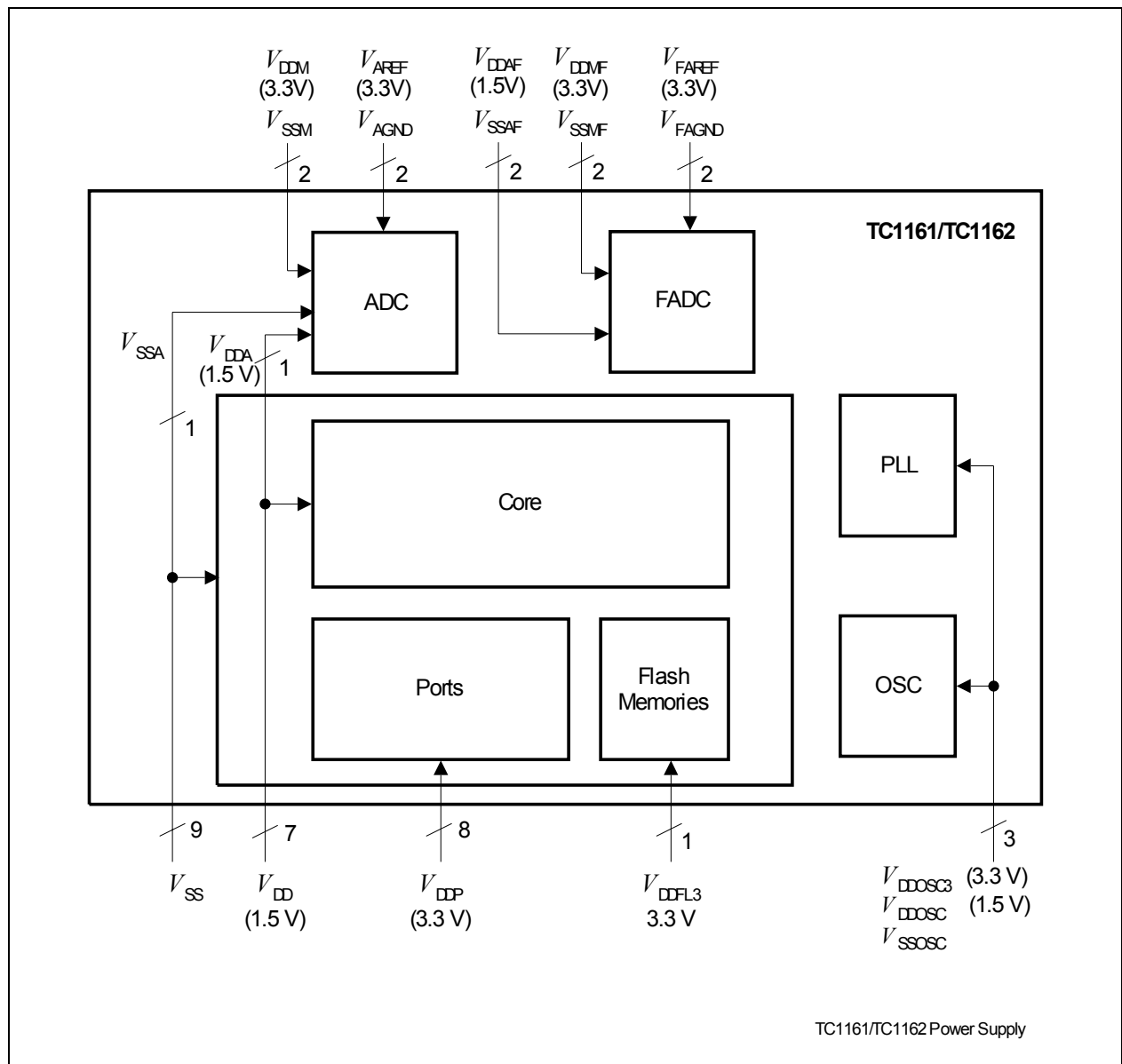


Figure 3-16 Power Supply Concept of TC1161/TC1162

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3.23 Identification Register Values

Table 3-8 shows the address map and reset values of the TC1161/TC1162 Identification Registers.

Table 3-8 TC1161/TC1162 Identification Registers

Short Name	Address	Reset Value
SCU_ID	F000 0008 _H	002C C002 _H
MANID	F000 0070 _H	0000 1820 _H
CHIPID	F000 0074 _H	0000 8B02 _H
RTID	F000 0078 _H	0000 0000 _H
SBCU_ID	F000 0108 _H	0000 6A0A _H
STM_ID	F000 0208 _H	0000 C006 _H
CBS_JDPID	F000 0408 _H	0000 6307 _H
MSC0_ID	F000 0808 _H	0028 C001 _H
ASC0_ID	F000 0A08 _H	0000 4402 _H
ASC1_ID	F000 0B08 _H	0000 4402 _H
GPTA0_ID	F000 1808 _H	0029 C004 _H
DMA_ID	F000 3C08 _H	001A C012 _H
CAN_ID ¹⁾	F000 4008 _H	002B C012 _H
SSC0_ID	F010 0108 _H	0000 4510 _H
FADC_ID	F010 0308 _H	0027 C012 _H
ADC0_ID	F010 0408 _H	0030 C001 _H
MLIO_ID	F010 C008 _H	0025 C006 _H
MCHK_ID	F010 C208 _H	001B C001 _H
CPS_ID	F7E0 FF08 _H	0015 C006 _H
CPU_ID	F7E1 FE18 _H	000A C005 _H
PMU_ID	F800 0508 _H	002E C012 _H
FLASH_ID	F800 2008 _H	0041 C002 _H
DMI_ID	F87F FC08 _H	0008 C004 _H
PMI_ID	F87F FD08 _H	000B C004 _H
LBCU_ID	F87F FE08 _H	000F C005 _H
LFI_ID	F87F FF08 _H	000C C005 _H

1) The address and reset value of CAN_ID is not applicable to TC1161.

4 Electrical Parameters

Chapter 4 provides the characteristics of the electrical parameters which are implementation-specific for the TC1161/TC1162.

4.1 General Parameters

The general parameters are described here to aid the users in interpreting the parameters mainly in **Section 4.2** and **Section 4.3**. The absolute maximum ratings and its operating conditions are provided for the appropriate setting in the TC1161/TC1162.

4.1.1 Parameter Interpretation

The parameters listed in this section partly represent the characteristics of the TC1161/TC1162 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are marked with an two-letter abbreviation in column "Symbol":

- **CC**
Such parameters indicate **C**ontroller **C**haracteristics which are a distinctive feature of the TC1161/TC1162 and must be regarded for a system design.
- **SR**
Such parameters indicate **S**ystem **R**equirements which must provided by the microcontroller system in which the TC1161/TC1162 designed in.

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4.1.2 Pad Driver and Pad Classes Summary

This section gives an overview on the different pad driver classes and its basic characteristics. More details (mainly DC parameters) are defined in [Section 4.2.1](#).

Table 4-1 Pad Driver and Pad Classes Overview

Class	Power Supply	Type	Sub Class	Speed Grade	Load	Leakage ¹⁾	Termination
A	3.3V	LVTTL I/O, LVTTL outputs	A1 (e.g. GPIO)	6 MHz	100 pF	500 nA	No
			A2 (e.g. serial I/Os)	40 MHz	50 pF	6 μ A	Series termination recommended
			A3 (e.g. BRKIN, BRKOUT)	66 MHz/	50 pF	6 μ A	Series termination recommended (for $f > 25$ MHz)
			A4 (e.g. Trace Clock)	66 MHz	25 pF	6 μ A	Series termination recommended
C	3.3V	LVDS	–	50 MHz		–	Parallel termination ²⁾ , $100\Omega \pm 10\%$
D	–	Analog inputs, reference voltage inputs					

1) Values are for $T_{Jmax} = 125$ °C.

2) In applications where the LVDS pins are not used (disabled), these pins must be either left unconnected, or properly terminated with the differential parallel termination of $100\Omega \pm 10\%$.

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4.1.3 Absolute Maximum Ratings

Table 4-2 shows the absolute maximum ratings of the TC1161/TC1162 parameters.

Table 4-2 Absolute Maximum Rating Parameters

Parameter	Symbol		Limit Values		Unit	Notes
			Min.	Max.		
Ambient temperature	T_A	SR	-40	85	°C	Under bias
Storage temperature	T_{ST}	SR	-65	150	°C	–
Junction temperature	T_J	SR	-40	125	°C	Under bias
Voltage at 1.5 V power supply pins with respect to $V_{SS}^{1)}$	V_{DD}	SR	–	2.25	V	–
Voltage at 3.3 V power supply pins with respect to $V_{SS}^{2)}$	V_{DDP}	SR	–	3.75	V	–
Voltage on any Class A input pin and dedicated input pins with respect to V_{SS}	V_{IN}	SR	-0.5	$V_{DDP} + 0.5$ or max. 3.7	V	Whatever is lower
Voltage on any Class D analog input pin with respect to V_{AGND}	V_{AIN}, V_{AREFx}	SR	-0.5	$V_{DDM} + 0.5$ or max. 3.7	V	Whatever is lower
Voltage on any Class D analog input pin with respect to V_{SSAF}	V_{AINF}, V_{FAREF}	SR	-0.5	$V_{DDMF} + 0.5$ or max. 3.7	V	Whatever is lower
CPU & LMB Bus Frequency	f_{CPU}	SR	–	66 ³⁾	MHz	–
FPI Bus Frequency	f_{SYS}	SR	–	66 ³⁾	MHz	⁴⁾

1) Applicable for V_{DD} , V_{DDOSC} , V_{DDPLL} , and V_{DDAF} .

2) Applicable for V_{DDP} , V_{DDFL3} , V_{DDM} , and V_{DDMF} .

3) The PLL jitter characteristics add to this value according to the application settings. See the PLL jitter parameters.

4) The ratio between f_{CPU} and f_{SYS} is fixed at 1:1.

Note: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

During absolute maximum rating overload conditions ($V_{IN} > \text{related } V_{DD}$ or $V_{IN} < V_{SS}$) the voltage on the related V_{DD} pins with respect to ground (V_{SS}) must not exceed the values defined by the absolute maximum ratings.

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4.1.4 Operating Conditions

The following operating conditions must not be exceeded in order to ensure correct operation of the TC1161/TC1162. All parameters specified in the following table refer to these operating conditions, unless otherwise noted.

Table 4-3 Operating Condition Parameters

Parameter	Symbol	SR	Limit Values		Unit	Notes Conditions
			Min.	Max.		
Digital supply voltage ¹⁾	V_{DD}	SR	1.42	1.58 ²⁾	V	–
	V_{DDOSC}					
	V_{DDP} V_{DDOSC3}	SR	3.13	3.47 ³⁾	V	For Class A pins (3.3V ± 5%)
	V_{DDFL3}	SR	3.13	3.47 ³⁾	V	–
Digital ground voltage	V_{SS}	SR	0		V	–
Ambient temperature under bias	T_A	SR	-40	+85	°C	–
Analog supply voltages	–		–	–	–	See separate specification Page 4-91 , Page 4-98
CPU clock	f_{CPU}	SR	– ⁴⁾	66 ⁵⁾	MHz	–
Short circuit current	I_{SC}	SR	-5	+5	mA	⁶⁾
Absolute sum of short circuit currents of a pin group (see Table 4-4)	$\Sigma I_{SC} $	SR	–	20	mA	See note ⁷⁾
Absolute sum of short circuit currents of the device	$\Sigma I_{SC} $	SR	–	100	mA	See note ⁷⁾
Inactive device pin current ($V_{DD} = V_{DDP} = 0$)	I_{ID}	SR	-1	1	mA	–
External load capacitance	C_L	SR	–	See DC characteristics	pF	Depending on pin class

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- 1) Digital supply voltages applied to the TC1161/TC1162 must be static regulated voltages which allow a typical voltage swing of $\pm 5\%$.
- 2) Voltage overshoot up to 1.7 V is permissible at Power-Up and $\overline{\text{PORST}}$ low, provided the pulse duration is less than 100 μs and the cumulated summary of the pulses does not exceed 1 h.
- 3) Voltage overshoot to 4 V is permissible at Power-Up and $\overline{\text{PORST}}$ low, provided the pulse duration is less than 100 μs and the cumulated summary of the pulses does not exceed 1 h.
- 4) The TC1161/TC1162 uses a static design, so the minimum operation frequency is 0 MHz. Due to test time restriction no lower frequency boundary is tested, however.
- 5) The PLL jitter characteristics add to this value according to the application settings. See the PLL jitter parameters.
- 6) Applicable for digital outputs.
- 7) See additional document "TC1796 Pin Reliability in Overload" for overload current definitions.

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Table 4-4 Pin Groups for Overload/Short-Circuit Current Sum Parameter

Group	Pins
1	TRCLK, P5.[7:0], P0.[7:6], P0.[15:14]
2	P0.[13:12], P0.[5:4], P2.[13:8], SOP0A, SON0, FCLP0A, FCLN0
3	P0.[11:8], P0.[3:0], P3.[13:11]
4	P3[10:0], P3.[15:14]
5	$\overline{\text{HDRST}}$, $\overline{\text{PORST}}$, $\overline{\text{NMI}}$, $\overline{\text{TESTMODE}}$, $\overline{\text{BRKIN}}$, $\overline{\text{BRKOUT}}$, $\overline{\text{BYPASS}}$, TCK, $\overline{\text{TRST}}$, TDO, TMS, TDI, P1.[7:4]
6	P1.[3:0], P1.[11:8], P4.[3:0]
7	P2.[7:0], P1.[14:12]
8	P5.[15:8]

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4.2 DC Parameters

The electrical characteristics of the DC Parameters are detailed in this section.

4.2.1 Input/Output Pins

Table 4-5 provides the characteristics of the input/output pins of the TC1161/TC1162.

Table 4-5 Input/Output DC-Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
General Parameters						
Pull-up current ¹⁾	I _{PUH}	CC	10	100	μA	V _{IN} < V _{IHAmin} ; class A1/A2/Input pads.
			20	200	μA	V _{IN} < V _{IHAmin} ; class A3/A4 pads.
Pull-down current ¹⁾	I _{PDL}	CC	10	150	μA	V _{IN} > V _{ILAmax} ; class A1/A2/Input pads.
			20	200	μA	V _{IN} > V _{ILAmax} ; class A3/A4 pads.
Pin capacitance ¹⁾ (Digital I/O)	C _{IO}	CC	–	10	pF	f = 1 MHz T _A = 25 °C
Input only Pads (V _{DDP} = 3.13 to 3.47 V = 3.3V ±5%)						
Input low voltage class A1/A2 pins	V _{ILA}	SR	-0.3	0.34 × V _{DDP}	V	–
Input high voltage class A1/A2 pins	V _{IHA}	SR	0.64 × V _{DDP}	V _{DDP} + 0.3 or max. 3.6	V	Whatever is lower
Ratio V _{IL} /V _{IH}		CC	0.53	–	–	–
Input low voltage class A3 pins	V _{ILA3}	SR	–	0.8	V	–
Input high voltage class A3 pins	V _{IHA3}	SR	2.0	–	V	–
Input hysteresis	HYSA	CC	0.1 × V _{DDP}	–	V	⁴⁾
Input leakage current	I _{OZI}	CC	–	±3000 ±6000	nA	((V _{DDP} /2)-1) < V _{IN}

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Table 4-5 Input/Output DC-Characteristics (cont'd)(Operating Conditions

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Class A Pads ($V_{DDP} = 3.13$ to 3.47 V = $3.3V \pm 5\%$)						
Output low voltage ³⁾	V_{OLA}	CC	–	0.4	V	$I_{OL} = 2$ mA for strong driver mode, (Not applicable to Class A1 pins) $I_{OL} = 1.8$ mA for medium driver mode, A2 pads $I_{OL} = 1.4$ mA for medium driver mode, A1 pads $I_{OL} = 370$ μ A for weak driver mode
Output high voltage ²⁾	V_{OHA}	CC	2.4	–	V	$I_{OH} = -2$ mA for strong driver mode, (Not applicable to Class A1 pins) $I_{OH} = -1.8$ mA for medium driver mode, A1/A2 pads $I_{OH} = -370$ μ A for weak driver mode
			$V_{DDP} - 0.4$	–	V	$I_{OH} = -1.4$ mA for strong driver mode, (Not applicable to Class A1 pins) $I_{OH} = -1$ mA for medium driver mode, A1/A2 pads $I_{OH} = -280$ μ A for weak driver mode
Input low voltage class A1/2 pins	V_{ILA}	SR	-0.3	$0.34 \times V_{DDP}$	V	–
Input high voltage class A1/2 pins	V_{IHA}	SR	$0.64 \times V_{DDP}$	$V_{DDP} + 0.3$ or 3.6	V	Whatever is lower
Ratio V_{IL}/V_{IH}		CC	0.53	–	–	–
Input hysteresis	HYSA	CC	$0.1 \times V_{DDP}$	–	V	4)

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Table 4-5 Input/Output DC-Characteristics (cont'd)(Operating Conditions

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Input leakage current Class A2/3/4 pins	I_{OZA24}	CC	–	± 3000 ± 6000	nA	$((V_{DDP}/2)-1) < V_{IN}$ $< ((V_{DDP}/2)+1)$ otherwise ²⁾
Input leakage current Class A1 pins	I_{OZA1}	CC	–	± 500	nA	$0 V < V_{IN} < V_{DDP}$

Class C Pads ($V_{DDP} = 3.13$ to $3.47 V = 3.3V \pm 5\%$)

Output low voltage	V_{OL}	CC	815		mV	Parallel termination $100 \Omega \pm 1\%$
Output high voltage	V_{OH}	CC		1545	mV	
Output differential voltage	V_{OD}	CC	150	600	mV	
Output offset voltage	V_{OS}	CC	1075	1325	mV	
Output impedance	R_0	CC	40	140		–

Class D Pads

see ADC Characteristics	–	–	–	–
-------------------------	---	---	---	---

- 1) Not subject to production test, verified by design / characterization.
- 2) Only one of these parameters is tested, the other is verified by design characterization
- 3) Max. resistance between pin and next power supply pin 25Ω for strong driver mode (verified by design characterization).
- 4) Function verified by design, value is not subject to production test - verified by design/characterization. Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It cannot be guaranteed that it suppresses switching due to external system noise.

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4.2.2 Analog to Digital Converter (ADC0)

Table 4-6 provides the characteristics of the ADC module in the TC1161/TC1162.

Table 4-6 ADC Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions / Remarks
			Min.	Typ.	Max.		
Analog supply voltage	V_{DDM}	SR	3.13	3.3	3.47 ¹⁾	V	–
	V_{DD}	SR	1.42	1.5	1.58 ²⁾	V	Power supply for ADC digital part, internal supply
Analog ground voltage	V_{SSM}	SR	-0.1	–	0.1	V	–
Analog reference voltage ¹⁶⁾	V_{AREFx}	SR	$V_{AGNDx} + 1V$	V_{DDM}	$V_{DDM} + 0.05$ ¹⁾ ³⁾	V	–
Analog reference ground ¹⁶⁾	V_{AGNDx}	SR	$V_{SSMx} - 0.05V$	0	$V_{AREF} - 1V$	V	–
Analog reference voltage range ⁴⁾¹⁶⁾	$V_{AREFx} - V_{AGNDx}$	SR	$V_{DDM}/2$		$V_{DDM} + 0.05$		
Analog input voltage range	V_{AIN}	SR	V_{AGNDx}	–	V_{AREFx}	V	–
V_{DDM} supply current	I_{DDM}	SR		2.5	4	mA rms	⁵⁾
Power-up calibration time	t_{PUC}	CC	–	–	3840	f_{ADC} CLK	–
Internal ADC clocks	f_{BC}	CC	2	–	40	MHz	$f_{BC} = f_{ANA} \times 4$
	f_{ANA}	CC	0.5	–	10	MHz	$f_{ANA} = f_{BC} / 4$
Sample time	t_S	CC	$4 \times (CHCONn.STC + 2) \times t_{BC}$			μs	–
			$8 \times t_{BC}$	–	–	μs	

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Table 4-6 ADC Characteristics (cont'd) (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions / Remarks
			Min.	Typ.	Max.		
Conversion time	t_C	CC	$t_S + 40 \times t_{BC} + 2 \times t_{DIV}$			μS	For 8-bit conversion
			$t_S + 48 \times t_{BC} + 2 \times t_{DIV}$			μS	For 10-bit conversion
			$t_S + 56 \times t_{BC} + 2 \times t_{DIV}$			μS	For 12-bit conversion
Total unadjusted error ⁴⁾	TUE ⁶⁾	CC	–	–	± 1	LSB	For 8-bit conv.
			–	–	± 2	LSB	For 10-bit conv.
			–	–	± 4	LSB	For 12-bit conv. ⁷⁾⁸⁾
			–	–	± 8	LSB	For 12-bit conv. ⁹⁾⁸⁾
DNL error ¹⁰⁾⁴⁾	TUE _{DNL}	CC	–	± 1.5	± 3.0	LSB	For 12-bit conv. ¹¹⁾⁸⁾
INL error ¹⁰⁾⁴⁾	TUE _{INL}	CC	–	± 1.5	± 3.0	LSB	For 12-bit conv. ¹¹⁾⁸⁾
Gain error ¹⁰⁾⁴⁾	TUE _{GAIN}	CC	–	± 0.5	± 3.5	LSB	For 12-bit conv. ¹¹⁾⁸⁾
Offset error ¹⁰⁾⁴⁾	TUE _{OFF}	CC	–	± 1.0	± 4.0	LSB	For 12-bit conv. ¹¹⁾⁸⁾
Input leakage current at analog inputs AN0, AN1 and AN31. see Figure 4-3 ¹²⁾	I_{OZ1} ¹³⁾	CC	–1000	–	300	nA	$(0\% V_{DDM}) < V_{IN} < (2\% V_{DDM})$
			–200		400	nA	$(2\% V_{DDM}) < V_{IN} < (95\% V_{DDM})$
			–200		1000	nA	$(95\% V_{DDM}) < V_{IN} < (98\% V_{DDM})$
			–200		3000	nA	$(98\% V_{DDM}) < V_{IN} < (100\% V_{DDM})$

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Table 4-6 ADC Characteristics (cont'd) (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions / Remarks
			Min.	Typ.	Max.		
Input leakage current at analog inputs AN2 to AN30, see Figure 4-3	$I_{OZ1}^{13)}$	CC	-1000	-	200	nA	$(0\% V_{DDM}) < V_{IN} < (2\% V_{DDM})$
			-200		300	nA	$(2\% V_{DDM}) < V_{IN} < (95\% V_{DDM})$
			-200		1000	nA	$(95\% V_{DDM}) < V_{IN} < (98\% V_{DDM})$
			-200		3000	nA	$(98\% V_{DDM}) < V_{IN} < (100\% V_{DDM})$
Input leakage current at V_{AREF}	I_{OZ2}	CC	-	-	± 1	μA	$0 V < V_{AREF} < V_{DDM}$, no conversion running
Input current at $V_{AREF}^{16)}$	I_{AREF}	CC	-	35	75	μA_{rms}	$0 V < V_{AREF} < V_{DDM}^{14)}$
Total capacitance of the voltage reference inputs ¹⁵⁾¹⁶⁾	$C_{AREFTOT}$	CC	-	-	25	pF	⁸⁾
Switched capacitance at the positive reference voltage input ¹⁶⁾	C_{AREFSW}	CC	-	15	20	pF	⁸⁾¹⁷⁾
Resistance of the reference voltage input path ¹⁵⁾	R_{AREF}	CC	-	1	1.5	k Ω	500 Ohm increased for AN[1:0] used as reference input ⁸⁾
Total capacitance of the analog inputs ¹⁵⁾	C_{AINTOT}	CC	-	-	25	pF	⁵⁾⁸⁾
Switched capacitance at the analog voltage inputs	C_{AINSW}	CC	-	-	7	pF	⁸⁾¹⁸⁾

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Table 4-6 ADC Characteristics (cont'd) (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions / Remarks
			Min.	Typ.	Max.		
ON resistance of the transmission gates in the analog voltage path	R_{AIN}	CC	–	1	1.5	k Ω	8)
ON resistance for the ADC test (pull-down for AIN7)	R_{AIN7T}	CC	200	300	1000	Ω	Test feature available only for AIN7 8)
Current through resistance for the ADC test (pull-down for AIN7)	I_{AIN7T}	CC	–	15 rms	30 peak	mA	Test feature available only for AIN7 8)

- 1) Voltage overshoot to 4 V are permissible, provided the pulse duration is less than 100 μ s and the cumulated summary of the pulses does not exceed 1 h.
- 2) Voltage overshoot to 1.7 V are permissible, provided the pulse duration is less than 100 μ s and the cumulated summary of the pulses does not exceed 1 h.
- 3) A running conversion may become inexact in case of violating the normal operating conditions (voltage overshoot).
- 4) If a reduced reference voltage in a range of $V_{DDM}/2$ to V_{DDM} is used, then the ADC converter errors increase. If the reference voltage is reduced with the factor k ($k < 1$), then TUE, DNL, INL Gain and Offset errors increase with the factor 1/k.
If a reduced reference voltage in a range of 1 V to $V_{DDM}/2$ is used, then there are additional decrease in the ADC speed and accuracy.
- 5) Current peaks of up to 6 mA with a duration of max. 2 ns may occur
- 6) TUE is tested at $V_{AREF} = 3.3$ V, $V_{AGND} = 0$ V and $V_{DDM} = 3.3$ V
- 7) ADC module capability.
- 8) Not subject to production test, verified by design / characterization.
- 9) Value under typical application conditions due to integration (switching noise, etc.).
- 10) The sum of DNL/INL/Gain/Offset errors does not exceed the related TUE total unadjusted error.
- 11) For 10-bit conversions the DNL/INL/Gain/Offset error values must be multiplied with factor 0.25.
For 8-bit conversions the DNL/INL/Gain/Offset error values must be multiplied with 0.0625.
- 12) The leakage current definition is a continuous function, as shown in [Figure 4-3](#). The numerical values defined determine the characteristic points of the given continuous linear approximation - they do not define step function.
- 13) Only one of these parameters is tested, the other is verified by design characterization.
- 14) I_{AREF_MAX} is valid for the minimum specified conversion time. The current flowing during an ADC conversion with a duration of up to $t_C = 25\mu$ s can be calculated with the formula $I_{AREF_MAX} = Q_{CONV}/t_C$. Every conversion needs a total charge of $Q_{CONV} = 150$ pC from V_{AREF} .
All ADC conversions with a duration longer than $t_C = 25\mu$ s consume an $I_{AREF_MAX} = 6\mu$ A.

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- 15) For the definition of the parameters see also [Figure 4-2](#).
- 16) Applies to AIN0 and AIN1, when used as auxiliary reference inputs.
- 17) This represents an equivalent switched capacitance. This capacitance is not switched to the reference voltage at once. Instead of this smaller capacitances are successively switched to the reference voltage.
- 18) The sampling capacity of the conversion C-Network is pre-charged to $V_{AREF}/2$ before the sampling moment. Because of the parasitic elements the voltage measured at AINx is lower then $V_{AREF}/2$.

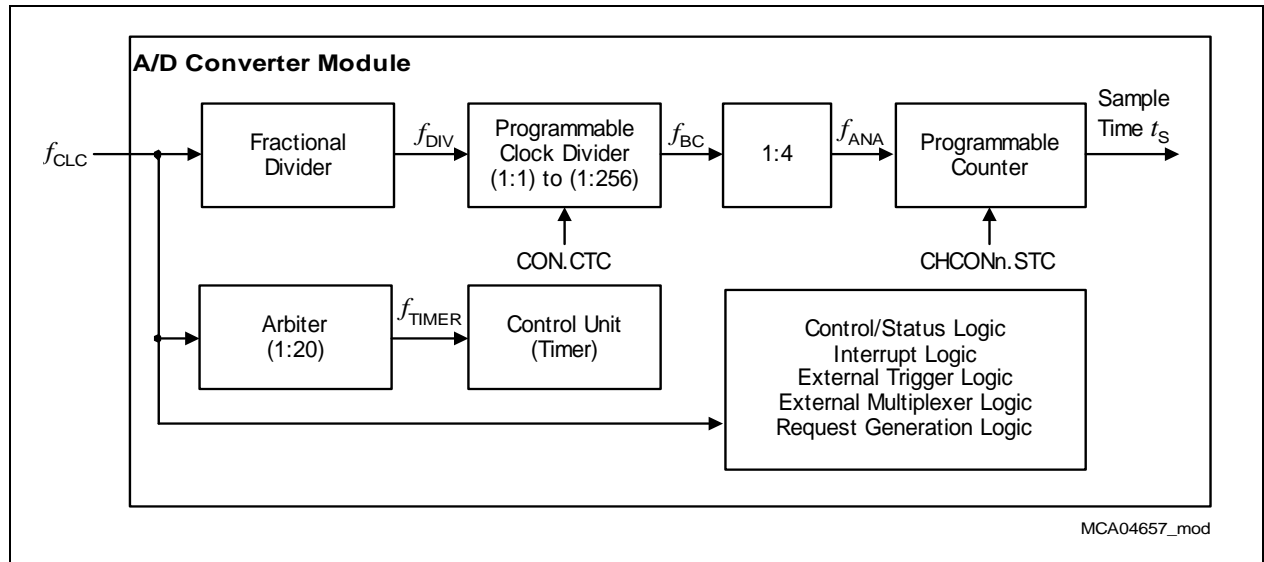


Figure 4-1 ADC0 Clock Circuit

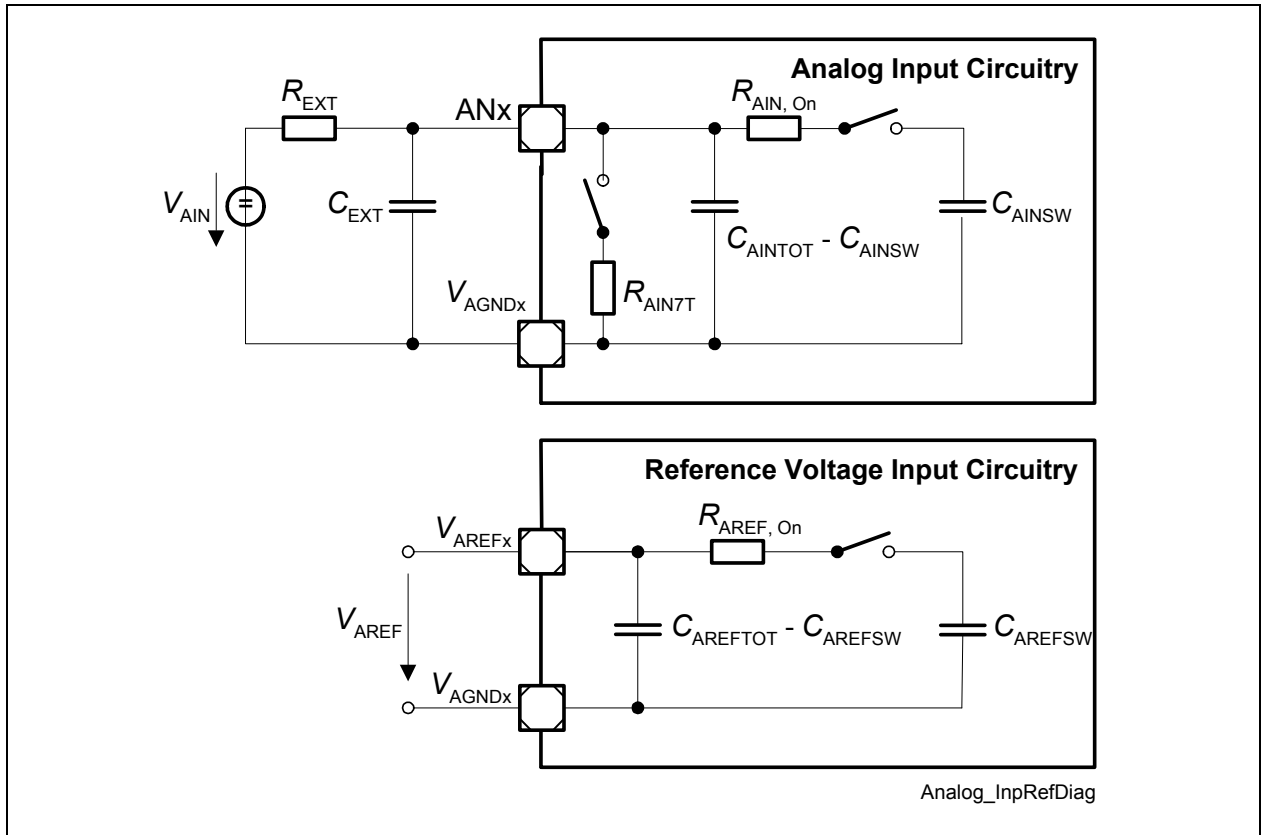


Figure 4-2 ADC0 Input Circuits

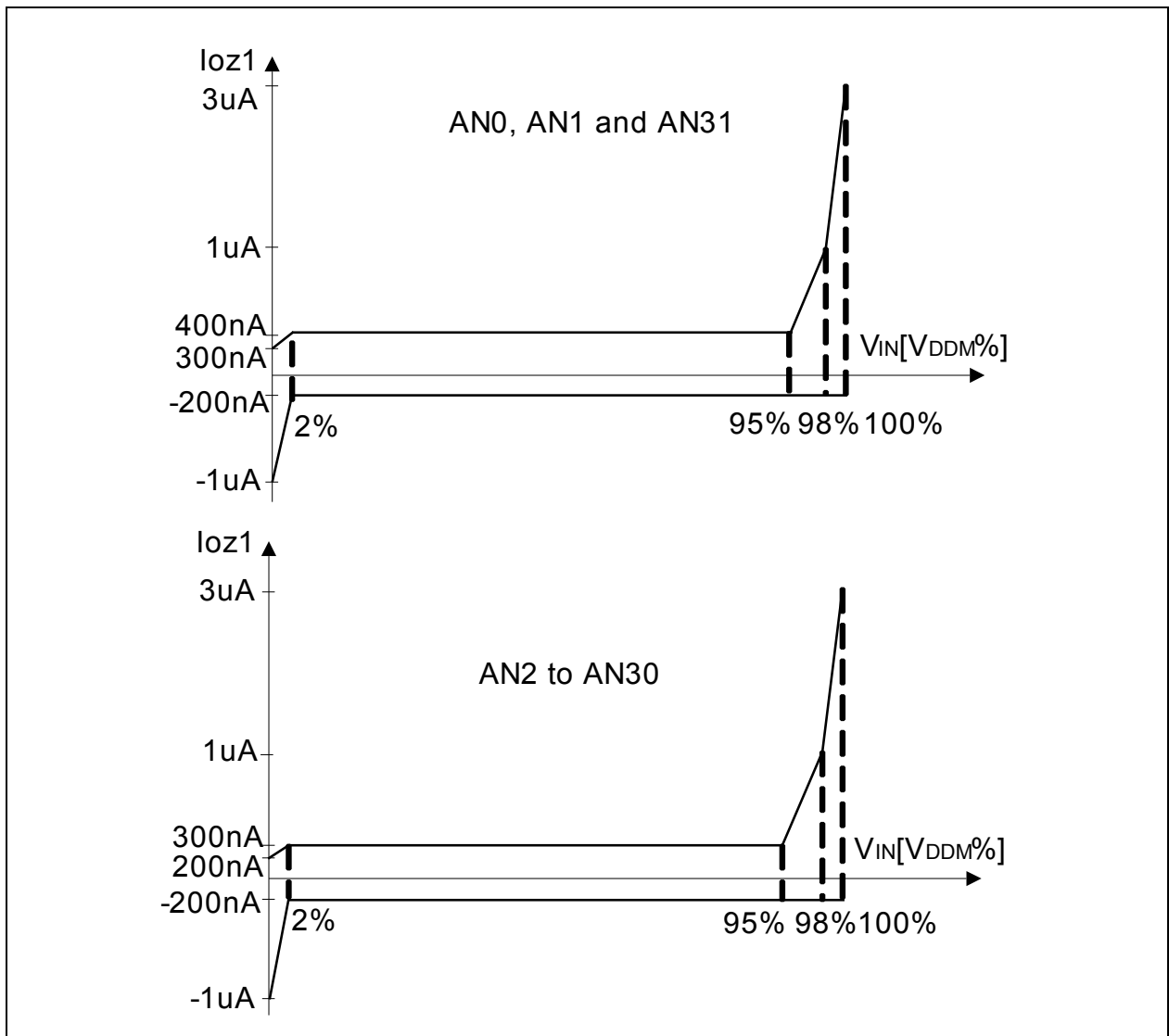


Figure 4-3 ADC0 Analog Inputs Leakage

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4.2.3 Fast Analog to Digital Converter (FADC)

Table 4-7 provides the characteristics of the FADC module in the TC1161/TC1162.

Table 4-7 FADC Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values		Unit	Remarks Conditions
			Min.	Max.		
DNL error	E_{DNL}	CC	–	± 1	LSB	¹²⁾
INL error	E_{INL}	CC	–	± 4	LSB	¹²⁾
Gradient error ¹⁾¹²⁾	E_{GRAD}	CC	–	± 3	%	²⁾ With calibration, gain 1, 2
			–	± 5	%	Without calibration gain 1, 2, 4
			–	± 6	%	Without calibration gain 8
Offset error ¹²⁾	E_{OFF} ³⁾	CC	–	± 20 ⁴⁾	mV	²⁾ With calibration
			–	± 60 ⁴⁾	mV	Without calibration
Reference error of internal $V_{FAREF}/2$	E_{REF}	CC	–	± 60	mV	–
Input leakage current at analog inputs AN32 to AN35. ⁵⁾ see Figure 4-5	I_{OZ1} ⁶⁾	CC	–1000	300	nA	$(0\% V_{DDM}) < V_{IN} < (2\% V_{DDM})$
			–200	400	nA	$(2\% V_{DDM}) < V_{IN} < (95\% V_{DDM})$
			–200	1000	nA	$(95\% V_{DDM}) < V_{IN} < (98\% V_{DDM})$
			–200	3000	nA	$(98\% V_{DDM}) < V_{IN} < (100\% V_{DDM})$
Analog supply voltages	V_{DDMF}	SR	3.13	3.47 ⁷⁾	V	–
	V_{DDAF}	SR	1.42	1.58 ⁸⁾	V	–
Analog ground voltage	V_{SSAF}	SR	–0.1	0.1	V	–
Analog reference voltage	V_{FAREF}	SR	3.13	3.47 ⁷⁾⁹⁾	V	Nominal 3.3 V
Analog reference ground	V_{FAGND}	SR	$V_{SSAF} - 0.05V$	$V_{SSAF} + 0.05V$	V	–
Analog input voltage range	V_{AINF}	SR	V_{FAGND}	V_{DDMF}	V	–

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Table 4-7 FADC Characteristics (cont'd)(Operating Conditions apply)

Parameter	Symbol		Limit Values		Unit	Remarks Conditions
			Min.	Max.		
Analog supply currents	I_{DDMF}	SR	–	9	mA	–
	I_{DDAF}	SR	–	17	mA	¹⁰⁾
Input current at each V_{FAREF}	I_{FAREF}	CC	–	150	μA rms	Independent of conversion
Input leakage current at V_{FAREF} ¹¹⁾	I_{FOZ2}	CC	–	± 500	nA	$0 V < V_{IN} < V_{DDMF}$
Input leakage current at V_{FAGND}	I_{FOZ3}	CC		± 8	μA	
Conversion time	t_C	CC	–	21	CLK of f_{ADC}	For 10-bit conv.
Converter Clock	f_{ADC}	CC	–	66	MHz	–
Input resistance of the analog voltage path (Rn, Rp)	R_{FAIN}	CC	100	200	k Ω	¹²⁾
Channel Amplifier Cutoff Frequency	f_{COFF}	CC	2		MHz	–
Settling Time of a Channel Amplifier after changing ENN or ENP	t_{SET}	CC		5	μsec	–

1) Calibration of the gain is possible for the gain of 1 and 2, and not possible for the gain of 4 and 8.

2) Callibration must be performed minimum once per week.

3) The offset error voltage drifts over the whole temperature range typically ± 2 LSB.

4) Applies when the gain of the channel equals one. For the other gain settings, the offset error increases; it must be multiplied with the applied gain.

5) The leakage current definition is a continuous function, as shown in [Figure 4-5](#). The numerical values defined determine the characteristic points of the given continuous linear approximation - they do not define step function.

6) Only one of these parameters is tested, the other is verified by design characterization.

7) Voltage overshoot to 4 V are permissible, provided the pulse duration is less than 100 μs and the cumulated summary of the pulses does not exceed 1 h.

8) Voltage overshoot to 1.7 V are permissible, provided the pulse duration is less than 100 μs and the cumulated sum of the pulses does not exceed 1 h.

9) A running conversion may become inexact in case of violating the normal operating conditions (voltage overshoots).

10) Current peaks of up to 40 mA with a duration of max. 2 ns may occur

11) This value applies in power-down mode.

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12) Not subject to production test, verified by design / characterization.

The calibration procedure should run after each power-up, when all power supply voltages and the reference voltage have stabilized. The offset calibration must run first, followed by the gain calibration.

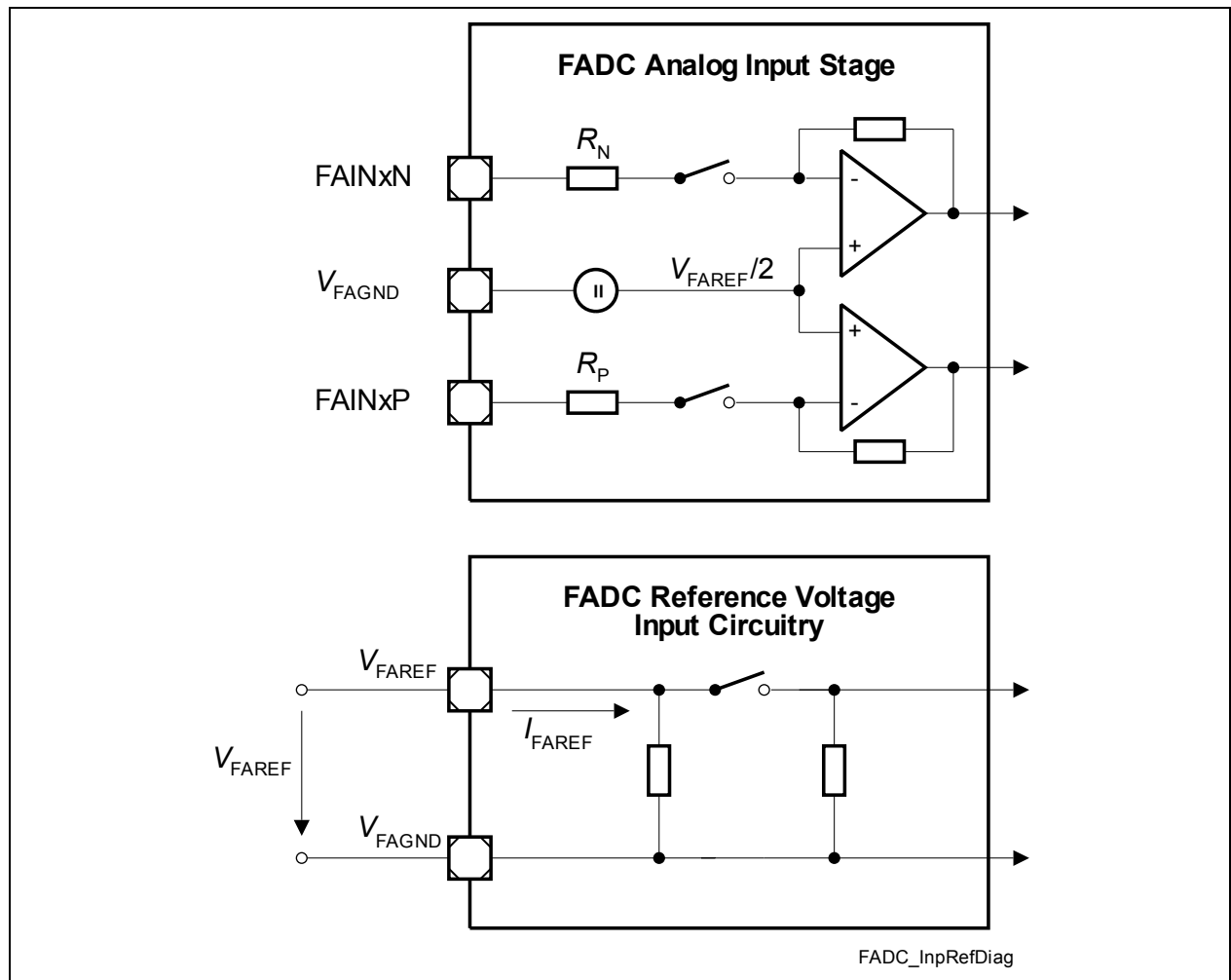


Figure 4-4 FADC Input Circuits

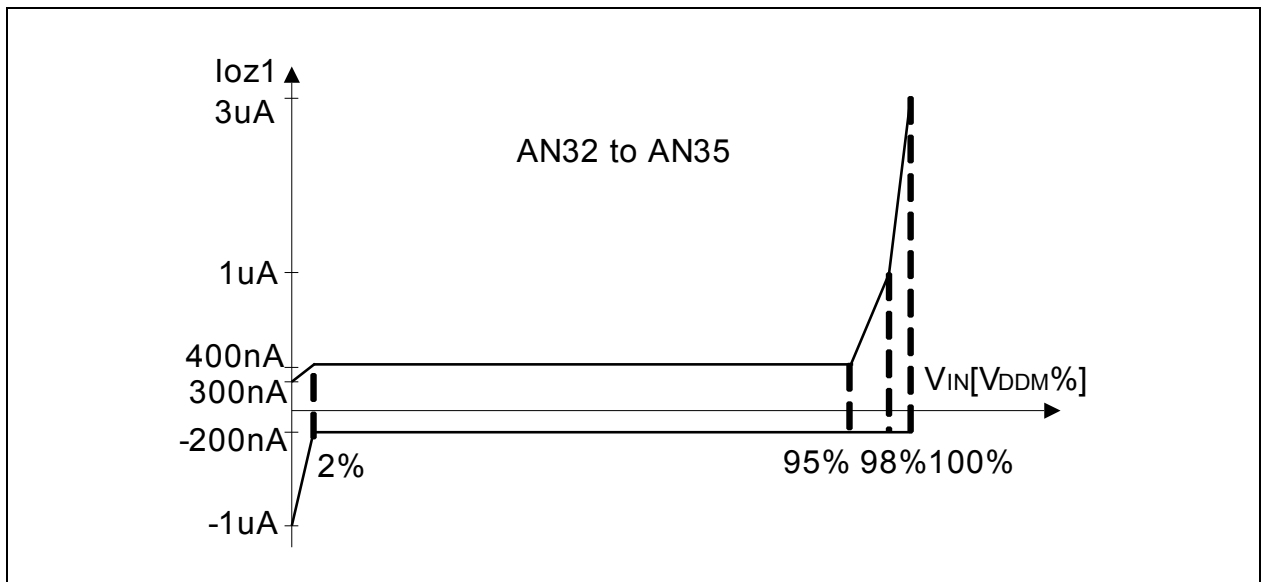


Figure 4-5 Analog Inputs AN32-AN35 Leakage

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4.2.4 Oscillator Pins

Table 4-8 provides the characteristics of the oscillator pins in the TC1161/TC1162.

Table 4-8 Oscillator Pins Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit values		Unit	Test Conditions
			Min.	Max.		
Frequency Range	f_{OSC}	CC	4	25	MHz	–
Input low voltage at XTAL1 ¹⁾	V_{ILX}	SR	-0.2	$0.3 \times V_{DDOSC3}$	V	–
Input high voltage at XTAL1 ¹⁾	V_{IHx}	SR	$0.7 \times V_{DDOSC3}$	$V_{DDOSC3} + 0.2$	V	–
Input current at XTAL1	I_{IX1}	CC	–	± 25	μA	$0 V < V_{IN} < V_{DDOSC3}$

1) If the XTAL1 pin is driven by a crystal, reaching a minimum amplitude (peak-to-peak) of $0.3 \times V_{DDOSC3}$ is necessary.

Note: It is strongly recommended to measure the oscillation allowance (negative resistance) in the final target system (layout) to determine the optimal parameters for the oscillator operation. Please refer to the limits specified by the crystal supplier.

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4.2.5 Temperature Sensor

Table 4-9 provides the characteristics of the temperature sensor in the TC1161/TC1162.

Table 4-9 Temperature Sensor Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values		Unit	Remarks
			Min.	Max.		
Temperature Sensor Range	T_{SR}	SR	-40	150	°C	–
Start-up time after resets inactive	t_{TSST}	SR		10	µs	
Temperature of the die at the sensor location	T_{TS}	CC	$T_{TS} = (ADC_Code - 487) \times 0.396 - 40$		°C	10-bit ADC result
			$T_{TS} = (ADC_Code - 1948) \times 0.099 - 40$		°C	12Bit ADC result
Sensor Inaccuracy	T_{TSA}	CC		±10	°C	
A/D Converter clock for DTS signal	f_{ANA}	SR	–	10	MHz	Conversion with ADC0

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4.2.6 Power Supply Current

Table 4-10 provides the characteristics of the power supply current in the TC1161/TC1162.

Table 4-10 Power Supply Current (Operating Conditions apply)

Parameter	Symbol		Limit Values			Unit	Test Conditions / Remarks
			Min.	Typ.	Max.		
PORST low current at V_{DD}	I_{DD_PORST}	CC	–	90	–	mA	The PLL running at the base frequency
PORST low current at V_{DDP}	I_{DDP_PORST}	CC	–	10	–	mA	The PLL running at the base frequency
Active mode core supply current¹⁾	I_{DD}	CC	–	200	–	mA	$f_{CPU} = 66\text{MHz}$ $f_{CPU}/f_{SYS} = 1:1$
Active mode analog supply current	$I_{DDAx};$ I_{DDMx}	CC	–	–	–	mA	See ADC0/FADC
Oscillator and PLL core power supply	I_{DDOSC}	CC	–	5	–	mA	–
Oscillator and PLL pads power supply	I_{DDOSC3}	CC	–	3 ²⁾	–	mA	–
FLASH power supply current	I_{DDFL3}	CC	–	45	–	mA	–
LVDS port supply (via V_{DDP})³⁾	I_{LVDS}	CC	–	25	–	mA	LVDS pads active
Maximum Allowed Power Dissipation⁴⁾	P_{Dmax}	SR	$P_D \times R_{TJA} < 40^\circ\text{C}$			–	At worst case, $T_A = 85^\circ\text{C}$

1) Infineon Power Loop: CPU running, all peripherals active. The power consumption of each custom application will most probably be lower than this value, but must be evaluated separately.

2) Estimated value; double-bonded at package level with V_{DDP} .

3) In case the LVDS pads are disabled, the power consumption per pair is negligible (less than 1µA).

4) For the calculation of the junction to ambient thermal resistance R_{TJA} , see [Chapter 5.1](#)

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4.3 AC Parameters

All AC parameters are defined with the temperature compensation disabled, which means that pads are constantly kept at the maximum strength.

4.3.1 Testing Waveforms

The testing waveforms for rise/fall time, output delay and output high impedance are shown in [Figure 4-6](#), [Figure 4-7](#) and [Figure 4-8](#).

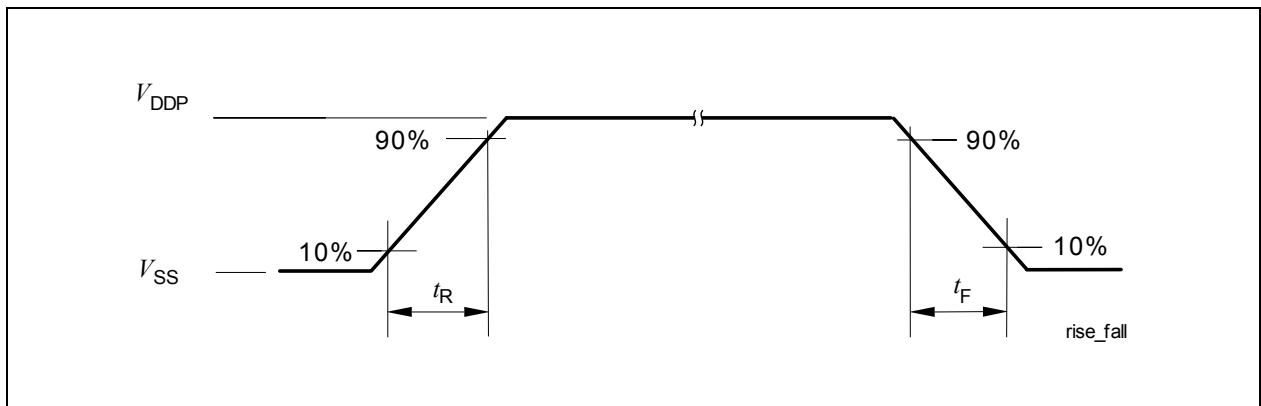


Figure 4-6 Rise/Fall Time Parameters

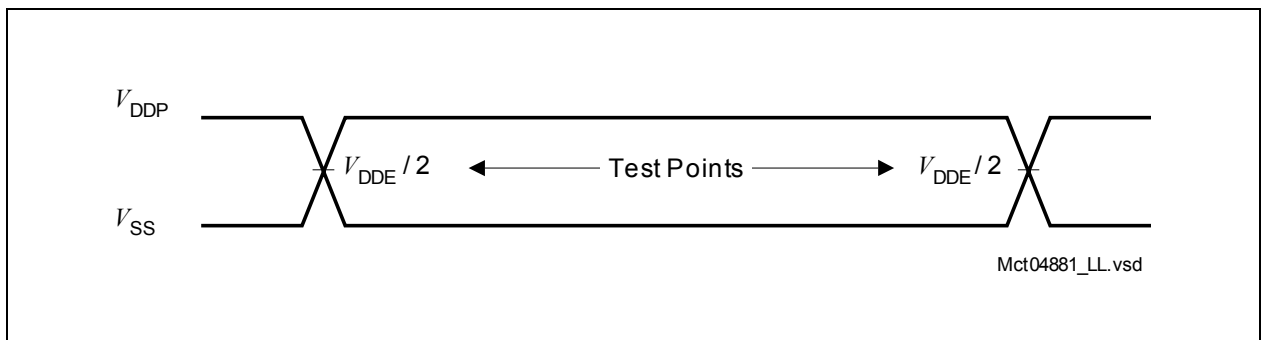


Figure 4-7 Testing Waveform, Output Delay

$$V_{\text{Load}} + 0.1 \text{ V}$$

Timing

$$V_{\text{OH}} - 0.1 \text{ V}$$

MCT04880_LL

Figure 4-8 Testing Waveform, Output High Impedance

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Electrical Parameters
4.3.2 Output Rise/Fall Times

Table 4-11 provides the characteristics of the output rise/fall times in the TC1161/TC1162.

Table 4-11 Output Rise/Fall Times (Operating Conditions apply)

Parameter	Symbol	Limit Values		Unit	Test Conditions
		Min.	Max.		
Class A1 Pads					
Rise/fall times ¹⁾ Class A1 pads	t_{RA1}, t_{FA1}		50 140 18000 150 550 65000	ns	Regular (medium) driver, 50 pF Regular (medium) driver, 150 pF Regular (medium) driver, 20 nF Weak driver, 20 pF Weak driver, 150 pF Weak driver, 20 000 pF
Class A2 Pads					
Rise/fall times ¹⁾ Class A2 pads	t_{FA2}, t_{FA2}		3.3 6 5.5 16 50 140 18000 150 550 65000	ns	Strong driver, sharp edge, 50 pF Strong driver, sharp edge, 100pF Strong driver, med. edge, 50 pF Strong driver, soft edge, 50 pF Medium driver, 50 pF Medium driver, 150 pF Medium driver, 20 000 pF Weak driver, 20 pF Weak driver, 150 pF Weak driver, 20 000 pF
Class A3 Pads					
Rise/fall times ¹⁾ Class A3 pads	t_{FA3}, t_{FA3}		2.5	ns	50 pF
Class A4 Pads					
Rise/fall times ¹⁾ Class A4 pads	t_{FA4}, t_{FA4}		2.0	ns	25 pF
Class C Pads					
Rise/fall times Class C pads	t_{rC}, t_{fC}		2	ns	

1) Not all parameters are subject to production test, but verified by design/characterization and test correlation.

4.3.3 Power Sequencing

There is a restriction for the power sequencing of V_{DD} and V_{DDP} as shown in **Figure 4-9**: V_{DDP} must always be higher than $V_{DD} - 0.5\text{ V}$. The gray area shows the valid range for V_{DDP} .

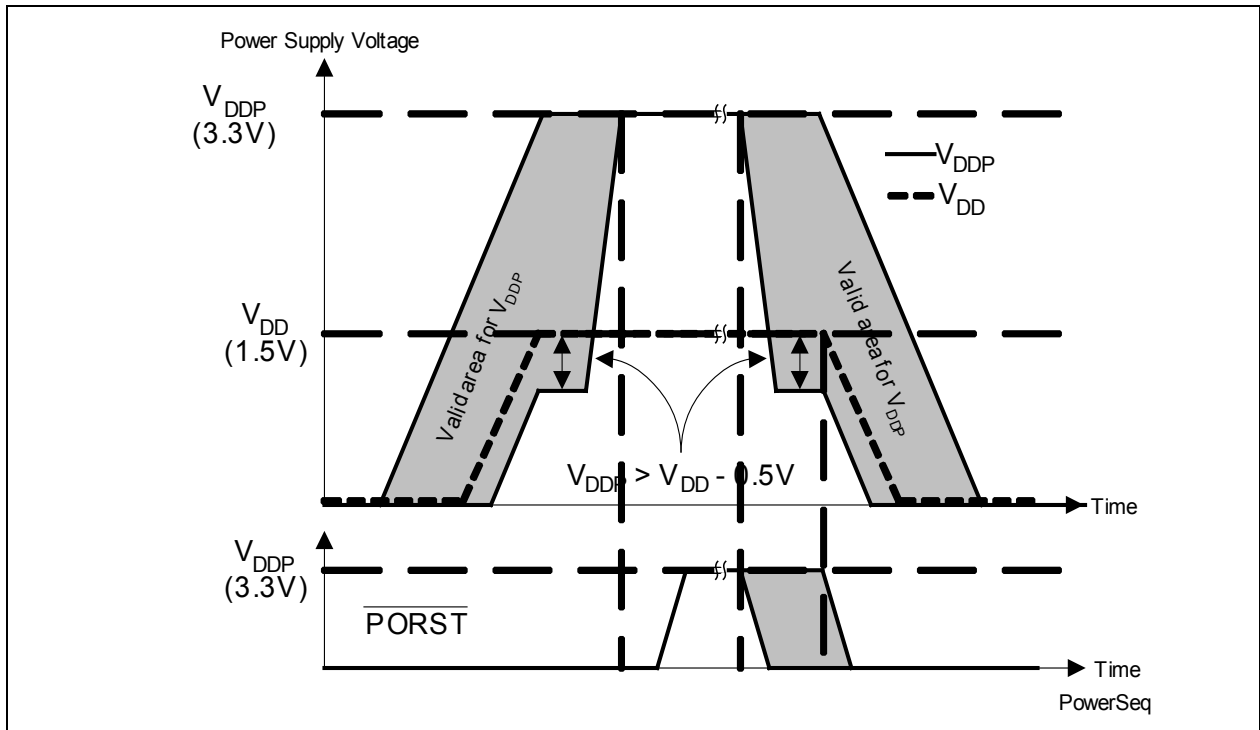


Figure 4-9 V_{DDP} / V_{DD} Power Up Sequence

All ground pins V_{SS} must be externally connected to one single star point in the system. The difference voltage between the ground pins must not exceed 200 mV.

The $\overline{\text{PORST}}$ signal must be activated at latest before any power supply voltage falls below the levels shown on the figure below. In this case, only the memory row that was the target of the write at the moment of the power loss will contain unreliable content. Additionally, the $\overline{\text{PORST}}$ signal should be activated as soon as possible. The sooner the $\overline{\text{PORST}}$ signal is activated, the less time the system operates outside of the normal operating power supply range.

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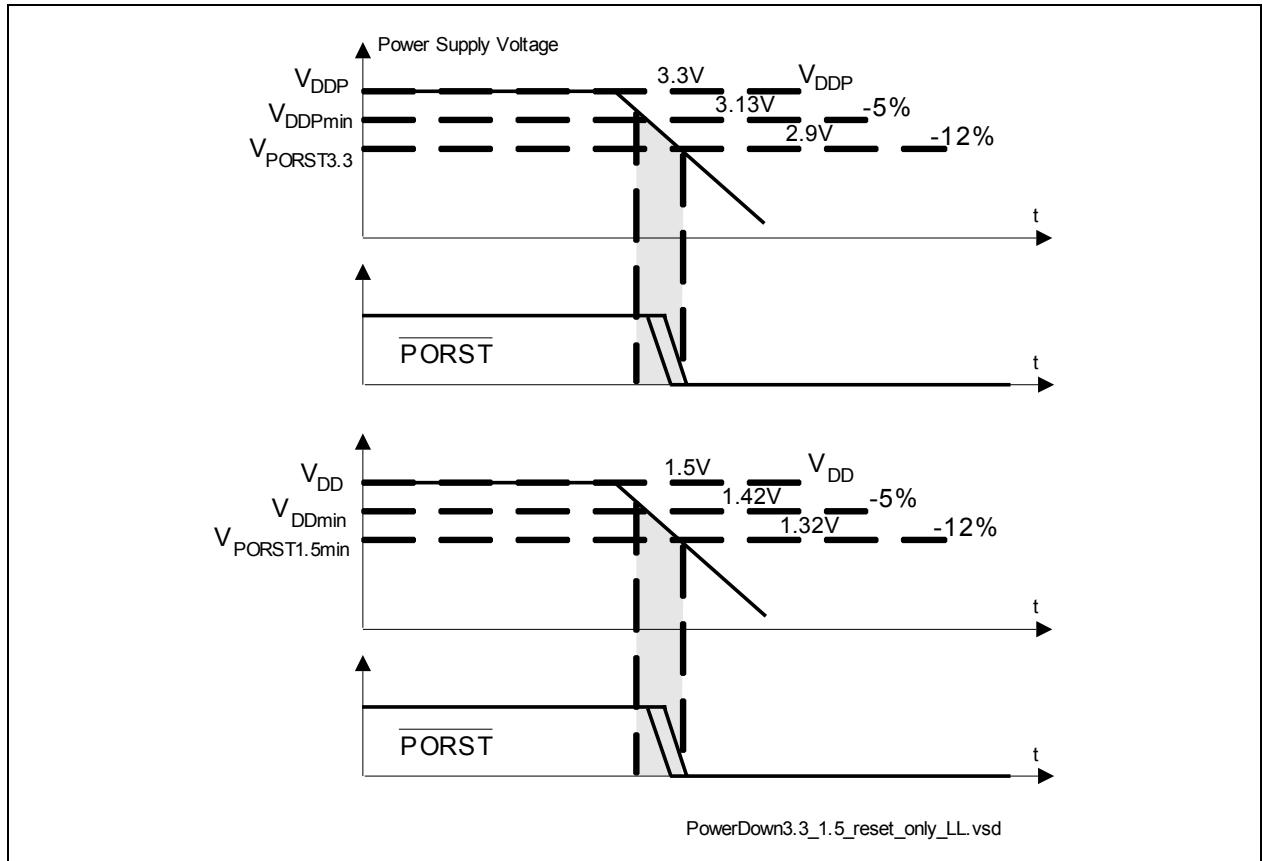


Figure 4-10 Power Down / Power Loss Sequence

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4.3.4 Power, Pad and Reset Timing

Table 4-12 provides the characteristics of the power, pad and reset timing in the TC1161/TC1162.

Table 4-12 Power, Pad and Reset Timing Parameters

Parameter	Symbol		Limit Values		Unit
			Min.	Max.	
Min. V_{DDP} voltage to ensure defined pad states ¹⁾	V_{DDPPA}	CC	0.6	–	V
Oscillator start-up time ²⁾	t_{OSCS}	CC	–	10	ms
Minimum \overline{PORST} active time after power supplies are stable at operating levels	t_{POA}	SR	10	–	ms
\overline{HDRST} pulse width	t_{HD}	CC	1024 clock cycles ³⁾	–	f_{SYS}
\overline{PORST} rise time	t_{POR}	SR	–	50	ms
Setup time to \overline{PORST} rising edge ⁴⁾	t_{POS}	SR	0	–	ns
Hold time from \overline{PORST} rising edge ⁴⁾	t_{POH}	SR	100	–	ns
Setup time to \overline{HDRST} rising edge ⁵⁾	t_{HDS}	SR	0	–	ns
Hold time from \overline{HDRST} rising edge ⁵⁾	t_{HDH}	SR	100 + $(2 \times 1/f_{SYS})$	–	ns
Ports inactive after \overline{PORST} reset active ⁶⁾⁷⁾	t_{PIP}	CC	–	150	ns
Ports inactive after \overline{HDRST} reset active ⁸⁾	t_{PI}	CC	–	150 + $5 \times 1/f_{SYS}$	ns
Minimum V_{DDP} \overline{PORST} activation threshold. ⁹⁾	$V_{PORST3.3}$	SR	–	2.9	V
Minimum V_{DD} \overline{PORST} activation threshold. ⁹⁾	$V_{PORST1.5}$	SR	–	1.32	V
Power-on Reset Boot Time ¹⁰⁾	t_{BP}	CC	2.15	3.50	mS
Hardware/Software Reset Boot Time at $f_{CPU}=66\text{MHz}$ ¹¹⁾	t_B	CC	500	800	μS

1) This parameter is valid under assumption that \overline{PORST} signal is constantly at low-level during the power-up/power-down of the V_{DDP} .

2) This parameter is verified by device characterization. The external oscillator circuitry must be optimized by the customer and checked for negative resistance as recommended and specified by crystal suppliers.

3) Any \overline{HDRST} activation is internally prolonged to 1024 FPI bus clock (f_{SYS}) cycles.

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- 4) Applicable for input pins $\overline{\text{TESTMODE}}$, $\overline{\text{TRST}}$, $\overline{\text{BRKIN}}$, and TXD1A with noise suppression filter of $\overline{\text{PORST}}$ switched-on (BYPASS = 0).
- 5) The setup/hold values are applicable for Port 0 and Port 4 input pins with noise suppression filter of $\overline{\text{HDRST}}$ switched-on (BYPASS = 0), independently whether $\overline{\text{HDRST}}$ is used as input or output.
- 6) Not subject to production test, verified by design / characterization.
- 7) This parameter includes the delay of the analog spike filter in the $\overline{\text{PORST}}$ pad.
- 8) Not subject to production test, verified by design / characterization.
- 9) In case of power loss during internal flash write, prevents Flash write to random address.
- 10) Booting from Flash, the duration of the boot-time is defined between the rising edge of the $\overline{\text{PORST}}$ and the moment when the first user instruction has entered the CPU and its processing starts.
- 11) Booting from Flash, the duration of the boot time is defined between the following events:
 1. Hardware reset: the falling edge of a short $\overline{\text{HDRST}}$ pulse and the moment when the first user instruction has entered the CPU and its processing starts, if the $\overline{\text{HDRST}}$ pulse is shorter than $1024 \times T_{\text{SYS}}$. If the $\overline{\text{HDRST}}$ pulse is longer than $1024 \times T_{\text{SYS}}$, only the time beyond the $1024 \times T_{\text{SYS}}$ should be added to the boot time ($\overline{\text{HDRST}}$ falling edge to first user instruction).
 2. Software reset: the moment of starting the software reset and the moment when the first user instruction has entered the CPU and its processing starts

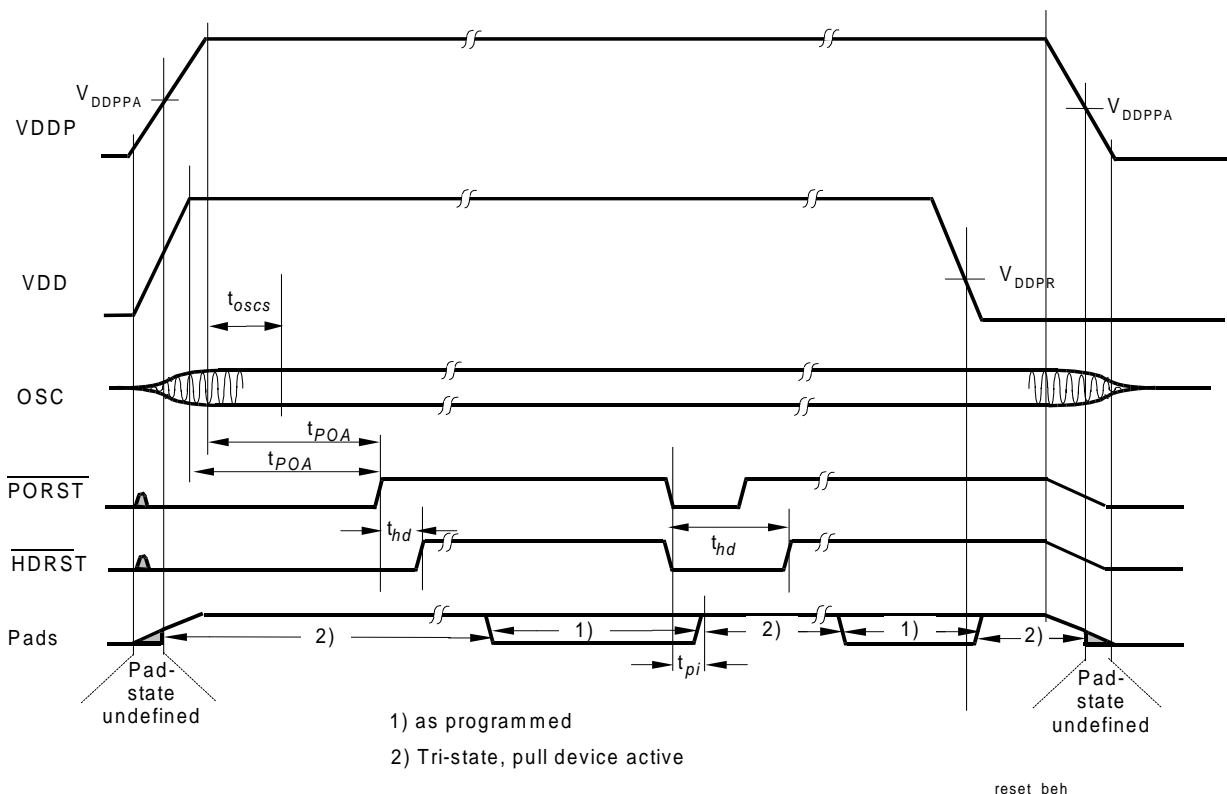


Figure 4-11 Power, Pad and Reset Timing

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4.3.5 Phase Locked Loop (PLL)

Section 4.3.5 provides the characteristics of the PLL parameters and its operation in the TC1161/TC1162.

Note: All PLL characteristics defined on this and the next page are verified by design characterization.

Table 4-13 PLL Parameters (Operating Conditions apply)

Parameter	Symbol	Limit Values		Unit
		Min.	Max.	
Accumulated jitter	D_P	To be defined		–
VCO frequency range	f_{VCO}	400	500	MHz
		500	600	MHz
		600	700	MHz
PLL base frequency ¹⁾	$f_{PLLBASE}$	140	320	MHz
		150	400	MHz
		200	480	MHz
PLL lock-in time	t_L	–	200	μs

1) The CPU base frequency which is selected after reset is calculated by dividing the limit values by 16 (this is the K factor after reset).

Phase Locked Loop Operation

When PLL operation is enabled and configured, the PLL clock f_{VCO} (and with it the CPU clock f_{CPU}) is constantly adjusted to the selected frequency. The relation between f_{VCO} and f_{SYS} is defined by: $f_{VCO} = K \times f_{CPU}$. The PLL causes a jitter of f_{CPU} and affects the clock outputs TRCLK and SYSCLK (P4.3) which are derived from the PLL clock f_{VCO} .

Two formulas that define the (absolute) approximate maximum value of jitter D_N in ns dependent on the K-factor, the CPU clock frequency f_{CPU} in MHz, and the number P of consecutive f_{CPU} clock periods will be defined.

Formula 1 : To be defined (4.1)

Formula 2 : To be defined (4.2)

Note: The frequency of system clock f_{SYS} can be selected to be either f_{CPU} or $f_{CPU}/2$.

With rising number P of clock cycles the maximum jitter increases linearly up to a value of P that is defined by the K-factor of the PLL. Beyond this value of P the maximum accumulated jitter remains at a constant value. Further, a lower CPU clock frequency f_{CPU} results in a higher absolute maximum jitter value.


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4.3.6 Debug Trace Timing

$V_{SS} = 0 \text{ V}$; $V_{DDP} = 3.13 \text{ to } 3.47 \text{ V}$ (Class A); $T_A = -40 \text{ }^{\circ}\text{C to } +85 \text{ }^{\circ}\text{C}$;
 $C_L (\text{TRCLK}) = 25 \text{ pF}$; $C_L (\text{TR}[15:0]) = 50 \text{ pF}$

Table 4-14 Debug Trace Timing Parameter¹⁾

Parameter	Symbol	Limit Values		Unit
		Min.	Max.	
TR[15:0] new state from TRCLK 	t_9 CC	-1	4	ns

1) Not subject to production test, verified by design/characterization.

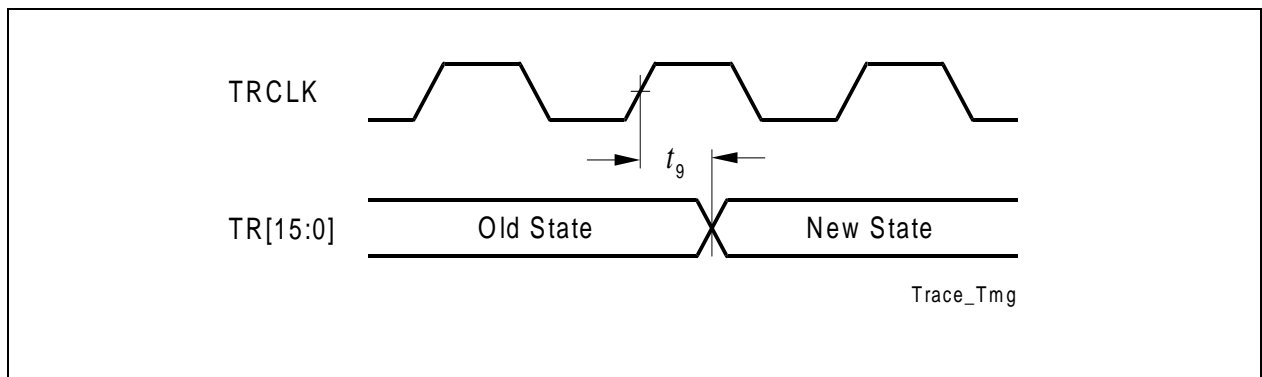


Figure 4-12 Debug Trace Timing

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4.3.7 Peripheral Timings





Section 4.3.7 provides the characteristics of the peripheral timings in the TC1161/TC1162.

Note: Peripheral timing parameters are not subject to production test. They are verified by design/characterization.

4.3.7.1 Micro Link Interface (MLI) Timing

Table 4-15 provides the characteristics of the MLI timing in the TC1161/TC1162.

Table 4-15 MLI Timing (Operating Conditions apply), $C_L = 50$ pF

Parameter	Symbol		Limit Values		Unit
			Min.	Max.	
TCLK/RCLK clock period ¹⁾²⁾	t_{30}	CC/ SR	$2 \times T_{MLI}$ ³⁾	—	ns
MLI outputs delay from TCLK 	t_{35}	CC	0	8	ns
MLI inputs setup to RCLK 	t_{36}	SR	4	—	ns
MLI inputs hold to RCLK 	t_{37}	SR	4	—	ns
RREADY output delay from RCLK 	t_{38}	CC	0	8	ns

1) TCLK signal rise/fall times are the same as the A2 Pads rise/fall times.

2) TCLK high and low times can be minimum $1 \times T_{MLI}$

3) $T_{MLImin} = T_{SYS} = 1/f_{SYS}$. When $f_{SYS} = 66\text{MHz}$, $t_{30} = 30.3\text{ns}$

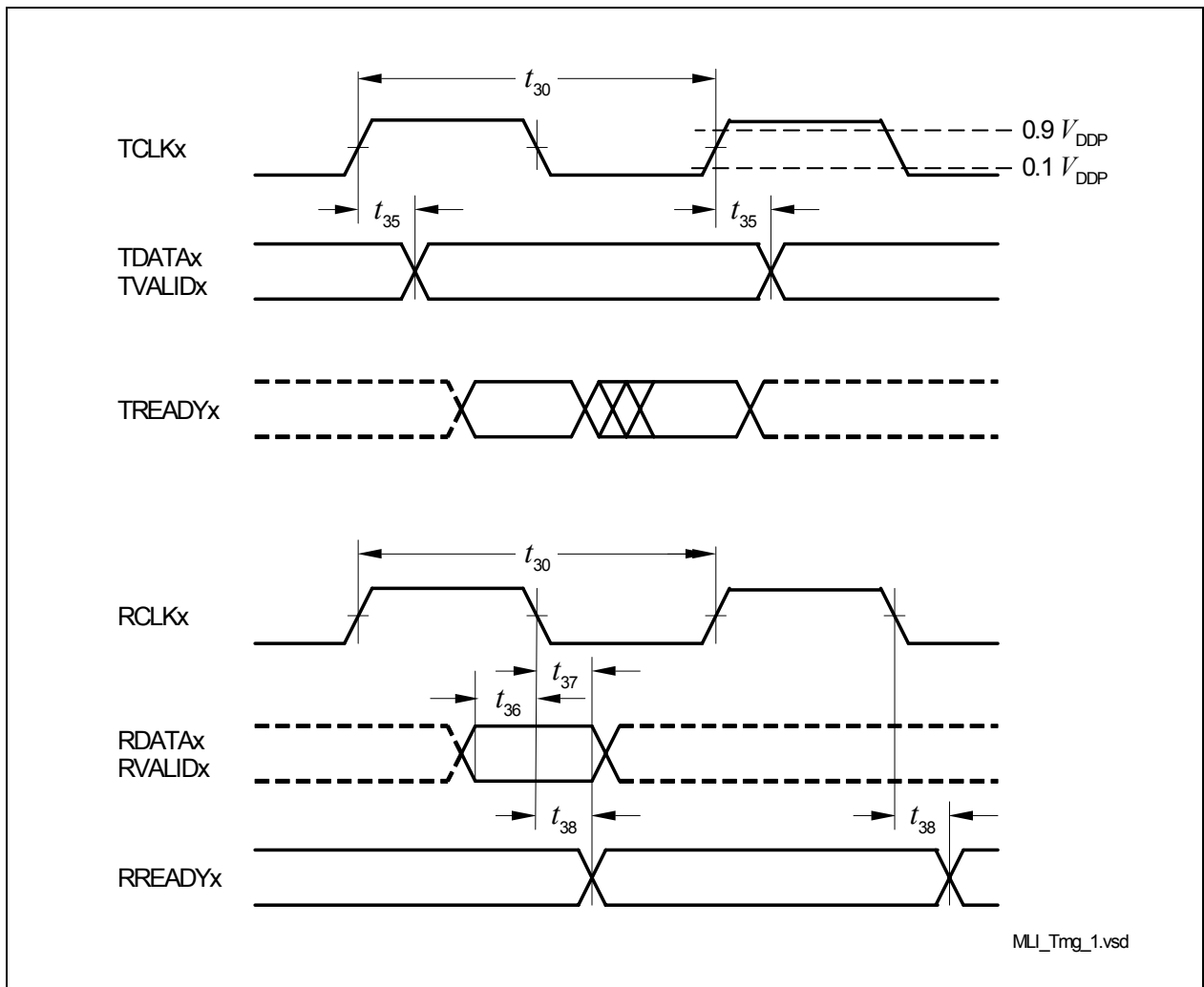


Figure 4-13 MLI Interface Timing

Note: The generation of RREADYx is in the input clock domain of the receiver. The reception of TREADYx is asynchronous to TCLKx.

4.3.7.2 Micro Second Channel (MSC) Interface Timing

Table 4-16 provides the characteristics of the MSC timing in the TC1161/TC1162.

Table 4-16 MSC Interface Timing (Operating Conditions apply), CL = 50 pF

Parameter	Symbol		Limit Values		Unit
			Min.	Max.	
FCLP clock period ¹⁾²⁾	t_{40}	CC	$2 \times T_{MSC}^{3)}$	–	ns
SOP/ENx outputs delay from FCLP	t_{45}	CC	-10	10	ns
SDI bit time	t_{46}	SR	$8 \times T_{MSC}$	–	ns
SDI rise time	t_{48}	SR		100	ns
SDI fall time	t_{49}	SR		100	ns

1) FCLP signal rise/fall times are the same as the A2 Pads rise/fall times.

2) FCLP signal high and low can be minimum $1 \times T_{MSC}$.

3) $T_{MSCmin} = T_{SYS} = 1/f_{SYS}$. When $f_{SYS} = 66\text{MHz}$, $t_{40} = 30.3\text{ns}$

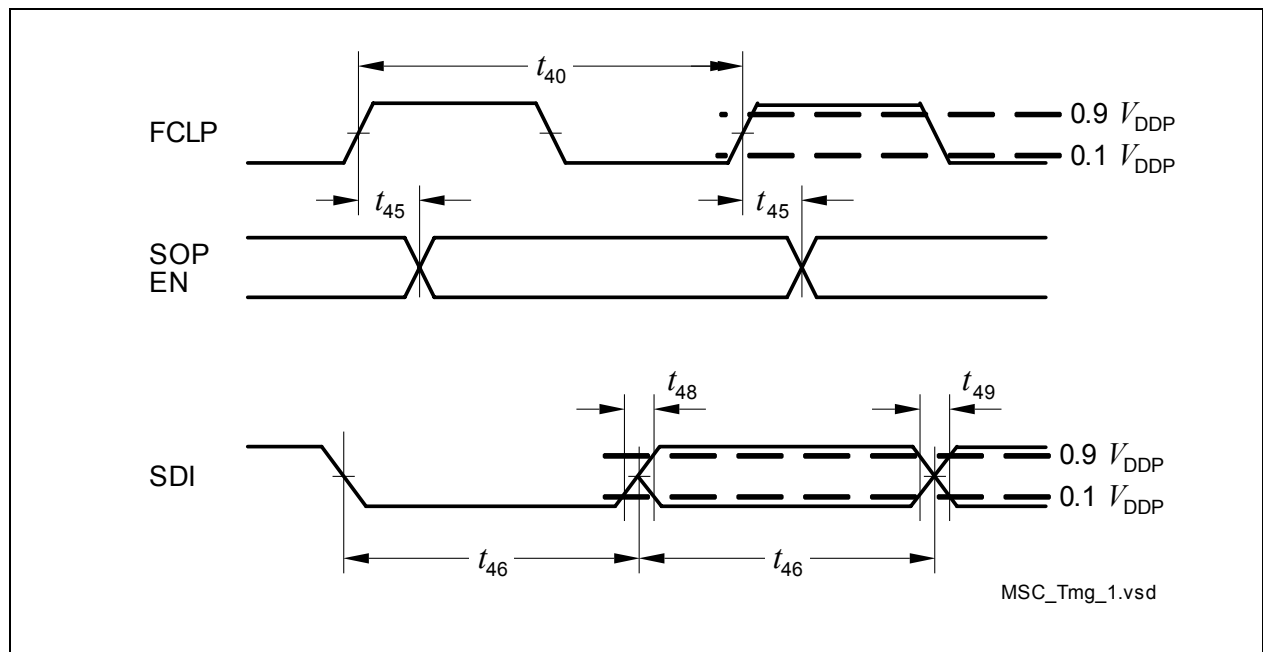


Figure 4-14 MSC Interface Timing

Note: The data at SOP should be sampled with the falling edge of FCLP in the target device.




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4.3.7.3 Synchronous Serial Channel (SSC) Master Mode Timing

Table 4-17 provides the characteristics of the SSC timing in the TC1161/TC1162.

Table 4-17 SSC Master Mode Timing (Operating Conditions apply), CL = 50 pF

Parameter	Symbol		Limit Values		Unit
			Min.	Max.	
SCLK clock period ¹⁾²⁾	t_{50}	CC	$2 \times T_{SSC}^{3)}$	–	ns
MTSR/SLSOx delay from SCLK 	t_{51}	CC	0	8	ns
MRST setup to SCLK 	t_{52}	SR	10	–	ns
MRST hold from SCLK 	t_{53}	SR	5	–	ns

1) SCLK signal rise/fall times are the same as the A2 Pads rise/fall times.

2) SCLK signal high and low times can be minimum $1 \times T_{SSC}$.

3) $T_{SSCmin} = T_{SYS} = 1/f_{SYS}$. When $f_{SYS} = 66$ MHz, $t_{50} = 30.3$ ns

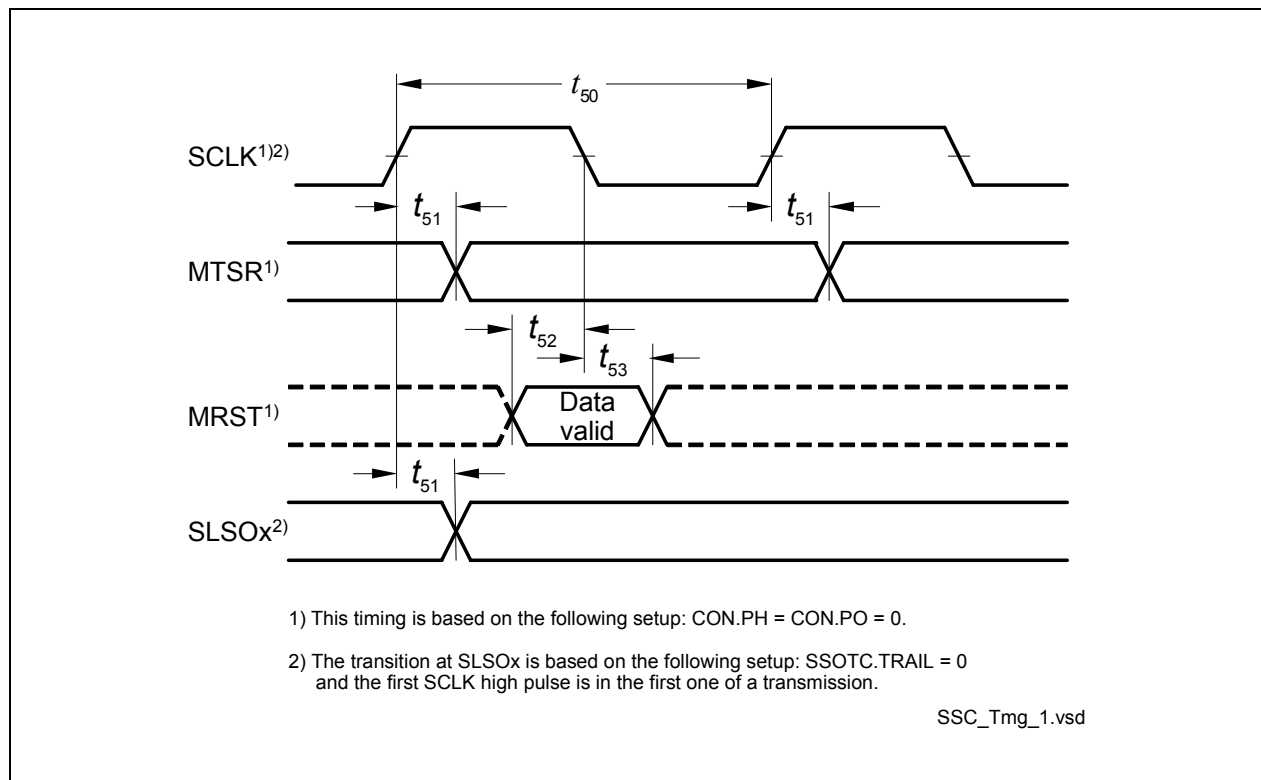


Figure 4-15 SSC Master Mode Timing

5 Packaging

Chapter 5 provides the information of the TC1161/TC1162 package.

5.1 Package Parameters

Table 5-1 provides the characteristics of the package parameters.

Table 5-1 Package Parameters (PG-LQFP-176-2)

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
Thermal resistance junction case top ¹⁾	R_{TJCT} CC	–	5.4	K/W	–
Thermal resistance junction case bottom ¹⁾	R_{TJCB} CC	–	21.5	K/W	–

1) The top and bottom thermal resistances between the case and the ambient (R_{TCAT} , R_{TCAB}) are to be combined with the thermal resistances between the junction and the case given above (R_{TJCT} , R_{TJCB}), in order to calculate the total thermal resistance between the junction and the ambient (R_{TJA}). The thermal resistances between the case and the ambient (R_{TCAT} , R_{TCAB}) depend on the external system (PCB, case) characteristics, and are under user responsibility.

The junction temperature can be calculated using the following equation: $T_J = T_A + R_{TJA} \times P_D$, where the R_{TJA} is the total thermal resistance between the junction and the ambient. This total junction ambient resistance R_{TJA} can be obtained from the upper four partial thermal resistances, by

- simply adding only the two bottom thermal resistances (junction case bottom and case ambient bottom), or
- by taking all four resistances into account, depending on the precision needed.

5.2 Package Outline

Figure 5-1 shows the package outlines of the TC1161/TC1162.

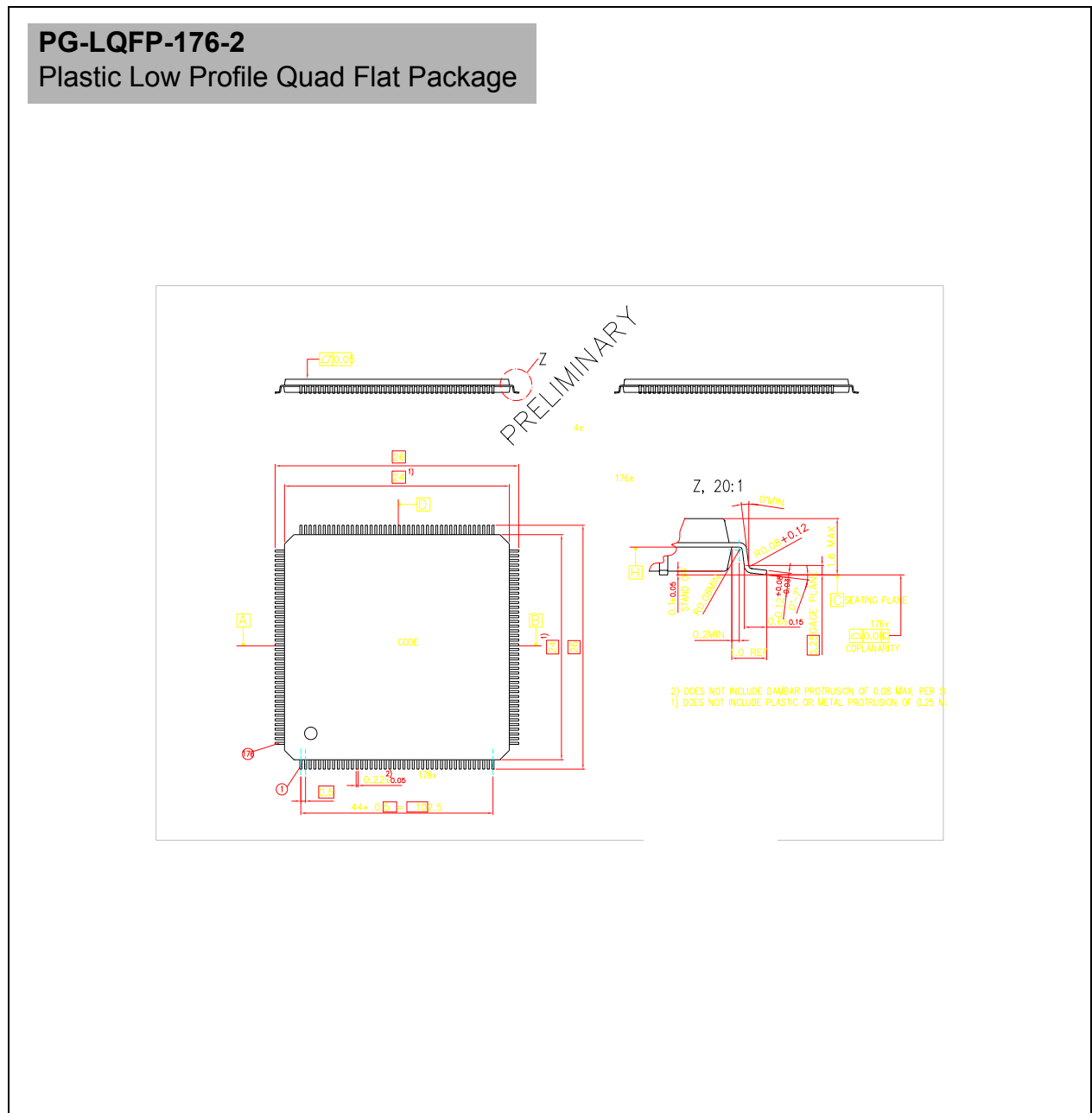


Figure 5-1 Package Outlines PG-LQFP-176-2

You can find all of our packages, sorts of packing and others in our Infineon Internet Page “Products”: <http://www.infineon.com/products>.

SMD = Surface Mounted Device

Dimensions in mm

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5.3 Flash Memory Parameters

The data retention time of the TC1161/TC1162's Flash memory (i.e. the time after which stored data can still be retrieved) depends on the number of times the Flash memory has been erased and programmed.

Table 5-2 Flash Parameters

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
Program Flash Retention Time, Physical Sector ^{1) 2)}	t_{RET}	15	–	years	Max. 1000 erase/program cycles
Program Flash Retention Time, Logical Sector ¹⁾²⁾	t_{RETL}	15	–	years	Max. 100 erase/program cycles
Data Flash Endurance (16 Kbyte)	N_{E}	15 000	–	–	Max. data retention time 2 years
Data Flash Endurance, EEPROM Emulation (8 × 2 Kbyte)	N_{E8}	120 000	–	–	Max. data retention time 2 years
Programming Time per Page ³⁾	t_{PR}	–	5	ms	–
Program Flash Erase Time per 256-Kbyte sector	t_{ERP}	–	5	s	$f_{\text{CPU}} = 66 \text{ MHz}$
Data Flash Erase Time per 8-Kbyte sector	t_{ERD}	–	312.5	ms	$f_{\text{CPU}} = 66 \text{ MHz}$
Wake-up time	t_{WU}	$4300 \times 1/f_{\text{CPU}} + 40\mu\text{s}$			

1) Storage and inactive time included.

2) At average weighted junction temperature $T_{\text{J}} = 100 \text{ }^{\circ}\text{C}$.

3) In case the Program Verify feature detects weak bits, these bits will be programmed once more. The reprogramming takes additional 5ms.

5.4 Quality Declaration

Table 5-3 shows the characteristics of the quality parameters in the TC1161/TC1162.

Table 5-3 Quality Parameters

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
ESD susceptibility according to Human Body Model (HBM)	V_{HBM}	–	2000	V	Conforming to EIA/JESD22-A114-B
ESD susceptibility of the LVDS pins	V_{HBM1}	–	500	V	–
ESD susceptibility according to Charged Device Model (CDM) pins	V_{CDM}	–	500	V	Conforming to JESD22-C101-C
Moisture Sensitivity Level (MSL)	V_{CDM}	–	3	V	Conforming to J-STD-020C for 240°C

Note: Information about soldering can be found on the “package” information page under: <http://www.infineon.com/products>.

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